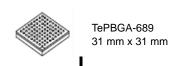
Data Sheet: Technical Data

Document Number: P1021EC

Rev. N, 03/2011

P1021



P1021 QorlQ Integrated Processor Hardware Specifications

The following list provides an overview of the feature set:

- Dual high-performance 32-bit cores, built on Power Architecture® technology:
 - 36-bit physical addressing
 - Double-precision floating-point support
 - 32 Kbyte L1 instruction cache and 32 Kbyte L1 data cache for each core
 - 533 MHz to 800 MHz clock frequency
- 256 Kbyte L2 cache with ECC. Also configurable as SRAM and stashing memory.
- Three 10/100/1000 Mbps enhanced three-speed Ethernet controllers (eTSECs)
 - TCP/IP acceleration, quality of service, and classification capabilities
 - IEEE® 1588 support
 - Lossless flow control
 - MII, RMII, RGMII, SGMII
- High-speed interfaces supporting various multiplexing options:
 - Four SerDes upto 2.5 GHz/lane multiplexed across controllers
 - Two PCI Express interfaces
 - Two SGMII interfaces
- High-Speed USB controller (USB 2.0)
 - Host and device support
 - Enhanced host controller interface (EHCI)
 - ULPI interface to PHY
- Enhanced secure digital host controller (SD/MMC)
- Enhanced Serial peripheral interface(eSPI)
- Integrated security engine
 - Protocol support includes ARC4, 3DES, AES, RSA/ECC, RNG, single-pass SSL/TLS
 - XOR acceleration
- 32-bit DDR2/DDR3 SDRAM memory controller with ECC support
- Programmable interrupt controller (PIC) compliant with OpenPIC standard

- · One four-channel DMA controller
- Two I²C controllers, DUART, timers
- Enhanced local bus controller (eLBC)
- · QUICC Engine block
- Operating junction temperature (T_j) range: 0–125°C and -40°C–125°C (industrial specification)
- 31 × 31 mm 689-pin WB-TePBGA II (wire bond temperature-enhanced plastic BGA)



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P1021 **Power Architecture Power Architecture** DDR2/DDR3 Security Acceleration e500 Core e500 Core **SDRAM Controller** 256 Kbyte L2 Cache 32 Kbyte 32 Kbyte 32 Kbyte 32 Kbyte **XOR** DUART, 2 × I²C, Timers, Interrupt Control, SD/MMC, SPI, USB 2.0/ULPI I-Cache D-Cache I-Cache D-Cache Power Management **Coherency Module** Enhanced Local Bus Controller (eLBC) System Bus On-Chip Network **QUICC Engine Block** 3 x Gigabit Ethernet 2 x PCI Express 4-ch DMA Accelerators 32-bit RISCs Serial DMA 64 K IRAM **Baud Rate** 24 K Interrupt 4-lane SERDES Generators MURAM Controller UCC5 UCC3 UCC7 Eth Mgmt SPI UCC1 Time Slot Assigner Communications Interfaces

Figure 1 shows the major functional units within the P1021.

Figure 1. P1021 Block Diagram

RMII

Up To 4 T1/E1

Core

UTOPIA

Acceleration

MII

Interface

1.1 Ball Layout Diagrams

The following figures show the top view of the 689-pin BGA ball map diagram and detailed quadrant views.

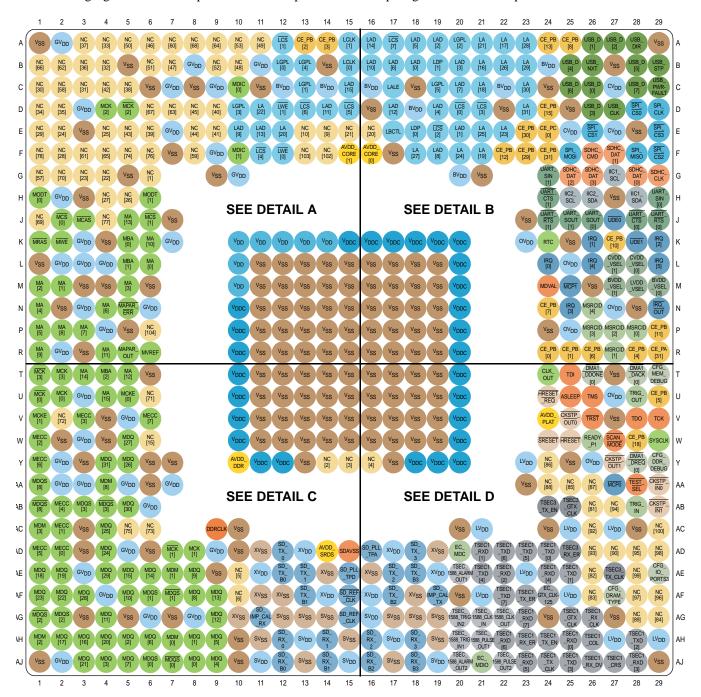


Figure 2. P1021 Top View Ballmap

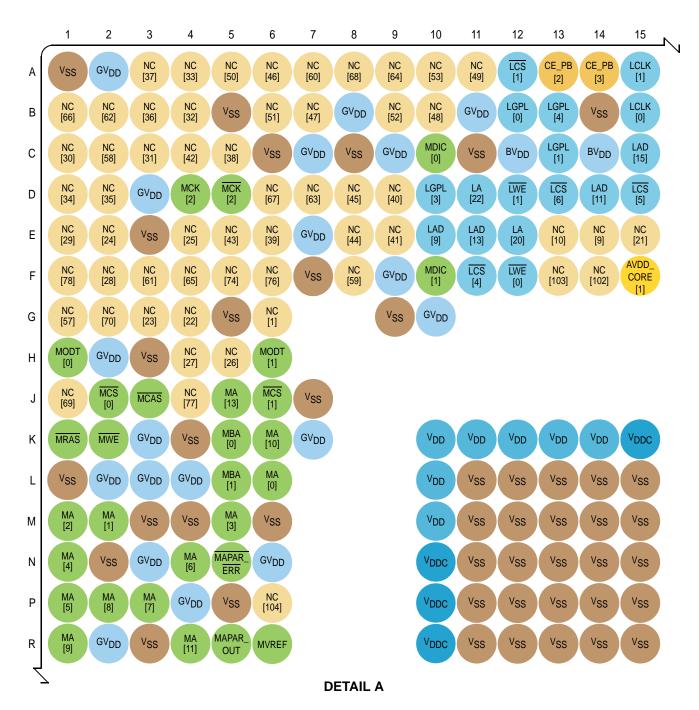


Figure 3. P1021 Detail A Ballmap

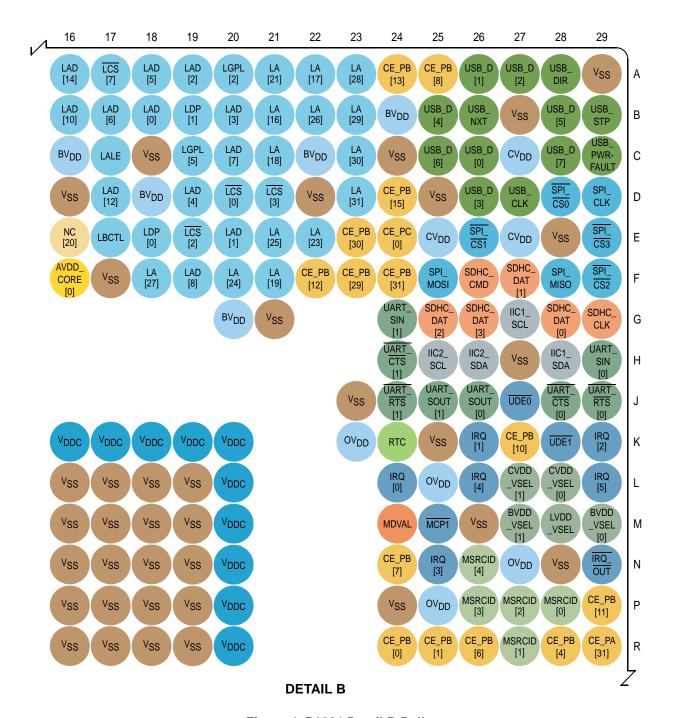


Figure 4. P1021 Detail B Ballmap

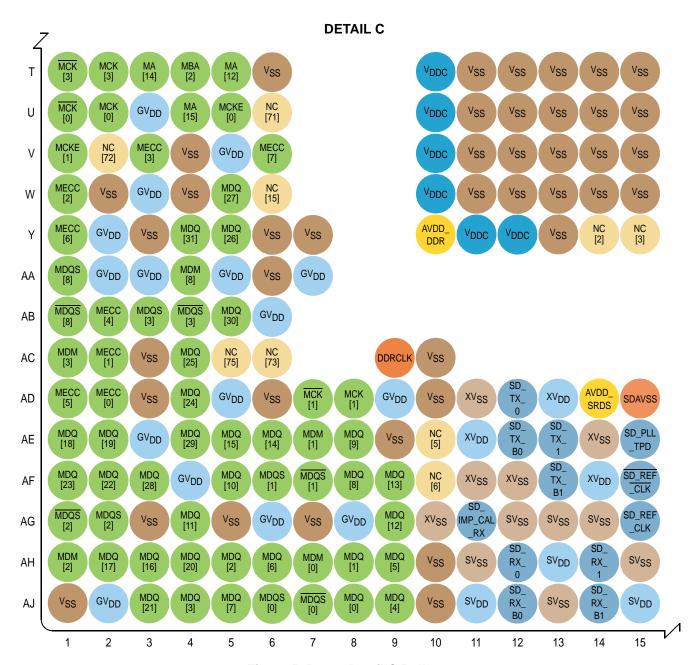


Figure 5. P1021 Detail C Ballmap

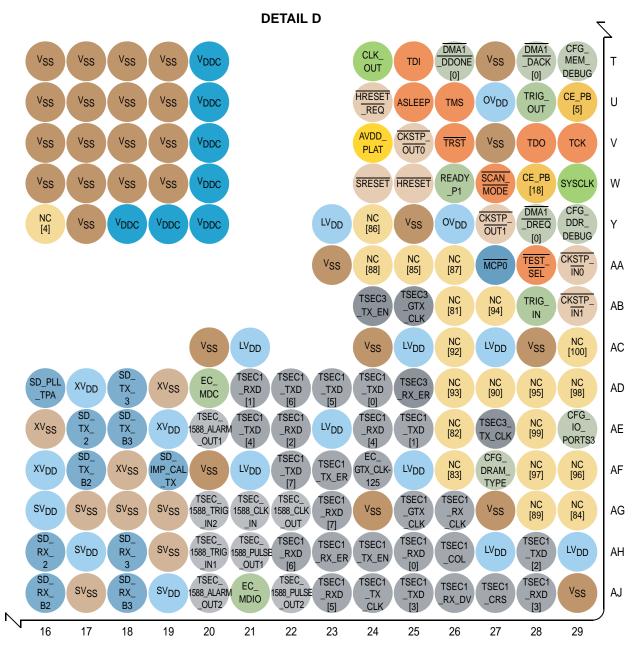


Figure 6. P1021 Detail D Ballmap

1.2 Pinout Assignments

Table 1 provides the pinout listing.

Table 1. P1021 Pinout Listing

| Signal | Package Pin Number | Pin Type | Power Supply | Notes |
|--------|--------------------|--------------|------------------|--------------|
| | DDR SDRAM Memo | ry Interface | | |
| MDQ00 | AJ8 | I/O | GV _{DD} | _ |
| MDQ01 | AH8 | I/O | GV _{DD} | _ |
| MDQ02 | AH5 | I/O | GV _{DD} | _ |
| MDQ03 | AJ4 | I/O | GV _{DD} | _ |
| MDQ04 | AJ9 | I/O | GV _{DD} | _ |
| MDQ05 | AH9 | I/O | GV _{DD} | _ |
| MDQ06 | AH6 | I/O | GV _{DD} | _ |
| MDQ07 | AJ5 | I/O | GV _{DD} | _ |
| MDQ08 | AF8 | I/O | GV _{DD} | _ |
| MDQ09 | AE8 | I/O | GV _{DD} | _ |
| MDQ10 | AF5 | I/O | GV _{DD} | _ |
| MDQ11 | AG4 | I/O | GV _{DD} | _ |
| MDQ12 | AG9 | I/O | GV _{DD} | _ |
| MDQ13 | AF9 | I/O | GV _{DD} | _ |
| MDQ14 | AE6 | I/O | GV _{DD} | _ |
| MDQ15 | AE5 | I/O | GV _{DD} | _ |
| MDQ16 | AH3 | I/O | GV _{DD} | _ |
| MDQ17 | AH2 | I/O | GV _{DD} | _ |
| MDQ18 | AE1 | I/O | GV _{DD} | _ |
| MDQ19 | AE2 | I/O | GV _{DD} | _ |
| MDQ20 | AH4 | I/O | GV _{DD} | - |
| MDQ21 | AJ3 | I/O | GV _{DD} | - |
| MDQ22 | AF2 | I/O | GV _{DD} | _ |
| MDQ23 | AF1 | I/O | GV _{DD} | _ |
| MDQ24 | AD4 | I/O | GV _{DD} | _ |
| MDQ25 | AC4 | I/O | GV _{DD} | _ |
| MDQ26 | Y5 | I/O | GV _{DD} | _ |
| MDQ27 | W5 | I/O | GV _{DD} | _ |
| MDQ28 | AF3 | I/O | GV _{DD} | _ |

Table 1. P1021 Pinout Listing (continued)

| Signal | Package Pin Number | Pin Type | Power Supply | Notes |
|--------|--------------------|----------|------------------|-------|
| MDQ29 | AE4 | I/O | GV _{DD} | _ |
| MDQ30 | AB5 | I/O | GV _{DD} | _ |
| MDQ31 | Y4 | I/O | GV _{DD} | _ |
| NC22 | G4 | NC | _ | _ |
| NC23 | G3 | NC | _ | _ |
| NC24 | E2 | NC | _ | _ |
| NC25 | E4 | NC | _ | _ |
| NC26 | H5 | NC | _ | _ |
| NC27 | H4 | NC | _ | _ |
| NC28 | F2 | NC | _ | _ |
| NC29 | E1 | NC | _ | _ |
| NC30 | C1 | NC | _ | _ |
| NC31 | C3 | NC | _ | _ |
| NC32 | B4 | NC | _ | _ |
| NC33 | A4 | NC | _ | _ |
| NC34 | D1 | NC | _ | _ |
| NC35 | D2 | NC | _ | _ |
| NC36 | B3 | NC | _ | _ |
| NC37 | A3 | NC | _ | _ |
| NC38 | C5 | NC | _ | _ |
| NC39 | E6 | NC | _ | _ |
| NC40 | D9 | NC | _ | _ |
| NC41 | E9 | NC | _ | _ |
| NC42 | C4 | NC | _ | _ |
| NC43 | E5 | NC | _ | _ |
| NC44 | E8 | NC | _ | _ |
| NC45 | D8 | NC | _ | _ |
| NC46 | A6 | NC | _ | _ |
| NC47 | B7 | NC | _ | _ |
| NC48 | B10 | NC | _ | _ |
| NC49 | A11 | NC | _ | _ |
| NC50 | A5 | NC | _ | _ |
| NC51 | B6 | NC | _ | _ |

Table 1. P1021 Pinout Listing (continued)

| Signal | Package Pin Number | Pin Type | Power Supply | Notes |
|-------------|--------------------|----------|------------------|-------|
| NC52 | B9 | NC | _ | _ |
| NC53 | A10 | NC | _ | _ |
| MECC00 | AD2 | I/O | GV _{DD} | _ |
| MECC01 | AC2 | I/O | GV _{DD} | _ |
| MECC02 | W1 | I/O | GV _{DD} | _ |
| MECC03 | V3 | I/O | GV _{DD} | _ |
| MECC04 | AB2 | I/O | GV _{DD} | _ |
| MECC05 | AD1 | I/O | GV _{DD} | _ |
| MECC06 | Y1 | I/O | GV _{DD} | _ |
| MECC07 | V6 | I/O | GV _{DD} | _ |
| MAPAR_ERR_B | N5 | I | GV _{DD} | _ |
| MAPAR_OUT | R5 | 0 | GV _{DD} | _ |
| MDM00 | AH7 | 0 | GV _{DD} | _ |
| MDM01 | AE7 | 0 | GV _{DD} | _ |
| MDM02 | AH1 | 0 | GV _{DD} | _ |
| MDM03 | AC1 | 0 | GV _{DD} | _ |
| NC57 | G1 | NC | _ | _ |
| NC58 | C2 | NC | _ | _ |
| NC59 | F8 | NC | _ | _ |
| NC60 | A7 | NC | _ | _ |
| MDM08 | AA4 | 0 | GV _{DD} | _ |
| MDQS00 | AJ6 | I/O | GV _{DD} | _ |
| MDQS01 | AF6 | I/O | GV _{DD} | _ |
| MDQS02 | AG2 | I/O | GV _{DD} | _ |
| MDQS03 | AB3 | I/O | GV _{DD} | _ |
| NC61 | F3 | NC | _ | _ |
| NC62 | B2 | NC | _ | _ |
| NC63 | D7 | NC | _ | _ |
| NC64 | A9 | NC | _ | _ |
| MDQS08 | AA1 | I/O | GV _{DD} | _ |
| MDQS_B00 | AJ7 | I/O | GV _{DD} | _ |
| MDQS_B01 | AF7 | I/O | GV _{DD} | _ |
| MDQS_B02 | AG1 | I/O | GV _{DD} | _ |

Table 1. P1021 Pinout Listing (continued)

| Signal | Package Pin Number | Pin Type | Power Supply | Notes |
|----------|--------------------|----------|------------------|-------|
| MDQS_B03 | AB4 | I/O | GV _{DD} | _ |
| NC65 | F4 | NC | _ | _ |
| NC66 | B1 | NC | _ | _ |
| NC67 | D6 | NC | _ | _ |
| NC68 | A8 | NC | _ | _ |
| MDQS_B08 | AB1 | I/O | GV _{DD} | _ |
| MBA00 | K5 | 0 | GV _{DD} | _ |
| MBA01 | L5 | 0 | GV _{DD} | _ |
| MBA02 | T4 | 0 | GV _{DD} | _ |
| MA00 | L6 | 0 | GV _{DD} | _ |
| MA01 | M2 | 0 | GV _{DD} | _ |
| MA02 | M1 | 0 | GV _{DD} | _ |
| MA03 | M5 | 0 | GV _{DD} | _ |
| MA04 | N1 | 0 | GV _{DD} | _ |
| MA05 | P1 | 0 | GV _{DD} | _ |
| MA06 | N4 | 0 | GV _{DD} | _ |
| MA07 | P3 | 0 | GV _{DD} | _ |
| MA08 | P2 | 0 | GV _{DD} | _ |
| MA09 | R1 | 0 | GV _{DD} | _ |
| MA10 | K6 | 0 | GV _{DD} | _ |
| MA11 | R4 | 0 | GV _{DD} | _ |
| MA12 | T5 | 0 | GV _{DD} | _ |
| MA13 | J5 | 0 | GV _{DD} | _ |
| MA14 | Т3 | 0 | GV _{DD} | _ |
| MA15 | U4 | 0 | GV _{DD} | _ |
| MWE_B | K2 | 0 | GV _{DD} | _ |
| MRAS_B | K1 | 0 | GV _{DD} | _ |
| MCAS_B | J3 | 0 | GV _{DD} | _ |
| MCS_B00 | J2 | 0 | GV _{DD} | _ |
| MCS_B01 | J6 | 0 | GV _{DD} | _ |
| NC69 | J1 | NC | _ | _ |
| NC70 | G2 | NC | _ | _ |
| MCKE00 | U5 | 0 | GV _{DD} | 11 |

Table 1. P1021 Pinout Listing (continued)

| Signal | Package Pin Number | Pin Type | Power Supply | Notes |
|----------|--------------------|----------|------------------------|-------|
| MCKE01 | V1 | 0 | GV _{DD} | 11 |
| NC71 | U6 | NC | _ | _ |
| NC72 | V2 | NC | _ | _ |
| MCK00 | U2 | 0 | GV _{DD} | _ |
| MCK01 | AD8 | 0 | GV _{DD} | _ |
| MCK02 | D4 | 0 | GV _{DD} | _ |
| MCK03 | T2 | 0 | GV _{DD} | _ |
| NC73 | AC6 | NC | _ | _ |
| NC74 | F5 | NC | _ | _ |
| MCK_B00 | U1 | 0 | GV _{DD} | _ |
| MCK_B01 | AD7 | 0 | GV _{DD} | _ |
| MCK_B02 | D5 | 0 | GV _{DD} | _ |
| MCK_B03 | T1 | 0 | GV _{DD} | _ |
| NC75 | AC5 | NC | _ | _ |
| NC76 | F6 | NC | _ | _ |
| MODT00 | H1 | 0 | GV _{DD} | _ |
| MODT01 | H6 | 0 | GV _{DD} | _ |
| NC77 | J4 | NC | _ | _ |
| NC78 | F1 | NC | _ | _ |
| MDIC00 | C10 | I/O | GV _{DD} | 23 |
| MDIC01 | F10 | I/O | GV _{DD} | 23 |
| | SerDes | • | | |
| SD_TX_3 | AD18 | 0 | XV _{DD} _SRDS | _ |
| SD_TX_2 | AE17 | 0 | XV _{DD} _SRDS | _ |
| SD_TX_1 | AE13 | 0 | XV _{DD} _SRDS | _ |
| SD_TX_0 | AD12 | 0 | XV _{DD} _SRDS | _ |
| SD_TX_B3 | AE18 | 0 | XV _{DD} _SRDS | _ |
| SD_TX_B2 | AF17 | 0 | XV _{DD} _SRDS | _ |
| SD_TX_B1 | AF13 | 0 | XV _{DD} SRDS | _ |
| SD_TX_B0 | AE12 | 0 | XV _{DD} _SRDS | _ |
| SD_RX_3 | AH18 | I | XV _{DD} _SRDS | _ |
| SD_RX_2 | AH16 | I | XV _{DD} _SRDS | _ |

Table 1. P1021 Pinout Listing (continued)

| Signal | Package Pin Number | Pin Type | Power Supply | Notes |
|---------------|-----------------------|--------------------|------------------------|-------|
| SD_RX_1 | AH14 | I | XV _{DD} _SRDS | _ |
| SD_RX_0 | AH12 | I | XV _{DD} _SRDS | _ |
| SD_RX_B3 | AJ18 | I | XV _{DD} _SRDS | _ |
| SD_RX_B2 | AJ16 | I | XV _{DD} _SRDS | _ |
| SD_RX_B1 | AJ14 | I | XV _{DD} _SRDS | _ |
| SD_RX_B0 | AJ12 | I | XV _{DD} _SRDS | _ |
| SD_REF_CLK | AG15 | I | XV _{DD} _SRDS | _ |
| SD_REF_CLK_B | AF15 | I | XV _{DD} _SRDS | _ |
| SD_PLL_TPD | AE15 | 0 | XV _{DD} _SRDS | 15 |
| SD_IMP_CAL_RX | AG11 | I | XV _{DD} _SRDS | 34 |
| SD_IMP_CAL_TX | AF19 | I | XV _{DD} _SRDS | 34 |
| SD_PLL_TPA | AD16 | 0 | XV _{DD} _SRDS | 15 |
| | Enhanced Local Bus Co | ntroller Interface | • | |
| LAD00 | B18 | I/O | BV _{DD} | 5,29 |
| LAD01 | E20 | I/O | BV _{DD} | 5,29 |
| LAD02 | A19 | I/O | BV _{DD} | 5,29 |
| LAD03 | B20 | I/O | BV _{DD} | 5,29 |
| LAD04 | D19 | I/O | BV _{DD} | 5,29 |
| LAD05 | A18 | I/O | BV _{DD} | 5,29 |
| LAD06 | B17 | I/O | BV _{DD} | 5,29 |
| LAD07 | C20 | I/O | BV _{DD} | 5,29 |
| LAD08/CE_PA0 | F19 | I/O | BV _{DD} | 5,29 |
| LAD09 | E10 | I/O | BV _{DD} | 5,29 |
| LAD10 | B16 | I/O | BV _{DD} | 5,29 |
| LAD11 | D14 | I/O | BV _{DD} | 5,29 |
| LAD12 | D17 | I/O | BV _{DD} | 5,29 |
| LAD13 | E11 | I/O | BV _{DD} | 5,29 |
| LAD14 | A16 | I/O | BV _{DD} | 5,29 |
| LAD15 | C15 | I/O | BV _{DD} | 5,29 |
| LDP00/CE_PA11 | E18 | I/O | BV _{DD} | 10 |
| LDP01/CE_PA12 | B19 | I/O | BV _{DD} | 10 |
| LA16/CE_PA4 | B21 | I/O | BV _{DD} | ,31 |

Table 1. P1021 Pinout Listing (continued)

| Signal | Package Pin Number | Pin Type | Power Supply | Notes |
|-----------------|--------------------|----------|------------------|-------|
| LA17/CE_PA5 | A22 | I/O | BV _{DD} | 19 |
| LA18/CE_PA6 | C21 | I/O | BV _{DD} | 5 |
| LA19/CE_PA7 | F21 | I/O | BV _{DD} | 5 |
| LA20/CE_PA8 | E12 | I/O | BV _{DD} | 5,27 |
| LA21/CE_PA9 | A21 | I/O | BV _{DD} | 5,27 |
| LA22/CE_PA10 | D11 | I/O | BV _{DD} | 5,27 |
| LA23/CE_PA17 | E22 | I/O | BV _{DD} | 5 |
| LA24/CE_PA18 | F20 | I/O | BV _{DD} | 5 |
| LA25/CE_PA19 | E21 | I/O | BV _{DD} | 5 |
| LA26/CE_PA20 | B22 | I/O | BV _{DD} | 5 |
| LA27/CE_PA21 | F18 | I/O | BV _{DD} | 31 |
| LA28/CE_PA13 | A23 | I/O | BV _{DD} | |
| LA29/CE_PA25 | B23 | I/O | BV _{DD} | _ |
| LA30/CE_PA26 | C23 | I/O | BV _{DD} | _ |
| LA31/CE_PA30 | D23 | I/O | BV _{DD} | _ |
| LCS_B00 | D20 | 0 | BV _{DD} | 10 |
| LCS_B01 | A12 | 0 | BV _{DD} | 10 |
| LCS_B02 | E19 | 0 | BV _{DD} | 10 |
| LCS_B03 | D21 | 0 | BV _{DD} | 10 |
| LCS_B04/CE_PA22 | F11 | I/O | BV _{DD} | 10 |
| LCS_B05/CE_PA23 | D15 | I/O | BV _{DD} | 10 |
| LCS_B06/CE_PA24 | D13 | 0 | BV _{DD} | 10 |
| LCS_B07/CE_PA27 | A17 | 0 | BV _{DD} | 10 |
| LWE_B00 | F12 | 0 | BV _{DD} | 8,9 |
| LWE_B01/CE_PB9 | D12 | I/O | BV _{DD} | |
| LBCTL/CE_PB20 | E17 | I/O | BV _{DD} | 8 |
| LALE | C17 | 0 | BV _{DD} | 8 |
| LGPL0/CE_PA1 | B12 | I/O | BV _{DD} | |
| LGPL1/CE_PA2 | C13 | I/O | BV _{DD} | |
| LGPL2 | A20 | 0 | BV _{DD} | 8 |
| LGPL3/CE_PA3 | D10 | I/O | BV _{DD} | 5 |
| LGPL4 | B13 | I/O | BV _{DD} | 36 |
| LGPL5/CE_PA14 | C19 | I/O | BV _{DD} | 5 |

Table 1. P1021 Pinout Listing (continued)

| Signal | Package Pin Number | Pin Type | Power Supply | Notes |
|------------------------|----------------------|----------------|------------------|-------|
| LCLK00/CE_PA28 | B15 | I/O | BV _{DD} | _ |
| LCLK01/CE_PA16 | A15 | I/O | BV _{DD} | _ |
| CE_PB2 | A13 | I/O | BV _{DD} | _ |
| CE_PB3 | A14 | I/O | BV _{DD} | _ |
| | DMA | | | |
| DMA1_DREQ_B00 | Y28 | I | OV _{DD} | _ |
| CE_PB18 | W28 | I/O | OV _{DD} | _ |
| DMA1_DACK_B00 | T28 | 0 | OV _{DD} | 37 |
| CFG_MEM_DEBUG /CE_PB19 | T29 | I/O | OV _{DD} | _ |
| DMA1_DDONE_B00 | T26 | 0 | OV _{DD} | _ |
| CFG_DDR_DEBUG /CE_PA29 | Y29 | I/O | OV _{DD} | _ |
| | Programmable Interru | upt Controller | | |
| UDE0_B | J27 | I | OV _{DD} | 2 |
| UDE1_B | K28 | I | OV _{DD} | 2 |
| MCP0_B | AA27 | I | OV _{DD} | 2 |
| MCP1_B | M25 | 1 | OV _{DD} | 2 |
| IRQ00 | L24 | I | OV _{DD} | _ |
| IRQ01 | K26 | I | OV _{DD} | _ |
| IRQ02 | K29 | I | OV _{DD} | _ |
| IRQ03 | N25 | I | OV _{DD} | _ |
| IRQ04 | L26 | I | OV _{DD} | _ |
| IRQ05 | L29 | I | OV _{DD} | _ |
| CE_PB10 | K27 | I | OV _{DD} | _ |
| IRQ_OUT_B | N29 | 0 | OV _{DD} | 2,4 |
| | Voltage Sel | ect | | |
| LVDD_VSEL | M28 | 1 | OV _{DD} | 28 |
| BVDD_VSEL0 | M29 | I | OV _{DD} | 28 |
| BVDD_VSEL1 | M27 | 1 | OV _{DD} | 28 |
| CVDD_VSEL0 | L28 | 1 | OV _{DD} | 28 |
| CVDD_VSEL1 | L27 | I | OV _{DD} | 28 |
| | 1588 | • | | |
| TSEC_1588_CLK_IN | AG21 | I | LV _{DD} | _ |

Table 1. P1021 Pinout Listing (continued)

| Signal | Package Pin Number | Pin Type | Power Supply | Notes |
|-----------------------------------|-------------------------|------------------|------------------|-------|
| TSEC_1588_TRIG_IN1 | AH20 | I | LV _{DD} | _ |
| TSEC_1588_TRIG_IN2 | AG20 | I | LV _{DD} | _ |
| TSEC_1588_ALARM_OUT1 | AE20 | 0 | LV _{DD} | 5,9 |
| TSEC_1588_ALARM_OUT2 | AJ20 | 0 | LV _{DD} | 5,9 |
| TSEC_1588_CLK_OUT | AG22 | 0 | LV _{DD} | 5,9 |
| TSEC_1588_PULSE_OUT1 | AH21 | 0 | LV _{DD} | 5,9 |
| TSEC_1588_PULSE_OUT2 | AJ22 | 0 | LV _{DD} | 5,9 |
| | Ethernet Manageme | ent Interface | | |
| EC_MDC | AD20 | 0 | LV _{DD} | 5,9 |
| EC_MDIO | AJ21 | I/O | LV _{DD} | _ |
| | Gigabit Ethernet Ref | erence Clock | , | |
| EC_GTX_CLK125 | AF24 | I | LV _{DD} | 26 |
| | Enhanced Three Speed Et | hernet Controlle | r 1 | |
| TSEC1_TXD07/TSEC3_TXD03 | AF22 | 0 | LV _{DD} | 5,9 |
| TSEC1_TXD06/TSEC3_TXD02 | AD22 | 0 | LV _{DD} | 5,9 |
| TSEC1_TXD05/TSEC3_TXD01 | AD23 | 0 | LV _{DD} | 5,9 |
| TSEC1_TXD04/TSEC3_TXD00 | AE21 | 0 | LV _{DD} | 5,9 |
| TSEC1_TXD03 | AJ25 | 0 | LV _{DD} | 5,9 |
| TSEC1_TXD02 | AH28 | 0 | LV _{DD} | 5,9 |
| TSEC1_TXD01 | AE25 | 0 | LV _{DD} | 5,9 |
| TSEC1_TXD00 | AD24 | 0 | LV _{DD} | 5,9 |
| TSEC1_TX_EN | AH24 | 0 | LV _{DD} | 33 |
| TSEC1_TX_ER | AF23 | 0 | LV _{DD} | 5,9 |
| TSEC1_TX_CLK/ TSEC1_GTX_CLK125 | AJ24 | I | LV _{DD} | _ |
| TSEC1_GTX_CLK | AG25 | 0 | LV _{DD} | _ |
| TSEC1_CRS/TSEC3_RX_DV | AJ27 | I/O | LV _{DD} | _ |
| TSEC1_COL/TSEC3_RX_CLK | AH26 | ı | LV _{DD} | _ |
| TSEC1_RXD07/TSEC3_RXD03 | AG23 | I | LV _{DD} | _ |
| TSEC1_RXD06/TSEC3_RXD02 | AH22 | I | LV _{DD} | _ |
| TSEC1_RXD05/TSEC3_RXD01 | AJ23 | I | LV _{DD} | |
| TSEC1_RXD04/TSEC3_RXD00 | AE24 | I | LV _{DD} | _ |

Table 1. P1021 Pinout Listing (continued)

| Signal | Package Pin Number | Pin Type | Power Supply | Notes |
|---------------|---------------------|----------------|------------------|-------|
| TSEC1_RXD03 | AJ28 | I | LV _{DD} | _ |
| TSEC1_RXD02 | AE22 | I | LV _{DD} | _ |
| TSEC1_RXD01 | AD21 | 1 | LV _{DD} | _ |
| TSEC1_RXD00 | AH25 | 1 | LV _{DD} | _ |
| TSEC1_RX_DV | AJ26 | I | LV _{DD} | _ |
| TSEC1_RX_ER | AH23 | I | LV _{DD} | _ |
| TSEC1_RX_CLK | AG26 | I | LV _{DD} | _ |
| | Three Speed Etherne | t Controller 3 | | |
| NC82 | AE26 | NC | _ | _ |
| NC83 | AF26 | NC | _ | _ |
| TSEC3_TX_EN | AB24 | 0 | LV _{DD} | 33 |
| TSEC3_GTX_CLK | AB25 | 0 | LV _{DD} | _ |
| NC84 | AG29 | NC | _ | _ |
| NC85 | AA25 | NC | _ | _ |
| CFG_DRAM_TYPE | AF27 | I | LV _{DD} | _ |
| NC86 | Y24 | NC | _ | _ |
| NC87 | AA26 | NC | _ | _ |
| CFG_IO_PORTS3 | AE29 | I | LV _{DD} | _ |
| NC88 | AA24 | NC | _ | _ |
| NC89 | AG28 | NC | _ | _ |
| TSEC3_RX_ER | AD25 | I/O | LV _{DD} | _ |
| TSEC3_TX_CLK | AE27 | I | LV _{DD} | _ |
| NC90 | AD27 | NC | _ | _ |
| NC91 | AB26 | NC | _ | _ |
| NC92 | AC26 | NC | _ | _ |
| NC93 | AD26 | NC | _ | _ |
| NC94 | AB27 | NC | _ | _ |
| NC95 | AD28 | NC | _ | _ |
| NC96 | AF29 | NC | _ | _ |
| NC97 | AF28 | NC | _ | _ |
| NC98 | AD29 | NC | _ | _ |
| NC99 | AE28 | NC | _ | _ |

Table 1. P1021 Pinout Listing (continued)

| Signal | Package Pin Number | Pin Type | Power Supply | Notes |
|-----------------------|--------------------|----------|------------------|-------|
| NC100 | AC29 | NC | _ | _ |
| | DUART | l | | |
| UART_SOUT00 | J26 | 0 | OV _{DD} | 27 |
| UART_SOUT01/CE_PB17 | J25 | I/O | OV _{DD} | 8 |
| UART_SIN00 | H29 | I | OV _{DD} | _ |
| UART_SIN01/CE_PB16 | G24 | I/O | OV _{DD} | _ |
| UART_CTS_B00 | J28 | 1 | OV _{DD} | _ |
| UART_CTS_B01/CE_PB14 | H24 | I/O | OV _{DD} | _ |
| UART_RTS_B00 | J29 | 0 | OV _{DD} | 5 |
| UART_RTS_B01/CE_PB15 | J24 | 0 | OV _{DD} | 5 |
| | I2C | | | |
| IIC1 | H28 | I/O | OV _{DD} | 4,18 |
| IIC1_SCL | G27 | I/O | OV _{DD} | 4,18 |
| IIC2_SDA/CE_PB21 | H26 | I/O | OV _{DD} | 18 |
| IIC2_SCL/CE_PB22 | H25 | I/O | OV _{DD} | 18 |
| | eSDHC | | | |
| SDHC_DATA00 | G28 | I/O | CV _{DD} | _ |
| SDHC_DATA01 | F27 | I/O | CV _{DD} | _ |
| SDHC_DATA02 | G25 | I/O | CV _{DD} | _ |
| SDHC_DATA03 | G26 | I/O | CV _{DD} | _ |
| SDHC_CMD | F26 | I/O | CV _{DD} | _ |
| SDHC_CLK | G29 | 0 | CV _{DD} | _ |
| | SPI | | | |
| SPI_MISO | F28 | I | CV _{DD} | _ |
| SPI_MOSI | F25 | I/O | CV _{DD} | _ |
| SPI_CS0_B/SDHC_DATA04 | D28 | I/O | CV _{DD} | _ |
| SPI_CS1_B/SDHC_DATA05 | E26 | I/O | CV _{DD} | _ |
| SPI_CS2_B/SDHC_DATA06 | F29 | I/O | CV _{DD} | _ |
| SPI_CS3_B/SDHC_DATA07 | E29 | I/O | CV _{DD} | _ |
| SPI_CLK | D29 | 0 | CV _{DD} | _ |
| | USB | | | |
| USB_NXT | B26 | I | CV _{DD} | _ |

Table 1. P1021 Pinout Listing (continued)

| Signal | Package Pin Number | Pin Type | Power Supply | Notes |
|-------------------|--------------------|-------------|------------------|-------|
| USB_DIR | A28 | I | CV _{DD} | 37 |
| USB_STP | B29 | 0 | CV _{DD} | _ |
| USB_PWRFAULT | C29 | I | CV _{DD} | _ |
| USB_CLK | D27 | I | CV _{DD} | _ |
| USB_D07 | C28 | I/O | CV _{DD} | _ |
| USB_D06 | C25 | I/O | CV _{DD} | _ |
| USB_D05 | B28 | I/O | CV _{DD} | _ |
| USB_D04 | B25 | I/O | CV _{DD} | _ |
| USB_D03 | D26 | I/O | CV _{DD} | _ |
| USB_D02 | A27 | I/O | CV _{DD} | _ |
| USB_D01 | A26 | I/O | CV _{DD} | _ |
| USB_D00 | C26 | I/O | CV _{DD} | _ |
| | General-Purpose Ir | nput/Output | 1 | |
| CE_PB4 | R28 | I/O | OV_{DD} | _ |
| CE_PB6 | R26 | I/O | OV _{DD} | _ |
| CE_PB11 | P29 | I/O | OV _{DD} | _ |
| CE_PB7 | N24 | I/O | OV _{DD} | _ |
| CE_PB5 | U29 | I/O | OV _{DD} | _ |
| CE_PB0 | R24 | I/O | OV _{DD} | _ |
| CE_PA31 | R29 | I/O | OV_DD | _ |
| CE_PB1 | R25 | I/O | OV_DD | _ |
| SDHC_CD/CE_PB12 | F22 | I/O | BV _{DD} | _ |
| SDHC_WP/CE_PB13 | A24 | I/O | BV _{DD} | _ |
| USB_PCTL0/CE_PB8 | A25 | I/O | BV _{DD} | _ |
| USB_PCTL1/CE_PA15 | D24 | I/O | BV _{DD} | _ |
| CE_PB29 | F23 | I/O | BV _{DD} | _ |
| CE_PB30 | E23 | I/O | BV _{DD} | _ |
| CE_PB31 | F24 | I/O | BV _{DD} | _ |
| CE_PC0 | E24 | I/O | BV _{DD} | _ |
| | System Cor | ntrol | <u>l</u> | |
| HRESET_B | W25 | I | OV _{DD} | _ |
| HRESET_REQ_B | U24 | 0 | OV_DD | 19 |

Table 1. P1021 Pinout Listing (continued)

| Signal | Package Pin Number | Pin Type | Power Supply | Notes |
|--|--------------------|----------|------------------|-------|
| SRESET_B | W24 | I | OV _{DD} | _ |
| CKSTP_IN0_B | AA29 | 1 | OV _{DD} | 2 |
| CKSTP_IN1_B | AB29 | 1 | OV _{DD} | 2 |
| CKSTP_OUT0_B | V25 | 0 | OV _{DD} | 2,4 |
| CKSTP_OUT1_B | Y27 | 0 | OV _{DD} | 2,4 |
| | Debug | | 1 | |
| TRIG_IN | AB28 | 1 | OV _{DD} | _ |
| TRIG_OUT | U28 | 0 | OV _{DD} | 8,9 |
| READY_P1 | W26 | 0 | OV _{DD} | 8 |
| MSRCID00/LB_MSRCID00/ PLL_PER_OUT00/CE_PB23 | P28 | I/O | OV _{DD} | _ |
| MSRCID01/LB_MSRCID01/ PLL_PER_OUT01/CE_PB24 | R27 | I/O | OV _{DD} | 19 |
| MSRCID02/LB_MSRCID02/ PLL_PER_OUT02/CE_PB25 | P27 | I/O | OV _{DD} | 19 |
| MSRCID03/LB_MSRCID03/ PLL_PER_OUT03/CE_PB26 | P26 | I/O | OV _{DD} | 19 |
| MSRCID04/LB_MSRCID04/ PLL_UP_DN/CE_PB27 | N26 | I/O | OV _{DD} | 27 |
| MDVAL/LB_MDVAL/ PLL_PER_VALID/CE_PB28 | M24 | I/O | OV _{DD} | 19 |
| | Clocks | | , | |
| CLK_OUT | T24 | 0 | OV _{DD} | 11 |
| RTC | K24 | I | OV _{DD} | _ |
| DDRCLK | AC9 | I | OV _{DD} | 25 |
| SYSCLK | W29 | I | OV _{DD} | _ |
| | DFT | | | |
| SCAN_MODE_B | W27 | I | OV _{DD} | 37 |
| TEST_SEL_B | AA28 | I | OV _{DD} | 37 |
| | JTAG | | | |
| TCK | V29 | I | OV _{DD} | _ |
| TDI | T25 | I | OV _{DD} | 12 |
| TDO | V28 | 0 | OV _{DD} | 11 |
| TMS | U26 | I | OV _{DD} | 12 |

Table 1. P1021 Pinout Listing (continued)

| Signal | Package Pin Number | Pin Type | Power Supply | Notes |
|-------------------------|--------------------|-----------|------------------|-------|
| TRST_B | V26 | I | OV _{DD} | 12 |
| | Power Manage | ement | , | |
| ASLEEP | U25 | 0 | OV _{DD} | 19 |
| NC1 | G6 | NC | _ | _ |
| NC2 | Y14 | NC | _ | _ |
| NC3 | Y15 | NC | _ | _ |
| NC4 | Y16 | NC | _ | _ |
| NC5 | AE10 | NC | _ | _ |
| NC6 | AF10 | NC | _ | _ |
| NC9 | E14 | NC | _ | _ |
| NC10 | E13 | NC | _ | _ |
| NC15 | W6 | NC | _ | _ |
| | Power and Groun | d Signals | | |
| GND | AH10 | _ | | _ |
| GND | AJ10 | _ | _ | _ |
| GND | AD10 | _ | _ | _ |
| NC20 | E16 | NC | _ | _ |
| NC21 | E15 | NC | _ | _ |
| AGND_SRDS | AD15 | _ | _ | _ |
| AV _{DD} _CORE0 | F16 | _ | _ | 17,32 |
| AV _{DD} _CORE1 | F15 | | _ | 17,32 |
| AV _{DD} _DDR | Y10 | _ | _ | 17 |
| NC102 | F14 | NC | _ | _ |
| AV _{DD} PLAT | V24 | _ | _ | 17 |
| AV _{DD} _SRDS | AD14 | _ | _ | 17 |
| BV_DD | B24 | _ | _ | _ |
| BV _{DD} | C12 | _ | _ | _ |
| BV_DD | C14 | _ | _ | _ |
| BV _{DD} | C16 | _ | _ | _ |
| BV_DD | C22 | _ | _ | _ |
| BV_DD | D18 | _ | _ | _ |
| BV _{DD} | G20 | _ | _ | _ |

Table 1. P1021 Pinout Listing (continued)

| Signal | Package Pin Number | Pin Type | Power Supply | Notes |
|------------------|--------------------|----------|--------------|-------|
| CV _{DD} | C27 | _ | _ | _ |
| CV _{DD} | E25 | _ | _ | _ |
| CV _{DD} | E27 | _ | _ | _ |
| GV _{DD} | A2 | _ | _ | _ |
| GV _{DD} | B8 | _ | _ | _ |
| GV _{DD} | B11 | _ | _ | _ |
| GV _{DD} | C7 | _ | _ | _ |
| GV _{DD} | C9 | _ | _ | _ |
| GV _{DD} | D3 | _ | _ | _ |
| GV _{DD} | E7 | _ | _ | _ |
| GV _{DD} | F9 | _ | _ | _ |
| GV _{DD} | G10 | _ | _ | _ |
| GV _{DD} | H2 | _ | _ | _ |
| GV _{DD} | K3 | _ | _ | _ |
| GV _{DD} | K7 | _ | _ | _ |
| GV _{DD} | L2 | _ | _ | _ |
| GV _{DD} | L3 | _ | _ | _ |
| GV _{DD} | L4 | _ | _ | _ |
| GV _{DD} | N3 | _ | _ | _ |
| GV _{DD} | N6 | _ | _ | _ |
| GV _{DD} | P4 | _ | _ | _ |
| GV _{DD} | R2 | _ | _ | _ |
| GV _{DD} | U3 | _ | _ | _ |
| GV _{DD} | V5 | _ | _ | _ |
| GV _{DD} | W3 | _ | _ | _ |
| GV _{DD} | Y2 | _ | _ | _ |
| GV _{DD} | AA2 | _ | _ | _ |
| GV _{DD} | AA3 | _ | _ | _ |
| GV _{DD} | AA5 | _ | _ | _ |
| GV _{DD} | AA7 | _ | _ | _ |
| GV _{DD} | AB6 | _ | _ | _ |
| GV _{DD} | AD5 | _ | _ | _ |
| GV _{DD} | AD9 | _ | _ | _ |

Table 1. P1021 Pinout Listing (continued)

| Signal | Package Pin Number | Pin Type | Power Supply | Notes |
|------------------------|--------------------|----------|--------------|-------|
| GV _{DD} | AE3 | _ | _ | _ |
| GV _{DD} | AF4 | _ | _ | _ |
| GV _{DD} | AG6 | _ | _ | _ |
| GV _{DD} | AG8 | _ | _ | _ |
| GV _{DD} | AJ2 | _ | _ | _ |
| LV _{DD} | Y23 | _ | _ | _ |
| LV _{DD} | AC21 | _ | _ | _ |
| LV _{DD} | AC25 | _ | _ | _ |
| LV _{DD} | AC27 | _ | _ | _ |
| LV _{DD} | AE23 | _ | _ | _ |
| LV _{DD} | AF21 | _ | _ | _ |
| LV _{DD} | AF25 | _ | _ | _ |
| LV _{DD} | AH27 | _ | _ | _ |
| LV _{DD} | AH29 | _ | _ | _ |
| SV _{DD} _SRDS | AG16 | _ | _ | _ |
| SV _{DD} _SRDS | AH13 | _ | _ | _ |
| SV _{DD} _SRDS | AH17 | _ | _ | _ |
| SV _{DD} _SRDS | AJ11 | _ | _ | _ |
| SV _{DD} _SRDS | AJ15 | _ | _ | _ |
| SV _{DD} _SRDS | AJ19 | _ | _ | _ |
| SGND_SRDS | AG12 | _ | _ | _ |
| SGND_SRDS | AG13 | _ | _ | _ |
| SGND_SRDS | AG14 | _ | _ | _ |
| SGND_SRDS | AG17 | _ | _ | _ |
| SGND_SRDS | AG18 | _ | _ | _ |
| SGND_SRDS | AG19 | _ | _ | _ |
| SGND_SRDS | AH11 | _ | _ | _ |
| SGND_SRDS | AH15 | _ | _ | _ |
| SGND_SRDS | AH19 | _ | _ | _ |
| SGND_SRDS | AJ13 | _ | _ | _ |
| SGND_SRDS | AJ17 | _ | _ | _ |
| XV _{DD} _SRDS | AD13 | _ | _ | _ |
| XV _{DD} _SRDS | AD17 | _ | _ | _ |

Table 1. P1021 Pinout Listing (continued)

| Signal | Package Pin Number | Pin Type | Power Supply | Notes |
|------------------------|--------------------|----------|--------------|-------|
| XV _{DD} _SRDS | AE11 | _ | _ | _ |
| XV _{DD} _SRDS | AE19 | _ | _ | _ |
| XV _{DD} _SRDS | AF14 | _ | _ | _ |
| XV _{DD} _SRDS | AF16 | _ | _ | _ |
| XGND_SRDS | AD11 | _ | _ | _ |
| XGND_SRDS | AD19 | _ | _ | _ |
| XGND_SRDS | AE14 | _ | _ | _ |
| XGND_SRDS | AE16 | _ | _ | _ |
| XGND_SRDS | AF11 | _ | _ | _ |
| XGND_SRDS | AF12 | _ | _ | _ |
| XGND_SRDS | AF18 | _ | _ | _ |
| XGND_SRDS | AG10 | _ | _ | _ |
| MVREF | R6 | _ | _ | _ |
| OV _{DD} | K23 | _ | _ | _ |
| OV _{DD} | L25 | _ | _ | _ |
| OV _{DD} | N27 | _ | _ | _ |
| OV _{DD} | P25 | _ | _ | _ |
| OV _{DD} | U27 | _ | _ | _ |
| OV _{DD} | Y26 | _ | _ | _ |
| NC103 | F13 | NC | _ | _ |
| NC104 | P6 | NC | _ | _ |
| V _{DD} | K10 | | _ | _ |
| V _{DD} | K11 | | _ | _ |
| V _{DD} | K12 | | _ | _ |
| V _{DD} | K13 | | _ | _ |
| V _{DD} | K14 | | _ | _ |
| V _{DD} | L10 | | _ | _ |
| V _{DD} | M10 | | _ | _ |
| V _{DDC} | K15 | _ | _ | _ |
| V _{DDC} | K17 | _ | _ | _ |
| V _{DDC} | K19 | _ | _ | _ |
| V _{DDC} | K16 | _ | _ | _ |
| V _{DDC} | L20 | _ | _ | _ |

Table 1. P1021 Pinout Listing (continued)

| Signal | Package Pin Number | Pin Type | Power Supply | Notes |
|------------------|--------------------|----------|--------------|-------|
| V_{DDC} | K18 | _ | _ | _ |
| V _{DDC} | K20 | _ | _ | _ |
| V _{DDC} | N10 | _ | _ | _ |
| V _{DDC} | N20 | _ | _ | _ |
| V _{DDC} | M20 | _ | _ | _ |
| V _{DDC} | R10 | _ | _ | _ |
| V _{DDC} | R20 | _ | _ | _ |
| V _{DDC} | P10 | _ | _ | _ |
| V _{DDC} | P20 | _ | _ | _ |
| V _{DDC} | U10 | _ | _ | _ |
| V _{DDC} | U20 | _ | _ | _ |
| V_{DDC} | T10 | _ | _ | _ |
| V_{DDC} | T20 | _ | _ | _ |
| V_{DDC} | W10 | _ | _ | _ |
| V_{DDC} | V10 | _ | _ | _ |
| V_{DDC} | V20 | _ | _ | _ |
| V_{DDC} | W20 | _ | _ | _ |
| V _{DDC} | Y11 | _ | _ | _ |
| V _{DDC} | Y19 | _ | _ | _ |
| GND | A1 | _ | _ | _ |
| GND | A29 | _ | _ | _ |
| GND | B5 | _ | _ | _ |
| GND | B14 | _ | _ | _ |
| GND | B27 | _ | _ | _ |
| GND | C6 | _ | _ | _ |
| GND | C8 | _ | _ | _ |
| GND | C11 | _ | _ | _ |
| GND | C18 | _ | _ | _ |
| GND | C24 | _ | _ | _ |
| GND | D16 | _ | _ | _ |
| GND | D22 | _ | _ | _ |
| GND | D25 | _ | _ | _ |
| GND | E3 | _ | _ | _ |

Table 1. P1021 Pinout Listing (continued)

| Signal | Package Pin Number | Pin Type | Power Supply | Notes |
|--------|--------------------|----------|--------------|-------|
| GND | E28 | _ | _ | _ |
| GND | F7 | _ | _ | _ |
| GND | G5 | _ | _ | _ |
| GND | G9 | _ | _ | _ |
| GND | G21 | _ | _ | _ |
| GND | H3 | _ | _ | _ |
| GND | H27 | _ | _ | _ |
| GND | J7 | _ | _ | _ |
| GND | J23 | _ | _ | _ |
| GND | K4 | _ | _ | _ |
| GND | F17 | _ | _ | _ |
| GND | L12 | _ | _ | _ |
| GND | L14 | _ | _ | _ |
| GND | L16 | _ | _ | _ |
| GND | L18 | _ | _ | _ |
| GND | M11 | _ | _ | _ |
| GND | K25 | _ | _ | _ |
| GND | L1 | _ | _ | _ |
| GND | L11 | _ | _ | _ |
| GND | L13 | _ | _ | _ |
| GND | L15 | _ | _ | _ |
| GND | L17 | _ | _ | _ |
| GND | L19 | _ | _ | _ |
| GND | M3 | _ | _ | _ |
| GND | M4 | _ | _ | _ |
| GND | M6 | _ | _ | _ |
| GND | M19 | _ | _ | _ |
| GND | M12 | _ | _ | _ |
| GND | M13 | _ | _ | _ |
| GND | M14 | _ | _ | _ |
| GND | M15 | _ | _ | _ |
| GND | M16 | _ | _ | _ |
| GND | M17 | _ | _ | _ |

Table 1. P1021 Pinout Listing (continued)

| Signal | Package Pin Number | Pin Type | Power Supply | Notes |
|--------|--------------------|----------|--------------|-------|
| GND | M18 | _ | _ | _ |
| GND | P11 | _ | _ | _ |
| GND | M26 | _ | _ | _ |
| GND | N2 | _ | _ | _ |
| GND | N11 | _ | _ | _ |
| GND | N12 | _ | _ | _ |
| GND | N13 | _ | _ | _ |
| GND | N14 | _ | _ | _ |
| GND | N15 | _ | _ | _ |
| GND | N16 | _ | _ | _ |
| GND | N17 | _ | _ | _ |
| GND | N18 | _ | _ | _ |
| GND | N19 | _ | _ | _ |
| GND | N28 | _ | _ | _ |
| GND | P5 | _ | _ | _ |
| GND | P19 | _ | _ | _ |
| GND | P12 | _ | _ | _ |
| GND | P13 | _ | _ | _ |
| GND | P14 | _ | _ | _ |
| GND | P15 | _ | _ | _ |
| GND | P16 | _ | _ | _ |
| GND | P17 | _ | _ | _ |
| GND | P18 | _ | _ | _ |
| GND | T11 | _ | _ | _ |
| GND | P24 | _ | _ | _ |
| GND | R3 | _ | _ | _ |
| GND | R11 | _ | _ | _ |
| GND | R12 | _ | _ | _ |
| GND | R13 | _ | _ | _ |
| GND | R14 | _ | _ | _ |
| GND | R15 | _ | _ | _ |
| GND | R16 | _ | _ | _ |
| GND | R17 | _ | _ | _ |

Table 1. P1021 Pinout Listing (continued)

| Signal | Package Pin Number | Pin Type | Power Supply | Notes |
|--------|--------------------|----------|--------------|-------|
| GND | R18 | _ | _ | _ |
| GND | R19 | _ | _ | _ |
| GND | T6 | _ | _ | _ |
| GND | T19 | _ | _ | _ |
| GND | T12 | _ | _ | _ |
| GND | T13 | _ | _ | _ |
| GND | T14 | _ | _ | _ |
| GND | T15 | _ | _ | _ |
| GND | T16 | _ | _ | _ |
| GND | T17 | _ | _ | _ |
| GND | T18 | _ | _ | _ |
| GND | V11 | _ | _ | _ |
| GND | T27 | _ | _ | _ |
| GND | U11 | _ | _ | _ |
| GND | U12 | _ | _ | _ |
| GND | U13 | _ | _ | _ |
| GND | U14 | _ | _ | _ |
| GND | U15 | _ | _ | _ |
| GND | U16 | _ | _ | _ |
| GND | U17 | _ | _ | _ |
| GND | U18 | _ | _ | _ |
| GND | U19 | _ | _ | _ |
| GND | V4 | _ | _ | _ |
| GND | V19 | _ | _ | _ |
| GND | V12 | _ | _ | _ |
| GND | V13 | _ | _ | _ |
| GND | V14 | _ | _ | _ |
| GND | V15 | _ | _ | _ |
| GND | V16 | _ | _ | _ |
| GND | V17 | _ | _ | _ |
| GND | V18 | _ | _ | _ |
| GND | W12 | _ | _ | _ |
| GND | V27 | _ | _ | _ |

Table 1. P1021 Pinout Listing (continued)

| Signal | Package Pin Number | Pin Type | Power Supply | Notes |
|------------------|--------------------|----------|--------------|-------|
| GND | W2 | _ | _ | _ |
| GND | W4 | _ | _ | _ |
| GND | W11 | _ | _ | _ |
| GND | W13 | _ | _ | _ |
| GND | W14 | _ | _ | _ |
| GND | W15 | _ | _ | _ |
| GND | W16 | _ | _ | _ |
| GND | W17 | _ | _ | _ |
| GND | W19 | _ | _ | _ |
| GND | Y3 | _ | _ | _ |
| GND | Y6 | _ | _ | _ |
| GND | Y7 | _ | _ | _ |
| GND | W18 | _ | _ | _ |
| V _{DDC} | Y12 | _ | _ | _ |
| GND | Y13 | _ | _ | _ |
| GND | Y17 | _ | _ | _ |
| V _{DDC} | Y18 | _ | _ | _ |
| V _{DDC} | Y20 | _ | _ | _ |
| GND | Y25 | _ | _ | _ |
| GND | AA6 | _ | _ | _ |
| GND | AA23 | _ | _ | _ |
| GND | AC3 | _ | _ | _ |
| GND | AC10 | _ | _ | _ |
| GND | AC20 | _ | _ | _ |
| GND | AC24 | _ | _ | _ |
| GND | AC28 | _ | _ | _ |
| GND | AD3 | _ | _ | _ |
| GND | AD6 | _ | _ | _ |
| GND | AE9 | _ | _ | _ |
| GND | AF20 | _ | _ | _ |
| GND | AG3 | _ | _ | _ |
| GND | AG5 | _ | _ | _ |
| GND | AG7 | _ | _ | _ |

Table 1. P1021 Pinout Listing (continued)

| Signal | Package Pin Number | Pin Type | Power Supply | Notes |
|--------|--------------------|----------|--------------|-------|
| GND | AG24 | _ | _ | _ |
| GND | AG27 | _ | _ | _ |
| GND | AJ1 | _ | _ | _ |
| GND | AJ29 | _ | _ | _ |

Note:

- 1. All multiplexed signals are listed only once and do not re-occur.
- 2. Recommend that a weak pull-up resistor (2–10 K Ω) be placed on this pin to OVDD.
- 4. This pin is an open drain signal.
- 5. This pin is a reset configuration pin. It has a weak internal pull-up, P-FET, which is enabled only when the processor is in the reset state. This pull-up is designed such that it can be overpowered by an external 4.7-k Ω pull-down resistor. However, if the signal is intended to be high after reset, and if there is any device on the net which might pull down the value of the net at reset, a pullup or active driver is needed.
- 8. The value of LALE, LGPL2, LBCTL, LWE_B00, UART_SOUT1, and READY_P1 at reset sets the e500 core clock to CCB Clock PLL ratio. These pins require 4.7-kΩ pull-up or pull-down resistors. See Section 4.1.4, "e500 Core PLL Ratio."
- 9. Functionally, this pin is an output, but structurally it is an I/O because it either samples configuration input during reset or because it has other manufacturing test functions. This pin is described as an I/O for boundary scan.
- 10. If this pin is configured for local bus controller usage, it is recommended that a weak pull-up resistor (2–10 $K\Omega$) be placed on this pin to BVDD, ensuring that there is no random chip select assertion due to possible noise or other factors.
- 11. This output is actively driven during reset rather than being three-stated during reset.
- 12. These JTAG pins have weak internal pull-up P-FETs that are always enabled.
- 15. Do not connect.
- 17. Independent supplies derived from board VDD.
- 18. Recommend that a pull-up resistor (\sim 1 k Ω) be placed on this pin to OVDD.
- 19. The following pins must NOT be pulled down during power-on reset: LA28, LA[17], HRESET_REQ, MSRCID[1:3], MDVAL, ASLEEP.
- 23. For DDR2 MDIC[0] is grounded through an $18.2-\Omega$ (full-strength mode) or $36.4-\Omega$ (half-strength mode) precision 1% resistor and Dn_MDIC[1] is connected to GVDD through an $18.2-\Omega$ (full-strength mode) or $36.4-\Omega$ (half-strength mode) precision 1% resistor. These pins are used for automatic calibration of the DDR IOs. The calibration resistor value for DDR3 should be $20-\Omega$ (full-strength mode) or $40-\Omega$ (half-strength mode).

Table 1. P1021 Pinout Listing (continued)

- 25. DDRCLK input is only required when the P1021 DDR controller is running in asynchronous mode. When the DDR controller is configured to run in synchronous mode via POR setting cfg_ddr_pll[0:2] = 111, the DDRCLK input is not required. It is recommended that users tie it off to GND when DDR controller is running in synchronous mode. See the P1021 QorlQ™ Integrated Host Processor Family Reference Manual, the "Clock Signals" section and the "DDR Complex Clock PLL Ratio" table in the "DDR PLL Ratio" section, for a more detailed description of DDR controller operation in asynchronous and synchronous modes
- 26. EC_GTX_CLK125 is a 125-MHz input clock shared among all eTSEC ports in the following modes: GMII, TBI, RGMII, and RTBI. If none of the eTSEC ports is operating in these modes, the EC_GTX_CLK125 input can be tied off to GND.
- 27. These POR configuration inputs may be used in the future to control functionality. It is advised that boards are built with the ability to pulldown these pins .LA[20:22], UART_SOUT[0], and MSRCID[4] are reserved for future reset configuration.
- 28. Incorrect settings can lead to irreversible device damage.
- 29. The value of LAD[0:15] during reset sets the upper 16 bits of the GPPORCR.
- 31. The value of LA27 and LA16 during reset is used to determine CPU boot configuration. See the "CPU Boot POR Configuration," section in the applicable device reference manual.
- 32. It must be the same as V_{DD}_Core.
- 33. When eTSEC1 and eTSEC3 are used as parallel interfaces, pins TSEC1_TX_EN and TSEC3_TX_EN requires an external 4.7-k_ pull-down resistor to prevent PHY from seeing a valid Transmit Enable before it is actively driven. However, because of the pull-down resistor on TSEC3_TX_EN cause the eSDHC card-detect (cfg_sdhc_cd_pol_sel) to be inverted, the inversion should be overridden from the SDHCDCR [CD_INV] debug control register.
- 34. SD_IMP_CAL_RX should be grounded through an $200-\Omega$ precision 1% resistor and SD_IMP_CAL_TX is grounded through an $100-\Omega$ precision 1% resistor.
- 36. For systems which boot from Local Bus (GPCM)-controlled NOR flash or (FCM)-controlled NAND flash, a pull-up on LGPL4 is required.
- 37. Refer to Section 4.7, "Pull-Up and Pull-Down Resistor Requirements," for the correct settings.

2 Electrical Characteristics

This section provides the AC and DC electrical specifications. The processor is currently targeted to these specifications. Some of these specifications are independent of the I/O cell, but are included for a more complete reference. These are not purely I/O buffer design specifications.

2.1 Overall DC Electrical Characteristics

This section covers the ratings, conditions, and other characteristics.

2.1.1 Absolute Maximum Ratings

Table 2 provides the absolute maximum ratings.

Table 2. Absolute Maximum Ratings¹

| Characteristic | Symbol | Max Value | Unit | Notes |
|------------------------------------|-----------|--------------|------|-------|
| Core 0 and platform supply voltage | V_{DDC} | -0.3 to 1.05 | V | - |
| Core 1 supply voltage | V_{DD} | -0.3 to 1.05 | V | _ |

Table 2. Absolute Maximum Ratings¹ (continued)

| | Characteristic | Symbol | Max Value | Unit | Notes |
|--|--|---|--|--------|-------|
| PLL supply voltage | | AV _{DD} _CORE0 AV _{DD} _CORE1 AV _{DD} _DDR AV _{DD} _PLAT AV _{DD} _SRDS | -0.3 to 1.05 | V | 8 |
| Core power supply | for SerDes transceivers | SV _{DD} _SRDS | -0.3 to 1.05 | V | _ |
| Pad power supply for | or SerDes transceivers | XV _{DD} _SRDS | -0.3 to 1.05 | V | _ |
| DDR2/3 DRAM I/O | voltage | GV _{DD} | -0.3 to 1.98 | V | _ |
| Three-speed Ethernet I/O, MII management voltage (eTSEC) | | LV _{DD} | -0.3 to 3.63 -0.3 to 2.75 | V | 1,4 |
| DUART, system control and power management, I ² C, and JTAG I/O voltage | | OV _{DD} | -0.3 to 3.63 | \ \ | _ |
| USB, eSPI, eSDHC | | CV _{DD} | -0.3 to 3.63 -0.3 to 2.75 -0.3 to 1.98 | V | _ |
| Enhanced local bus I/O voltage | | BV _{DD} | -0.3 to 3.63 -0.3 to 2.75 -0.3 to 1.98 | V | _ |
| Input voltage | DDR2/DDR3 DRAM signals | MV _{IN} | -0.3 to (GV _{DD} + 0.3) | V | 2, 7 |
| | DDR2/DDR3 DRAM reference | MV _{REF} | -0.3 to (GV _{DD} /2 + 0.3) | ٧ | _ |
| | Three-speed Ethernet signals | LV _{IN} | -0.3 to (LV _{DD} + 0.3) | V | 3, 7 |
| | Enhanced local bus signals | BV _{IN} | -0.3 to (BV _{DD} + 0.3) | _ | 5 |
| | DUART, SYSCLK, system control and power management, I ² C, clocking, I/O voltage select, and JTAG I/O voltage | OV _{IN} | -0.3 to (OV _{DD} + 0.3) | V | 6, 7 |
| | USB, eSPI, eSDHC | CV _{IN} | -0.3 to (CV _{DD} + 0.3) | ٧ | 4 |
| | SerDes signals | XV _{IN} | -0.3 to (XV _{DD} + 0.3) | V | _ |

Electrical Characteristics

Table 2. Absolute Maximum Ratings¹ (continued)

| Characteristic | Symbol | Max Value | Unit | Notes |
|---------------------------|------------------|------------|------|-------|
| Storage temperature range | T _{STG} | -55 to 150 | °C | - |

- 1. Functional operating conditions are given in Table 3. Absolute maximum ratings are stress ratings only, and functional operation at the maximums is not guaranteed. Stresses beyond those listed may affect device reliability or cause permanent damage to the device.
- 2. Caution: MVIN must not exceed GVDD by more than 0.3 V. This limit may be exceeded for a maximum of 20 ms during power-on reset and power-down sequences.
- 3. Caution: LVIN must not exceed LVDD by more than 0.3 V. This limit may be exceeded for a maximum of 20 ms during power-on reset and power-down sequences.
- 4. Caution: CVIN must not exceed CVDD by more than 0.3 V. This limit may be exceeded for a maximum of 20 ms during power-on reset and power-down sequences.
- 5. Caution: BVIN must not exceed BVDD by more than 0.3 V. This limit may be exceeded for a maximum of 20 ms during power-on reset and power-down sequences.
- 6. Caution: OVIN must not exceed OVDD by more than 0.3 V. This limit may be exceeded for a maximum of 20 ms during power-on reset and power-down sequences.
- 7. (C,X,B,G,L,O)VIN and MV_{REF} may overshoot/undershoot to a voltage and for a maximum duration as shown in Figure 7.
- AV_{DD} is measured at the input to the filter (as shown in Section 4.3.1, "PLL Power Supply Filtering") and not at the pin of the device.

2.1.2 Recommended Operating Conditions

Table 3 provides the recommended operating conditions for this device. Note that the values in Table 3 are the recommended and tested operating conditions. Proper device operation outside these conditions is not guaranteed.

Table 3. Recommended Operating Conditions

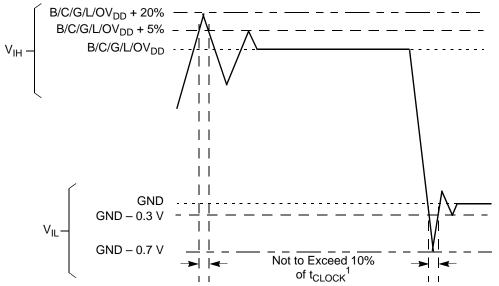
| Characteristic | Symbol | Recommended Value | Unit | Notes |
|--|---|---|------|-------|
| Core 0 and platform supply voltage | V _{DDC} | 1.0 ± 50 mV | V | 1 |
| Core 1 supply voltage | V_{DD} | 1.0 ± 50 mV | V | 1 |
| PLL supply voltage | $\begin{array}{c} {\rm AV_{DD_CORE0}} \\ {\rm AV_{DD_CORE1}} \\ {\rm AV_{DD_DDR}} \\ {\rm AV_{DD_PLAT}} \\ {\rm AV_{DD_SRDS}} \end{array}$ | 1.0 ± 50 mV | V | _ |
| Core power supply for SerDes transceivers | SV _{DD} _SRDS | 1.0 ± 50 mV | V | _ |
| Pad power supply for SerDes transceivers and PCI Express | XV _{DD} _SRDS | 1.0 ± 50 mV | V | _ |
| DDR2 DRAM I/O voltage | GV _{DD} | 1.8 V ± 90 mV | V | _ |
| DDR3 DRAM I/O voltage | GV _{DD} | 1.5 V ± 75 mV | _ | _ |
| Three-speed Ethernet I/O voltage (eTSEC) | LV _{DD} | 3.3 V ± 165 mV 2.5 V ± 125 mV | V | _ |
| DUART, system control and power management, I ² C, QUICC Engine block, and JTAG I/O voltage | OV _{DD} | 3.3 V ± 165 mV | V | _ |
| Enhanced local bus I/O and QUICC Engine block voltage | BV _{DD} | 3.3 V ± 165 mV | V | _ |
| USB, eSPI, eSDHC | CV _{DD} | 3.3 V ± 165 mV 2.5 V ± 125 mV 1.8 V ± 90 mV | V | |

| | Characteristic | Symbol | Recommended Value | Unit | Notes |
|----------------|--|-------------------|--|------|-------|
| Input voltage | DDR2/3 DRAM signals | MV _{IN} | GND to GV _{DD} | V | _ |
| | DDR2/3 DRAM reference | MV _{REF} | GND to GV _{DD} /2 | V | _ |
| | Three-speed Ethernet signals | LV _{IN} | GND to LV _{DD} | V | _ |
| | Enhanced local bus signals | BV _{IN} | GND to BV _{DD} | V | _ |
| | DUART, SYSCLK, system control and power management, I ² C, and JTAG signals | OV _{IN} | GND to OV _{DD} | V | _ |
| | USB, eSPI, eSDHC | CVIN | GND to CV _{DD} | V | _ |
| Junction tempe | rature range | TA/TJ | 0 to 125 Commercial -40 to 125 Industrial | °C | 3 |

Notes:

- 1. Caution: Until V_{DD} reaches its recommended operating voltage, V_{DD} may exceed L/C/B/G/OV_{DD} by up to 0.7 V. If 0.7 V is exceeded, extra current will be drawn by the device.
- 2. Caution: Until V_{DD} reaches its recommended operating voltage, if L/C/B/G/OV_{DD} exceeds V_{DD}, extra current may be drawn by the device.
- 3. Min temp is specified with TA; Max temp is specified with TJ.

Figure 7 shows the undershoot and overshoot voltages at the interfaces of the device.



Note:

- 1. t_{CLOCK} refers to the clock period associated with the respective interface:

 - For I 2 C and JTAG, t_{CLOCK} references SYSCLK. For DDR, t_{CLOCK} references MCK. For eTSEC, t_{CLOCK} references EC_GTX_CLK125.
 - For eLBC, t_{CLOCK} references LCLK.

Figure 7. Overshoot/Undershoot Voltage for BV_{DD}/CV_{DD}/GV_{DD}/LV_{DD}/OV_{DD}

The core voltage must always be provided at nominal 1.0 V (see Table 3 for actual recommended core voltage). Voltage to the processor interface I/Os are provided through separate sets of supply pins and must be provided at the voltages shown in Table 3. The input voltage threshold scales with respect to the associated I/O supply voltage. OV_{DD} and LV_{DD} based receivers are simple CMOS I/O circuits and satisfy appropriate LVCMOS type specifications. The SDRAM interface uses a differential receiver

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referenced the externally supplied MV_{REF} signal (nominally set to $GV_{DD}/2$). The DDR DQS receivers cannot be operated in single-ended fashion. The complement signal must be properly driven and cannot be grounded.

2.1.3 Output Driver Characteristics

Table 4 provides information on the characteristics of the output driver strengths. The values are preliminary estimates.

Table 4. Output Drive Capability

| Driver Type | Output Impedance (Ω) | Supply Voltage | Notes |
|------------------------------|-------------------------------|--|-------|
| Enhanced local bus interface | 45 | BV _{DD} = 3.3 V | _ |
| DDR2/3 signal (Programmable) | 16 32 (half strength mode) | GV _{DD} = 1.8 V DDR2 GV _{DD} = 1.5 V DDR3 | 1 |
| TSEC signals | 45 | $LV_{DD} = 2.5/3.3 \text{ V}$ | _ |
| DUART, system control, JTAG | 45 | OV _{DD} = 3.3 V | _ |
| I ² C | 45 | OV _{DD} = 3.3 V | _ |
| USB, SPI, eSDHC | 45 | $CV_{DD} = 3.3 V$ $CV_{DD} = 2.5 V$ $CV_{DD} = 1.8 V$ | _ |

Notes:

2.2 Power Sequencing

The processor requires that its power rails be applied in a specific sequence in order to ensure proper device operation. These requirements are as follows for power up:

- $1. \quad V_{DD}, \, V_{DDC}, \, AV_{DD}, \, BV_{DD}, \, LV_{DD}, \, CV_{DD,} \, OV_{DD}, \, SV_{DD_SRDS} \, and, \, XV_{DD_SRDS}$
- 2. GV_{DD}

All supplies must be at their stable values within 50 ms.

Items on the same line have no ordering requirement with respect to one another. Items on separate lines must be ordered sequentially such that voltage rails on a previous step must reach 90% of their value before the voltage rails on the current step reach 10% of theirs.

To guarantee MCKE low during power-up, the above sequencing for GV_{DD} is required. If there is no concern about any of the DDR signals being in an indeterminate state during power-up, the sequencing for GV_{DD} is not required.

NOTE

From a system standpoint, if any of the I/O power supplies ramp prior to the V_{DD} core supply, the I/Os associated with that I/O supply may drive a logic one or zero during power-up, and extra current may be drawn by the device.

^{1.} The drive strength of the DDR2/3 interface in half-strength mode is at T_i = 105°C and at GV_{DD} (min)

2.3 Power Down Requirements

The power-down cycle must complete such that power supply values are below 0.4 V before a new power-up cycle can be started.

2.4 RESET Initialization

This section describes the AC electrical specifications for the RESET initialization timing requirements. Table 5 provides the RESET initialization AC timing specifications for the DDR SDRAM component(s).

Table 5. RESET Initialization Timing Specifications

| Parameter/Condition | Min | Max | Unit | Notes |
|---|-----|-----|---------|-------|
| Required assertion time of HRESET | 25 | _ | μS | 1, 2 |
| Minimum assertion time of TRESET simultaneous to HRESET assertion | 25 | _ | ns | 3 |
| Maximum rise/fall time of HRESET | _ | 1 | SYSCLK | _ |
| Minimum assertion time for SRESET | 3 | _ | SYSCLKs | 4 |
| Input setup time for POR configs (other than PLL config) with respect to negation of HRESET | 4 | _ | SYSCLKs | 4 |
| Input hold time for all POR configs (including PLL config) with respect to negation of HRESET | 2 | _ | SYSCLKs | 4 |
| Maximum valid-to-high impedance time for actively driven POR configs with respect to negation of HRESET | _ | 5 | SYSCLKs | 4 |

Notes:

- 1. There may be some extra current leakage when driving signals high during this time.
- 2. Reset assertion timing requirements for DDR3 DRAMs may differ.
- 3. TRST is an asynchronous level sensitive signal. For guidance on how this requirement can be met, refer to the JTAG signal termination guidelines in Section 4.10, "JTAG Configuration Signals."
- 4. SYSCLK is the primary clock input for the processor.

Table 6 provides the PLL lock times.

Table 6. PLL Lock Times

| Parameter/Condition | Min | Max | Unit | Notes |
|---------------------|-----|-----|------|-------|
| PLL lock times | _ | 100 | μs | |

2.5 Power-on Ramp Rate

This section describes the AC electrical specifications for the power-on ramp rate requirements. Controlling the maximum power-on ramp rate is required to avoid falsely triggering the ESD circuitry. Table 7 provides the power supply ramp rate specifications.

Table 7. Power Supply Ramp Rate

| Parameter | Min | Max | Unit | Notes |
|--|-----|-------|------|-------|
| Required ramp rate for all voltage supplies (including OVDD/CVDD/GVDD/SVDD/SVDD/LVDD, All VDD suplies, MVREF and all AVDD supplies.) | _ | 36000 | V/s | 1, 2 |

Note:

- 1. Ramp rate is specified as a linear ramp from 10 to 90%. If non-linear (e.g. exponential), the maximum rate of change from 200 to 500 mV is the most critical as this range might falsely trigger the ESD circuitry.
- 2. Over full recommended operating temperature range (see Table 3).

2.6 Power Characteristics

The estimated typical core power dissipation for the core complex bus (CCB) versus the core frequency for this family of QorIQ devices is shown in Table 8.

Core Frequency Platform Junction $V_{DD}(V)$ **Power Mode** Power (W) **Notes** Frequency (MHz) Temperature (°C) (MHz) 533 266 1.0 Typical 65 **TBD** 2, 3 Maximum 105 2, 4 2.4 2, 4 125 2.9 667 333 1.0 Typical 65 **TBD** 2, 3 Maximum 105 2.6 2, 4 125 3.0 2, 4 800 400 **TBD** 2, 3 1.0 Typical 65 Maximum 105 3.0 2, 4 125 3.6 2, 4

Table 8. Core Power Dissipation

- 1. This table includes power numbers for the VDD and AVDD_n rails.
- 2. These values specify the power consumption at nominal voltage and apply to all valid processor bus frequencies and configurations. The values do not include power dissipation for I/O supplies.
- 3. Typical power is an average value measured while running the Dhrystone benchmark, using the *nominal* process and *recommended* core and platform voltages (V_{DD}) at 65 °C junction temperature
- 4 Maximum power is the maximum power measured at nominal core voltage (V_{DD}) and maximum operating junction temperature (see Table 3) while running a test which includes an entirely L1-cache-resident, contrived sequence of instructions which keep all the execution units busy with the cores running at 75% utilization and a typical workload on platform blocks.

2.6.1 I/O DC Power Supply Recommendation

Table 9 provides estimated I/O power numbers for each block: DDR, PCIe, eLBC, eTSEC, SGMII, eSDHC, USB, eSPI, DUART, I²C, and GPIO.

Table 9. I/O Power Supply Estimated Values

| Interface | Parameter | Symbol | Typical | Unit | Notes |
|-----------------------------------|-------------------|----------------------------|---------|------|---------|
| DDR3 75% utilization | 600 MHz data rate | GV _{DD} (1.5 V) | 0.76 | W | 1, 2 |
| | 667 MHz data rate | GV _{DD} (1.5 V) | 0.82 | W | 1, 2 |
| DDR3 40% utilization | 600 MHz data rate | GV _{DD} (1.5 V) | 0.57 | W | 1, 2 |
| | 667 MHz data rate | GV _{DD} (1.5 V) | 0.63 | W | 1, 2 |
| PCI Express | ×1, 2.5 G-baud | X/SV _{DD} (1.0 V) | 0.11 | W | 1 |
| | ×2, 2.5 G-baud | X/SV _{DD} (1.0 V) | 0.15 | W | 1 |
| | ×4, 2.5 G-baud | X/SV _{DD} (1.0 V) | 0.229 | W | 1 |
| SGMII | ×1, 1.25G-baud | X/SV _{DD} (1.0 V) | 0.096 | W | 1 |
| eLBC | 16-bit, 83MHz | BV _{DD} (1.8 V) | 0.017 | W | 1, 3 |
| | | BV _{DD} (2.5 V) | 0.03 | W | 1, 3 |
| | | BV _{DD} (3.3 V) | 0.047 | W | 1, 3 |
| eTSEC | RGMII | LV _{DD} (2.5 V) | 0.075 | W | 1, 3, 4 |
| | | LV _{DD} (3.3 V) | 0.124 | W | 1, 3, 4 |
| eSDHC | _ | CV _{DD} (1.8 V) | 0.005 | W | 1, 3 |
| | | CV _{DD} (2.5 V) | 0.009 | W | 1, 3 |
| | | CV _{DD} (3.3 V) | 0.014 | W | 1, 3 |
| USB | _ | CV _{DD} (1.8 V) | 0.004 | W | 1, 3 |
| | | CV _{DD} (2.5 V) | 0.008 | W | 1, 3 |
| | | CV _{DD} (3.3 V) | 0.012 | W | 1, 3 |
| eSPI | _ | CV _{DD} (1.8 V) | 0.004 | W | 1, 3 |
| | | CV _{DD} (2.5 V) | 0.006 | W | 1, 3 |
| | | CV _{DD} (3.3 V) | 0.01 | W | 1, 3 |
| I ² C | _ | OV _{DD} (3.3 V) | 0.002 | W | 1, 3 |
| DUART | _ | OV _{DD} (3.3 V) | 0.006 | W | 1, 3 |
| IEEE1588 | _ | LV _{DD} (2.5 V) | 0.004 | W | 1, 3 |
| | | LV _{DD} (3.3 V) | 0.007 | W | 1, 3 |
| QUICC Engine block (UTOPIA) L2 | _ | BV _{DD} (3.3 V) | 0.08 | W | 1, 3 |

- 1. The typical values are estimates based on simulations 65 C junction temperature.
- 2. DDR power numbers are based on 2 rank DIMM.
- 3. Assuming 15 pF total capaciatnce load per pin.
- 4. The current values are per each eTSEC used.
- 5. GPIO x8 support on OVDD and x8 on BVDD rail supply.

2.7 Input Clocks

This section discusses the system clock timing, SYSCLK and spread spectrum sources, real time clock timing, eTSEC Gigabit reference clock timing, DDR clock timing, and other input clocks.

2.7.1 System Clock Timing

Table 10 provides the system clock (SYSCLK) DC specifications.

Table 10. SYSCLK DC Electrical Characteristics

At recommended operating conditions with $OV_{DD} = 3.3 \text{ V} \pm 165 \text{ mV}$

| Parameter | Symbol | Min | Typical | Max | Unit | Notes |
|--|-----------------|-----|---------|-----|------|-------|
| Input high voltag | V _{IH} | 2.0 | _ | | V | 1 |
| Input low voltage | V _{IL} | _ | _ | 0.8 | V | 1 |
| Input capacitance | C _{IN} | _ | 7 | 15 | pf | _ |
| Input current (V _{IN} = 0 V or V _{IN} = V _{DD)} | I _{IN} | _ | _ | ±50 | μΑ | 2 |

Note:

- 1. The max V_{IH} , and min V_{IL} values can be found in Table 3.
- 2. The symbol V_{IN} , in this case, represents the OV_{IN} symbol referenced in Table 3.

Table 11 provides the system clock (SYSCLK) AC timing specifications.

Table 11. SYSCLK AC Timing Specifications

At recommended operating conditions (see Table 3) with $OV_{DD} = 3.3 \text{ V} \pm 165 \text{ mV}$

| Parameter/Condition | Symbol | Min | Typical | Max | Unit | Notes |
|---|---------------------------------------|-----|---------|-------|------|-------|
| SYSCLK frequency | f _{SYSCLK} | 64 | _ | 100 | MHz | 1 |
| SYSCLK cycle time | tsysclk | 10 | _ | 15 | ns | _ |
| SYSCLK duty cycle | t _{KHK} /t _{SYSCLK} | 40 | _ | 60 | % | 2 |
| SYSCLK slew rate | _ | 1 | _ | 4 | V/ns | 3 |
| SYSCLK peak period jitter | _ | _ | _ | ± 150 | ps | _ |
| SYSCLK jitter phase noise at – 56dBc | _ | _ | _ | 500 | KHz | 4 |
| AC Input Swing Limits at 3.3 V OV _{DD} | ΔV_{AC} | 1.9 | _ | _ | V | _ |

- 1. Caution: The CCB_clk to SYSCLK ratio and e500 core to CCB_clk ratio settings must be chosen such that the resulting SYSCLK frequency, e500 core frequency, and CCB_clk frequency do not exceed their respective maximum or minimum operating frequencies. Refer to Section 4.1.3, "CCB/SYSCLK PLL Ratio," and Section 4.1.4, "e500 Core PLL Ratio" for ratio settings. Refer to Section 4.1.3, "CCB/SYSCLK PLL Ratio," and Section 4.1.4, "e500 Core PLL Ratio" for ratio settings.
- 2. Measured at the rising edge and/or the falling edge at ${\rm OV_{DD}/2}$.
- 3. Slew rate as measured from \pm 0.3 ΔV_{AC} at center of peak to peak voltage at clock input.
- 4. Phase noise is calculated as FFT of TIE jitter.

2.7.2 SYSCLK and Spread Spectrum Sources

Spread spectrum clock sources are an increasingly popular way to control electromagnetic interference emissions (EMI) by spreading the emitted noise to a wider spectrum and reducing the peak noise magnitude in order to meet industry and government requirements. These clock sources intentionally add long-term jitter in order to diffuse the EMI spectral content. The jitter specification given in Table 12 considers short-term (cycle-to-cycle) jitter only and the clock generator's cycle-to-cycle output jitter should meet the processor's input cycle-to-cycle jitter requirement. Frequency modulation and spread are separate concerns, and the P1021 is compatible with spread spectrum sources if the recommendations listed in Table 12 are observed.

Table 12. Spread Spectrum Clock Source Recommendations

At recommended operating conditions. See Table 3.

| Parameter | Min | Max | Unit | Notes |
|----------------------|-----|-----|------|-------|
| Frequency modulation | _ | 60 | kHz | _ |
| Frequency spread | _ | 1.0 | % | 1, 2 |

Note:

- 1. SYSCLK frequencies resulting from frequency spreading, and the resulting core and VCO frequencies, must meet the minimum and maximum specifications given in Table 11.
- 2. Maximum spread spectrum frequency may not result in exceeding any maximum operating frequency of the device.

CAUTION

The processor's minimum and maximum SYSCLK, DDRCLK, core, and VCO frequencies must not be exceeded regardless of the type of clock source. Therefore, systems in which the processor is operated at its maximum rated e500 core/DDR memory frequency should avoid violating the stated limits by using down-spreading only.

2.7.3 Real Time Clock Timing

The real time clock timing (RTC) input is sampled by the platform clock (CCB clock). The output of the sampling latch is then used as an input to the counters of the PIC and the TimeBase unit of the e500. There is no jitter specification. The minimum pulse width of the RTC signal should be greater than $2\times$ the period of the CCB clock. That is, minimum clock high time is $2\times t_{CCB}$, and minimum clock low time is $2\times t_{CCB}$. There is no minimum RTC frequency; RTC may be grounded if not needed.

2.7.4 eTSEC Gigabit Reference Clock Timing

Table 13 lists the eTSEC gigabit reference clock DC electrical characteristics.

Table 13. eTSEC Gigabit Reference Clock DC Electrical Characteristics

| Parameter | Symbol | Min | Max | Unit | Notes |
|--|-----------------|-----|-----|------|-------|
| High-level input voltage | V _{IH} | 2 | _ | V | 1 |
| Low-level input voltage | V _{IL} | _ | 0.8 | V | 1 |
| Input current (V _{IN} = 0 V or V _{IN} = V _{DD)} | I _{IN} | _ | ±40 | μΑ | 2 |

- 1. The max $V_{\mbox{\scriptsize IH}},$ and min $V_{\mbox{\scriptsize IL}}$ values can be found in Table 3.
- 2. The symbol V_{IN} , in this case, represents the OV_{IN} symbol referenced in Table 3.

Table 14 provides the eTSEC gigabit reference clocks (EC_GTX_CLK125) AC timing specifications.

Table 14. EC_GTX_CLK125 AC Timing Specifications

At recommended operating conditions with LV_{DD} = 2.5 ± 0.125 mV/ 3.3 V ± 165 mV

| Parameter/Condition | Symbol | Min | Typical | Max | Unit | Notes |
|--|--|-----|---------|-------------|------|-------|
| EC_GTX_CLK125 frequency | t _{G125} | _ | 125 | _ | MHz | _ |
| EC_GTX_CLK125 cycle time | t _{G125} | _ | 8 | _ | ns | _ |
| EC_GTX_CLK rise and fall time | t _{G125R} /t _{G125F} | _ | | 0.75 1.0 | ns | 1 |
| EC_GTX_CLK125 duty cycle 1000Base-T for RGMII | t _{G125H} /t _{G125} | 47 | _ | 53 | % | 2 |
| EC_GTX_CLK125 jitter | _ | _ | _ | ±150 | ps | 2 |

Notes:

- 1. Rise and fall times for EC_GTX_CLK125 are measured from 0.5 and 2.0 V for LV_{DD} = 2.5 V and from 0.6 and 2.7 V for LV_{DD} = 3.3 V.
- 2..EC_GTX_CLK125 is used to generate the GTX clock for the eTSEC transmitter with 2% degradation. EC_GTX_CLK125 duty cycle can be loosened from 47/53% as long as the PHY device can tolerate the duty cycle generated by the eTSEC GTX_CLK. See Section 2.11.3.2, "RGMII AC Timing Specifications," for duty cycle for 10Base-T and 100Base-T reference clock.

2.7.5 DDR Clock Timing

Table 15 provides the system clock (DDRCLK) DC specifications.

Table 15. DDRCLK DC Electrical Characteristics

At recommended operating conditions with $OV_{DD} = 3.3 \text{ V} \pm 165 \text{ mV}$

| Parameter | Symbol | Min | Typical | Max | Unit | Notes |
|--|-----------------|------|---------|------------------------|------|-------|
| Input high voltage | V _{IH} | 2.0 | _ | OV _{DD} + 0.3 | V | 1 |
| Input low voltage | V_{IL} | -0.3 | _ | 0.8 | V | 1 |
| Input capacitance | C _{IN} | _ | 7 | 15 | pf | _ |
| Input current (V _{IN} = 0 V or V _{IN} = V _{DD)} | I _{IN} | _ | _ | ±50 | μΑ | 2 |

Note:

1. The symbol V_{IN}, in this case, represents the OV_{IN} symbol referenced in Table 2 and Table 3.

Table 16 provides the DDR clock (DDRCLK) AC timing specification.

Table 16. DDRCLK AC Timing Specifications

At recommended operating conditions with OV_{DD} of 3.3 V ± 5%.

| Parameter/Condition | Symbol | Min | Typical | Max | Unit | Notes |
|---------------------|---------------------------------------|------|---------|-------|------|-------|
| DDRCLK frequency | f _{DDRCLK} | 66.7 | _ | 166.7 | MHz | 1, 2 |
| DDRCLK cycle time | t _{DDRCLK} | 6 | _ | 15 | ns | 1, 2 |
| DDRCLK duty cycle | t _{KHK} /t _{DDRCLK} | 40 | _ | 60 | % | 2 |
| DDRCLK slew rate | _ | 1 | _ | 4 | V/ns | 3 |

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Table 16. DDRCLK AC Timing Specifications (continued)

At recommended operating conditions with OV_{DD} of 3.3 V ± 5%.

| Parameter/Condition | Symbol | Min | Typical | Max | Unit | Notes |
|---|-----------------|-----|---------|------|------|-------|
| DDRCLK peak period jitter | _ | _ | _ | ±150 | ps | _ |
| DDRCLK jitter phase noise at – 56dBc | _ | _ | _ | 500 | KHz | 4 |
| AC Input Swing Limits at 3.3 V OV _{DD} | ΔV_{AC} | 1.9 | _ | _ | V | _ |

Notes:

- Caution: The DDR complex clock to DDRCLK ratio settings must be chosen such that the resulting DDR complex clock frequency does not exceed the maximum or minimum operating frequencies. Refer to Section 4.1.5, "DDR/DDRCLK PLL Ratio," for ratio settings.
- 2. Measured at the rising edge and/or the falling edge at OV_{DD}/2.
- 3. Slew rate as measured from \pm 0.3 ΔV_{AC} at center of peak to peak voltage at clock input.
- 4. Phase noise is calculated as FFT of TIE jitter.

2.7.6 Other Input Clocks

A description of the overall clocking of this device is available in the *QorIQ P102 1Integrated Host Processor Family Reference Manual* in the form of a clock subsystem block diagram. For information on the input clocks of other functional blocks of the platform, such as SerDes and eTSEC, see the specific section of this document.

2.8 DDR2 and DDR3 SDRAM

This section describes the DC and AC electrical specifications for the DDR SDRAM interface. Note that the required $GV_{DD}(typ)$ voltage is 1.8 V or 1.5 V when interfacing to DDR2 or DDR3 SDRAM respectively.

2.8.1 DDR SDRAM DC Electrical Characteristics

Table 17 provides the recommended operating conditions for the DDR SDRAM component(s) when interfacing to DDR2 SDRAM.

Table 17. DDR2 SDRAM Interface DC Electrical Characteristics

At recommended operating condition with $GV_{DD} = 1.8 V1$

| Parameter | Symbol | Min | Max | Unit | Notes |
|-----------------------|-------------------|-------------------------------------|-------------------------------------|------|---------|
| I/O reference voltage | MV _{REF} | $0.49 \times \text{GV}_{\text{DD}}$ | $0.51 \times \text{GV}_{\text{DD}}$ | V | 2, 3, 4 |
| Input high voltage | V _{IH} | MV _{REF} + 0.125 | _ | V | 5 |
| Input low voltage | V_{IL} | _ | MV _{REF} - 0.125 | V | 5 |

Table 17. DDR2 SDRAM Interface DC Electrical Characteristics (continued)

At recommended operating condition with GV_{DD} = 1.8 V1

| Parameter | Symbol | Min | Мах | Unit | Notes |
|---|-----------------|-------------|-----|------|-------|
| Output high current (V _{OUT} = 1.37 V) | I _{OH} | -13.4 | _ | mA | 6 |
| Output low current (V _{OUT} = 0.330 V) | l _{OL} | 13.4 | _ | mA | 6 |
| I/O leakage current | l _{OZ} | – 50 | 50 | μΑ | 7 |

Notes:

- GV_{DD} is expected to be within 50 mV of the DRAM's voltage supply at all times. The DRAM's and memory controller's voltage supply may or may not be from the same source.
- 2. MV_{REF} is expected to be equal to 0.5 × GV_{DD} and to track GV_{DD} DC variations as measured at the receiver. Peak-to-peak noise on MV_{RFF} may not exceed ±2% of the DC value.
- 3. V_{TT} is not applied directly to the device. It is the supply to which far end signal termination is made, and it is expected to be equal to MV_{REF} with a min value of MV_{REF} 0.04 and a max value of MV_{REF} + 0.04. V_{TT} should track variations in the DC level of MV_{REF} .
- 4. The voltage regulator for MV $_{\mbox{\scriptsize REF}}$ must be able to supply up to 1500 $\mu\mbox{\scriptsize A}.$
- 5. Input capacitance load for DQ, DQS, and \overline{DQS} are available in the IBIS models.
- 6. Refer to the IBIS model for the complete output IV curve characteristics.
- 7. Output leakage is measured with all outputs disabled, 0 V \leq V_{OUT} \leq GV_{DD}.

Table 18 provides the DDR controller interface capacitance for DDR2 and DDR3.

Table 18. DDR2 DDR3 SDRAM Capacitance

At recommended operating conditions with GV_{DD} of 1.8 V \pm 5% for DDR2 or 1.5 V \pm 5% for DDR3

| Parameter | Symbol | Min | Max | Unit | Notes |
|--|------------------|-----|-----|------|-------|
| Input/output capacitance: DQ, DQS, DQS | C _{IO} | 6 | 8 | pF | 1, 2 |
| Delta input/output capacitance: DQ, DQS, DQS | C _{DIO} | _ | 0.5 | pF | 1, 2 |

Note:

- 1. This parameter is sampled. GVDD = 1.8 V \pm 0.1 V (for DDR2), f = 1 MHz, T_A = 25°C, V_{OUT} = GVDD/2, V_{OUT} (peak-to-peak) = 0.2 V.
- 2. This parameter is sampled. GVDD = 1.5 V \pm 0.075 V (for DDR3), f = 1 MHz, T_A = 25°C, V_{OUT} = GVDD/2, V_{OUT} (peak-to-peak) = 0.175 V.

Table 19 provides the current draw characteristics for MV_{REF}.

Table 19. Current Draw Characteristics for MV_{RFF}

For recommended operating conditions, see Table 3.

| Parameter | Symbol | Min | Мах | Unit | Notes |
|---|-------------------|-----|------|------|-------|
| Current draw for DDR2 SDRAM for MV _{REF} | MV _{REF} | _ | 1500 | μΑ | _ |
| Current draw for DDR3 SDRAM for MV _{REF} | MV_REF | _ | 1250 | μΑ | _ |

2.8.2 DDR2 and DDR3 SDRAM Interface AC Timing Specifications

This section provides the AC timing specifications for the DDR SDRAM controller interface. The DDR controller supports both DDR2 and DDR3 memories. Note that the required GV_{DD}(typ) voltage is 1.8 V or 1.5 V when interfacing to DDR2 or DDR3 SDRAM respectively.

2.8.2.1 DDR2 and DDR3 SDRAM Interface Input AC Timing Specifications

Table 20 provides the input AC timing specifications for the DDR controller when interfacing to DDR2 SDRAM.

Table 20. DDR2 SDRAM Interface Input AC Timing Specifications

At recommended operating conditions with GV_{DD} of 1.8 V ± 5%

| Param | eter | Symbol | Min | Max | Unit | Notes |
|-----------------------|---------------------|-------------------|--------------------------|--------------------------|------|-------|
| AC input low voltage | ≥ 667 MHz data rate | V _{ILAC} | _ | MV _{REF} - 0.20 | V | _ |
| | ≤ 533 MHz data rate | | _ | MV _{REF} - 0.25 | | |
| AC input high voltage | ≥ 667 MHz data rate | V _{IHAC} | MV _{REF} + 0.20 | _ | V | _ |
| | ≤ 533 MHz data rate | | MV _{REF} + 0.25 | _ | | |

Table 21 provides the input AC timing specifications for the DDR controller when interfacing to DDR3 SDRAM.

Table 21. DDR3 SDRAM Interface Input AC Timing Specifications

At recommended operating conditions with GV_{DD} of 1.5 V ± 5%

| Parameter | Symbol | Min | Max | Unit | Notes |
|-----------------------|-------------------|---------------------------|---------------------------|------|-------|
| AC input low voltage | V _{ILAC} | _ | MV _{REF} – 0.175 | V | _ |
| AC input high voltage | V _{IHAC} | MV _{REF} + 0.175 | _ | V | _ |

Table 22 provides the input AC timing specifications for the DDR controller when interfacing to DDR2 and DDR3 SDRAM.

Table 22. DDR2 and DDR3 SDRAM Interface Input AC Timing Specifications

At recommended operating conditions with GV_{DD} of 1.8 V \pm 5% for DDR2 or 1.5 V \pm 5% for DDR3

| Parameter | Symbol | Min | Max | Unit | Notes |
|-----------------------------------|---------------------|--------------|-----|------|-------|
| Controller Skew for MDQS—MDQ/MECC | t _{CISKEW} | _ | _ | ps | 1 |
| 667 MHz data rate | | -390 | 390 | | 1 |
| 533 MHz data rate | | -450 | 450 | | 1 |
| 400 MHz data rate | | – 515 | 515 | | 1 |

Table 22. DDR2 and DDR3 SDRAM Interface Input AC Timing Specifications (continued)

At recommended operating conditions with GV $_{DD}$ of 1.8 V $\pm\,5\%$ for DDR2 or 1.5 V $\pm\,5\%$ for DDR3

| Parameter | Symbol | Min | Мах | Unit | Notes |
|----------------------------------|---------------------|------|-----|------|-------|
| Tolerated Skew for MDQS—MDQ/MECC | t _{DISKEW} | _ | _ | ps | 3 |
| 667 MHz data rate | | -360 | 360 | | 3 |
| 533 MHz data rate | | -488 | 488 | | 3 |
| 400 MHz data rate | | -733 | 733 | | 3 |

- 1. t_{CISKEW} represents the total amount of skew consumed by the controller between MDQS[n] and any corresponding bit that will be captured with MDQS[n]. This should be subtracted from the total timing budget.
- DDR3 only
- 3. The amount of skew that can be tolerated from MDQS to a corresponding MDQ signal is called t_{DISKEW} . This can be determined by the following equation: $t_{DISKEW} = \pm (T \div 4 abs(t_{CISKEW}))$ where T is the clock period and $abs(t_{CISKEW})$ is the absolute value of t_{CISKEW} .

Figure 8 shows the DDR2 and DDR3 SDRAM interface input timing diagram.

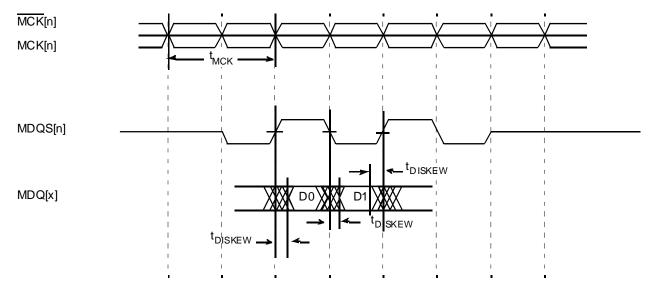


Figure 8. DDR2 and DDR3 SDRAM Interface Input Timing Diagram

2.8.2.2 DDR2 and DDR3 SDRAM Interface Output AC Timing Specifications

Table 23 contains the output AC timing targets for the DDR2 and DDR3 SDRAM interface.

Table 23. DDR2 and DDR3 SDRAM Interface Output AC Timing Specifications

At recommended operating conditions with GV $_{DD}$ of 1.8 V $\pm\,5\%$ for DDR2 or 1.5 V $\pm\,5\%$ for DDR3

| Parameter | Symbol ¹ | Min | Max | Unit | Notes |
|---|---------------------|------|-----|------|-------|
| MCK[n] cycle time | t _{MCK} | 3 | 5 | ns | 2 |
| ADDR/CMD output setup with respect to MCK | t _{DDKHAS} | _ | _ | ns | 3 |
| 667 MHz data rate | | 1.10 | _ | | 3 |
| 533 MHz data rate | | 1.48 | _ | | 3 |
| 400 MHz data rate | | 1.95 | _ | | 3 |
| ADDR/CMD output hold with respect to MCK | t _{DDKHAX} | _ | _ | ns | 3 |
| 667 MHz data rate | | 1.10 | _ | | 3 |
| 533 MHz data rate | | 1.48 | _ | | 3 |
| 400 MHz data rate | | 1.95 | _ | | 3 |
| MCS[n] output setup with respect to MCK | t _{DDKHCS} | _ | _ | ns | 3 |
| 667 MHz data rate | | 1.10 | _ | | 3 |
| 533 MHz data rate | | 1.48 | _ | | 3 |
| 400 MHz data rate | | 1.95 | _ | | 3 |
| MCS[n] output hold with respect to MCK | t _{DDKHCX} | _ | _ | ns | 3 |
| 667 MHz data rate | | 1.10 | _ | | 3 |
| 533 MHz data rate | | 1.48 | _ | | 3 |
| 400 MHz data rate | | 1.95 | _ | | 3 |
| MCK to MDQS Skew | t _{DDKHMH} | _ | _ | ns | 4 |
| ≤ 667 MHz data rate | | -0.6 | 0.6 | | 4 |

Table 23. DDR2 and DDR3 SDRAM Interface Output AC Timing Specifications (continued)

At recommended operating conditions with GV_{DD} of 1.8 V ± 5% for DDR2 or 1.5 V ± 5% for DDR3

| Parameter | Symbol ¹ | Min | Max | Unit | Notes |
|--|--|----------------------|----------------------|------|-------|
| MDQ/MECC/MDM output setup with respect to MDQS | t _{DDKHDS,} t _{DDKLDS} | | _ | ps | 5 |
| 667 MHz data rate | | 300 | _ | | 5 |
| 533 MHz data rate | | 388 | _ | | 5 |
| 400 MHz data rate | | 550 | _ | | 5 |
| MDQ/MECC/MDM output hold with respect to MDQS | t _{DDKHDX} , t _{DDKLDX} | _ | _ | ps | 5 |
| 667 MHz data rate | | 300 | _ | | 5 |
| 533 MHz data rate | | 388 | _ | | 5 |
| 400 MHz data rate | | 550 | _ | | 5 |
| MDQS preamble | t _{DDKHMP} | $0.9 \times t_{MCK}$ | _ | ns | _ |
| MDQS postamble | t _{DDKHME} | $0.4 \times t_{MCK}$ | $0.6 \times t_{MCK}$ | ns | _ |

Note:

- 1. The symbols used for timing specifications follow the pattern of t_(first two letters of functional block)(signal)(state) (reference)(state) for inputs and t_(first two letters of functional block)(reference)(state)(signal)(state) for outputs. Output hold time can be read as DDR timing (DD) from the rising or falling edge of the reference clock (KH or KL) until the output went invalid (AX or DX). For example, t_{DDKHAS} symbolizes DDR timing (DD) for the time t_{MCK} memory clock reference (K) goes from the high (H) state until outputs (A) are setup (S) or output valid time. Also, t_{DDKLDX} symbolizes DDR timing (DD) for the time t_{MCK} memory clock reference (K) goes low (L) until data outputs (D) are invalid (X) or data output hold time.
- 2. All MCK/MCK and MCDQS/MCDQS referenced measurements are made from the crossing of the two signals.
- 3. ADDR/CMD includes all DDR SDRAM output signals except MCK/MCK, MCS, and MDQ/MECC/MDM/MDQS.
- 4. Note that t_{DDKHMH} follows the symbol conventions described in note 1. For example, t_{DDKHMH} describes the DDR timing (DD) from the rising edge of the MCK[n] clock (KH) until the MDQS signal is valid (MH). t_{DDKHMH} can be modified through control of the MDQS override bits (called WR_DATA_DELAY) in the TIMING_CFG_2 register. This is typically set to the same delay as in DDR_SDRAM_CLK_CNTL[CLK_ADJUST]. The timing parameters listed in the table assume that these two parameters have been set to the same adjustment value. See the QorlQ P1021 Integrated Processor Reference Manual for a description and explanation of the timing modifications enabled by use of these bits.
- 5. Determined by maximum possible skew between a data strobe (MDQS) and any corresponding bit of data (MDQ), ECC (MECC), or data mask (MDM). The data strobe should be centered inside of the data eye at the pins of the microprocessor.

NOTE

For the ADDR/CMD setup and hold specifications in Table 23, it is assumed that the clock control register is set to adjust the memory clocks by ½ applied cycle.

Figure 9 shows the DDR2 and DDR3 SDRAM interface output timing for the MCK to MDQS skew measurement (t_{DDKHMH}).

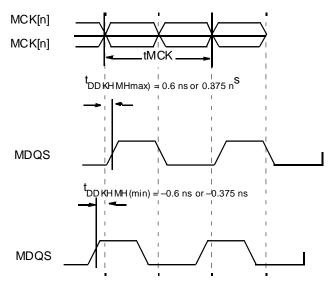


Figure 9. t_{DDKHMH} Timing Diagram

Figure 10 shows the DDR2 and DDR3 SDRAM output timing diagram.

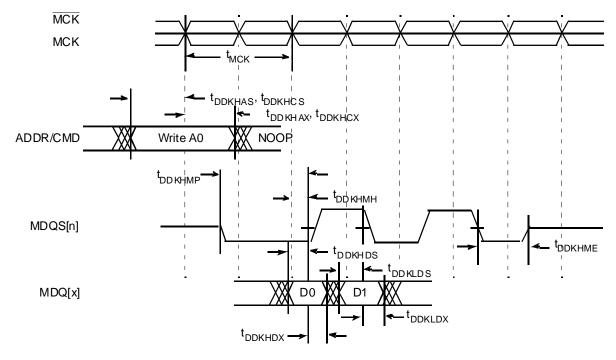


Figure 10. DDR2 and DDR3 Output Timing Diagram

Figure 11 provides the AC test load for the DDR2 and DDR3 controller bus.

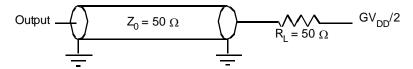


Figure 11. DDR2 and DDR3 Controller Bus AC Test Load

2.8.2.3 DDR2 and DDR3 SDRAM Differential Timing Specifications

This section describes the DC and AC differential timing specifications for the DDR2 and DDR3 SDRAM controller interface. Figure 12 shows the differential timing specification.

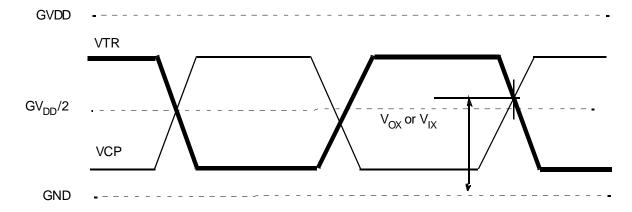


Figure 12. DDR2 and DDR3 SDRAM Differential Timing Specifications

NOTE

VTR specifies the true input signal (such as MCK or MDQS) and VCP is the complementary input signal (such as \overline{MCK} or \overline{MDQS}).

Table 24 provides the DDR2 differential specifications for the differential signals MDQS/MDQS and MCK/MCK.

Table 24. DDR2 SDRAM Differential Electrical Characteristics

| Parameter | Symbol | Min | Max | Unit | Notes |
|---|-------------------|--------------------|----------------------------------|------|-------|
| Input AC Differential Crosspoint Voltage | V _{IXAC} | 0.5 × GVDD – 0.175 | 0.5 × GVDD + 0.175 | V | _ |
| Output AC Differential Crosspoint Voltage | V_{OXAC} | 0.5 × GVDD – 0.125 | $0.5 \times \text{GVDD} + 0.125$ | V | _ |

Table 25 provides the DDR3 differential specifications for the differential signals MDQS/MDQS and MCK/MCK.

Table 25. DDR3 SDRAM Differential Electrical Characteristics

| Parameter | Symbol | Min | Max | Unit | Notes |
|---|-------------------|----------------------------------|--------------------|------|-------|
| Input AC Differential Crosspoint Voltage | V _{IXAC} | $0.5 \times \text{GVDD} - 0.150$ | 0.5 × GVDD + 0.150 | V | _ |
| Output AC Differential Crosspoint Voltage | V _{OXAC} | 0.5 × GVDD – 0.115 | 0.5 × GVDD + 0.115 | V | _ |

2.9 eSPI

This section describes the DC and AC electrical specifications for the SPI interface.

2.9.1 eSPI DC Electrical Characteristics

Table 26 provides the DC electrical characteristics for eSPI interface at $CV_{DD} = 3.3 \text{ V}$.

Table 26. SPI DC Electrical Characteristics (3.3V)

For recommended operating conditions, see Table 3.

| Parameter | Symbol | Min | Max | Unit | Note |
|---|-----------------|-----|-----|------|------|
| Input high voltage | V _{IH} | 2.0 | _ | V | 1 |
| Input low voltage | V _{IL} | _ | 0.8 | V | 1 |
| Input current (0 V \leq V _{IN} \leq CV _{DD}) | I _{IN} | _ | ±10 | μΑ | 2 |
| Output high voltage (I _{OH} = -6.0 mA) | V _{OH} | 2.4 | _ | V | _ |
| Output low voltage (I _{OL} = 6.0mA) | V _{OL} | _ | 0.5 | V | _ |
| Output low voltage (IOL = 3.2mA) | V _{OL} | _ | 0.4 | V | _ |

Note:

- 1. Note that the min V_{IL} and max V_{IH} values are based on the respective min and max CV_{IN} values found in Table 3.
- Note that the symbol V_{IN}, in this case, represents the CV_{IN} symbol referenced in Section 2.1.2, "Recommended Operating Conditions."

Table 27 provides the DC electrical characteristics for the eSPI interface operating at $CV_{DD} = 2.5 \text{ V}$.

Table 27. SPI DC Electrical Characteristics (2.5 V)

| Parameter | Symbol | Min | Max | Unit | Note |
|---|-----------------|-----|-----|------|------|
| High-level input voltage | V _{IH} | 1.7 | _ | V | 1 |
| Low-level input voltage | V_{IL} | _ | 0.7 | V | 1 |
| Input current (V _{IN} = 0 V or V _{IN} = CV _{DD)} | I _{IN} | _ | ±40 | μΑ | 2 |
| High-level output voltage (CV _{DD} = min, I _{OH} = -1 mA) | V _{OH} | 2.0 | _ | V | _ |
| Low-level output voltage (CV _{DD} = min, I _{OL} = 1 mA) | V _{OL} | _ | 0.4 | V | _ |

- 1. The min V_{II} and max V_{IH} values are based on the respective min and max CV_{IN} values found in Table 3.
- 2. The symbol V_{IN}, in this case, represents the CV_{IN} symbol referenced in Section 2.1.2, "Recommended Operating Conditions."

Table 28 provides the DC electrical characteristics for the eSPI interface operating at $CV_{DD} = 1.8 \text{ V}$.

Table 28. SPI DC Electrical Characteristics (1.8 V)

| Parameter | Symbol | Min | Max | Unit | Note |
|--------------------------|-----------------|------|-----|------|------|
| High-level input voltage | V _{IH} | 1.25 | _ | V | 1 |
| Low-level input voltage | V _{IL} | _ | 0.6 | V | 1 |

Table 28. SPI DC Electrical Characteristics (1.8 V) (continued)

| Parameter | Symbol | Min | Max | Unit | Note |
|--|-----------------|------|-----|------|------|
| Input current (V _{IN} = 0 V or V _{IN} = CV _{DD}) | I _{IN} | _ | ±40 | μΑ | 2 |
| High-level output voltage ($CV_{DD} = min, I_{OH} = -0.5 mA$) | V _{OH} | 1.35 | _ | V | _ |
| Low-level output voltage ($CV_{DD} = min$, $I_{OL} = 0.5 mA$) | V_{OL} | _ | 0.4 | V | _ |

Note:

- 1. The min V_{IL} and max V_{IH} values are based on the respective min and max CV_{IN} values found in Table 3.
- 2. The symbol V_{IN}, in this case, represents the CV_{IN} symbol referenced in Section 2.1.2, "Recommended Operating Conditions."

2.9.2 eSPI AC Timing Specifications

Table 29 provides the SPI input and output AC timing specifications.

Table 29. SPI AC Timing Specifications¹

For recommended operating conditions, see Table 3.

| Parameter | Symbol | Min | Max | Unit | Note |
|--|----------------------|-----|-----|------|------|
| SPI outputs—Master data (internal clock) hold time | t _{NIKHOX} | 0.5 | _ | ns | 2 |
| SPI outputs—Master data (internal clock) delay | t _{NIKHOV} | _ | 6.0 | ns | 2 |
| SPI_CS outputs—Master data (internal clock) hold time | t _{NIKHOX2} | 0 | _ | ns | 2 |
| SPI_CS outputs—Master data (internal clock) delay | t _{NIKHOV2} | _ | 6.0 | ns | 2 |
| SPI inputs—Master data (internal clock) input setup time | t _{NIIVKH} | 5 | _ | ns | _ |
| SPI inputs—Master data (internal clock) input hold time | t _{NIIXKH} | 0 | _ | ns | _ |

- 1. The symbols used for timing specifications follow the pattern of t_(first two letters of functional block)(signal)(state) (reference)(state) for inputs and t_(first two letters of functional block)(reference)(state)(signal)(state) for outputs. For example, t_{NIKHOV} symbolizes the NMSI outputs internal timing (NI) for the time t_{SPI} memory clock reference (K) goes from the high state (H) until outputs (O) are valid (V).
- 2. Output specifications are measured from the 50% level of the rising edge of CLKIN to the 50% level of the signal. Timings are measured at the pin.

Figure 13 provides the AC test load for the SPI.

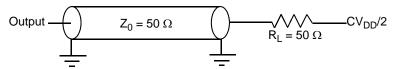


Figure 13. SPI AC Test Load

Figure 14 represents the AC timing from Table 29 in master mode (internal clock). Note that although the specifications are generally refer to the rising edge of the clock, these AC timing diagrams also apply when the falling edge is the active edge. Also, note that the clock edge is selectable on SPI.

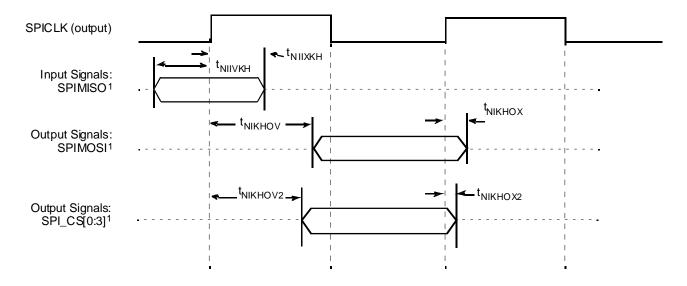


Figure 14. SPI AC Timing in Master Mode (Internal Clock) Diagram

2.10 DUART

This section describes the DC and AC electrical specifications for the DUART interface.

2.10.1 DUART DC Electrical Characteristics

Table 30 provides the DC electrical characteristics for the DUART interface.

Table 30. DUART DC Electrical Characteristics

For recommended operating conditions, see Table 3

| Parameter | Symbol | Min | Max | Unit | Notes |
|--|-----------------|-----|-----|------|-------|
| Input high voltage | V _{IH} | 2 | _ | V | 1 |
| Input low voltage | V _{IL} | _ | 0.8 | V | 1 |
| Input current (OV _{IN} = 0 V or OV _{IN} = OV _{DD}) | I _{IN} | _ | ±40 | μΑ | 2 |
| Output high voltage (OV _{DD} = mn, I _{OH} = -2 mA) | V _{OH} | 2.4 | _ | V | _ |
| Output low voltage (OV _{DD} = min, I _{OL} = 2 mA) | V _{OL} | _ | 0.4 | V | _ |

- 1. Note that the min V_{IL}and max V_{IH} values are based on the respective min and max OV_{IN} values found in Figure 3.
- 2. Note that the symbol OVIN represents the input voltage of the supply. It is referenced in Figure 3.

2.10.2 DUART AC Electrical Specifications

Table 31 provides the AC timing parameters for the DUART interface.

Table 31. DUART AC Timing Specifications

| Parameter | Value | Unit | Notes |
|-------------------|---------------------|------|-------|
| Minimum baud rate | CCB clock/1,048,576 | baud | 1 |
| Maximum baud rate | CCB clock/16 | baud | 2 |
| Oversample rate | 16 | _ | 3 |

Notes:

- 1. CCB clock refers to the platform clock.
- 2. Actual attainable baud rate will be limited by the latency of interrupt processing.
- 3. The middle of a start bit is detected as the 8th sampled 0 after the 1-to-0 transition of the start bit. Subsequent bit values are sampled each 16th sample.

2.11 Ethernet: Enhanced Three-Speed Ethernet (eTSEC) (10/100/1000 Mbps)—MII/RMII/RGMII/SGMII Electrical Characteristics

This section provides the AC and DC electrical characteristics for enhanced three-speed Ethernet 10/100/1000 controller and MII management.

2.11.1 MII Interface Electrical Specifications

This section provides AC and DC electrical characteristics of MII interface for eTSEC.

2.11.1.1 MII and RMII DC Electrical Characteristics

All MII drivers and receivers comply with the DC parametric attributes specified in Table 32.

Table 32. MII amd RMII DC Electrical Characteristics

At recommended operating conditions with $LV_{DD} = 3.3 \text{ V}$

| Parameter | Symbol | Min | Max | Unit | Notes |
|---|-----------------|------|-----|------|-------|
| Input high voltage | V _{IH} | 2.0 | _ | V | 1 |
| Input low voltage | V _{IL} | _ | 0.8 | V | _ |
| Input high current (V _{IN} = LV _{DD}) | I _{IH} | _ | 40 | μА | 2 |
| Input low current (V _{IN} = GND) | I _{IL} | -600 | _ | μΑ | 2 |
| Output high voltage (LV _{DD} = min, I _{OH} = -4.0 mA) | V _{OH} | 2.4 | _ | V | _ |
| Output low voltage (LV _{DD} = min, I _{OL} = 4.0 mA) | V _{OL} | _ | 0.4 | V | _ |

- 1. The min V_{IL}and max V_{IH} values are based on the respective min and max LV_{IN} values found in Table 3.
- 2. The symbol V_{IN} , in this case, represents the LV_{IN} symbols referenced in Table 2 and Table 3.

2.11.1.2 MII AC Timing Specifications

This section describes the MII transmit and receive AC timing specifications.

2.11.1.2.1 MII Transmit AC Timing Specifications

Table 33 provides the MII transmit AC timing specifications.

Table 33. MII Transmit AC Timing Specifications

For recommended operating conditions, see Table 3.

| Parameter | Symbol | Min | Тур | Max | Unit |
|---|-------------------------------------|--------|-----|--------|------|
| TX_CLK clock period 10 Mbps | t _{MTX} | 399.96 | 400 | 400.04 | ns |
| TX_CLK clock period 100 Mbps | t _{MTX} | 39.996 | 40 | 40.004 | ns |
| TX_CLK duty cycle | t _{MTXH} /t _{MTX} | 35 | _ | 65 | % |
| TX_CLK to MII data TXD[3:0], TX_ER, TX_EN delay | t _{MTKHDX} | 1 | 5 | 15 | ns |
| TX_CLK data clock rise (20%–80%) | t _{MTXR} | 1.0 | _ | 4.0 | ns |
| TX_CLK data clock fall (80%–20%) | t _{MTXF} | 1.0 | _ | 4.0 | ns |

Figure 15 shows the MII transmit AC timing diagram.

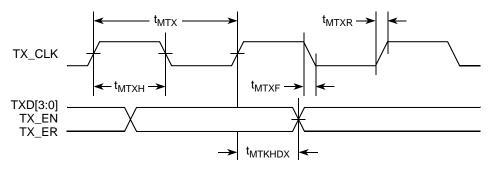


Figure 15. MII Transmit AC Timing Diagram

2.11.1.2.2 MII Receive AC Timing Specifications

Table 34 provides the MII receive AC timing specifications.

Table 34. MII Receive AC Timing Specifications

| Parameter | Symbol | Min | Тур | Max | Unit |
|---|-------------------------------------|--------|-----|--------|------|
| RX_CLK clock period 10 Mbps | t _{MRX} | 399.96 | 400 | 400.04 | ns |
| RX_CLK clock period 100 Mbps | t _{MRX} | 39.996 | 40 | 40.004 | ns |
| RX_CLK duty cycle | t _{MRXH} /t _{MRX} | 35 | _ | 65 | % |
| RXD[3:0], RX_DV, RX_ER setup time to RX_CLK | t _{MRDVKH} | 10.0 | _ | _ | ns |
| RXD[3:0], RX_DV, RX_ER hold time to RX_CLK | t _{MRDXKH} | 10.0 | _ | _ | ns |
| RX_CLK clock rise (20%-80%) | t _{MRXR} | 1.0 | _ | 4.0 | ns |
| RX_CLK clock fall time (80%–20%) | t _{MRXF} | 1.0 | _ | 4.0 | ns |

Note: The frequency of RX_CLK should not exceed the frequency of TX_CLK by more than 300 ppm.

Figure 16 provides the AC test load for eTSEC.

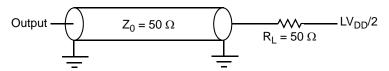


Figure 16. eTSEC AC Test Load

Figure 17 shows the MII receive AC timing diagram.

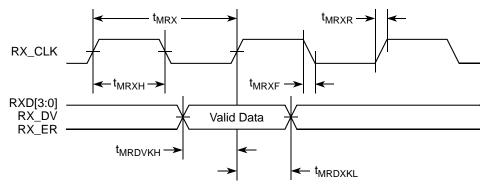


Figure 17. MII Receive AC Timing Diagram

2.11.2 RMII AC Timing Specifications

In RMII mode, the reference clock should be fed to TSEC*n*_TX_CLK. This section describes the RMII transmit and receive AC timing specifications.

Table 35 lists the RMII transmit AC timing specifications.

Table 35. RMII Transmit AC Timing Specifications

For recommended operating conditions, see Table 3.

| Parameter | Symbol | Min | Тур | Max | Unit |
|---|--------------------|-----|------|------|------|
| TSECn_TX_CLK clock period | t _{RMT} | _ | 20.0 | _ | ns |
| TSECn_TX_CLK duty cycle | t _{RMTH} | 35 | _ | 65 | % |
| TSECn_TX_CLK peak-to-peak jitter | t _{RMTJ} | _ | _ | 250 | ps |
| Rise time TSECn_TX_CLK (20%–80%) | t _{RMTR} | 1.0 | _ | 5.0 | ns |
| Fall time TSECn_TX_CLK (80%–20%) | t _{RMTF} | 1.0 | _ | 5.0 | ns |
| TSECn_TX_CLK to RMII data TXD[1:0], TX_EN delay | t _{RMTDX} | 2.0 | _ | 10.0 | ns |

Figure 18 shows the RMII transmit AC timing diagram.

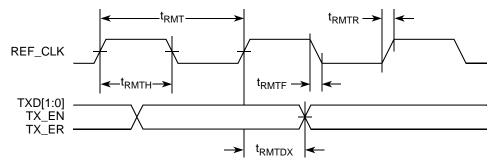


Figure 18. RMII Transmit AC Timing Diagram

Table 36 lists the RMII receive AC timing specifications.

Table 36. RMII Receive AC Timing Specifications

For recommended operating conditions, see Table 3

| Parameter | Symbol | Min | Тур | Max | Unit |
|--|--------------------|-----|------|-----|------|
| TSECn_TX_CLK clock period | t _{RMR} | _ | 20.0 | _ | ns |
| TSECn_TX_CLK duty cycle | t _{RMRH} | 35 | _ | 65 | % |
| TSECn_TX_CLK peak-to-peak jitter | t _{RMRJ} | _ | _ | 250 | ps |
| Rise time TSECn_TX_CLK (20%–80%) | t _{RMRR} | 1.0 | _ | 5.0 | ns |
| Fall time TSECn_TX_CLK (80%–20%) | t _{RMRF} | 1.0 | _ | 5.0 | ns |
| RXD[1:0], CRS_DV, RX_ER setup time to TSECn_TX_CLK rising edge | t _{RMRDV} | 4.0 | _ | _ | ns |
| RXD[1:0], CRS_DV, RX_ER hold time to TSECn_TX_CLK rising edge | t _{RMRDX} | 2.0 | _ | _ | ns |

Figure 19 provides the AC test load for eTSEC.

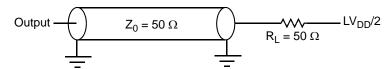


Figure 19. eTSEC AC Test Load

Figure 20 shows the RMII receive AC timing diagram.

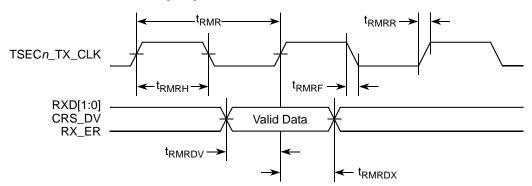


Figure 20. RMII Receive AC Timing Diagram

2.11.3 RGMII Interface Electrical Specifications

This section provides AC and DC electrical characteristics of RGMII interface for eTSEC.

2.11.3.1 RGMII DC Electrical Characteristics

Table 37 shows the RGMII DC electrical characteristics when operating from a 2.5 V supply.

Table 37. RGMII DC Electrical Characteristics (2.5V)

At recommended operating conditions with $LV_{DD} = 2.5 \text{ V}$

| Parameter | Symbol | Min | Max | Unit | Notes |
|---|-----------------|-----------|------------------------|------|-------|
| Input high voltage | V _{IH} | 1.70 | _ | V | _ |
| Input low voltage | V _{IL} | _ | 0.70 | V | _ |
| Input high current (V _{IN} = LV _{DD}) | I _{IH} | _ | 10 | μА | _ |
| Input low current (V _{IN} = GND) | I _{IL} | -15 | _ | μΑ | 1 |
| Output high voltage (LV _{DD} = min, I _{OH} = -1.0 mA) | V _{OH} | 2.00 | LV _{DD} + 0.3 | V | _ |
| Output low voltage (LV _{DD} = min, I _{OL} = 1.0 mA) | V _{OL} | GND - 0.3 | 0.40 | V | _ |

Note:

- 1. Note that the min V_{IL} and max V_{IH} values are based on the respective min and max LV_{IN} values found in Table 3.
- 2. The symbol $\rm V_{IN}$, in this case, represents the $\rm LV_{IN}$ symbols referenced in Table 3.

2.11.3.2 RGMII AC Timing Specifications

Table 38 presents the RGMII and RTBI AC timing specifications.

Table 38. RGMII AC Timing Specifications

For recommended operating conditions, see Table 3.

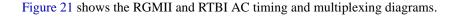
| Parameter | Symbol ¹ | Min | Тур | Max | Unit | Notes |
|--|-------------------------------------|------|-----|-----|------|-------|
| Data to clock output skew (at transmitter) | t _{SKRGT_TX} | -500 | 0 | 500 | ps | 5 |
| Data to clock input skew (at receiver) | t _{SKRGT_RX} | 1.0 | _ | 2.6 | ns | 2 |
| Clock period duration | t _{RGT} | 7.2 | 8.0 | 8.8 | ns | 3 |
| Duty cycle for 10BASE-T and 100BASE-TX | t _{RGTH} /t _{RGT} | 40 | 50 | 60 | % | 3, 4 |

Table 38. RGMII AC Timing Specifications (continued)

For recommended operating conditions, see Table 3.

| Parameter | Symbol ¹ | Min | Тур | Max | Unit | Notes |
|------------------------|-------------------------------------|-----|-----|------|------|-------|
| Duty cycle for Gigabit | t _{RGTH} /t _{RGT} | 45 | 50 | 55 | % | _ |
| Rise time (20%–80%) | t _{RGTR} | _ | _ | 0.75 | ns | _ |
| Fall time (20%–80%) | t _{RGTF} | _ | _ | 0.75 | ns | _ |

- In general, the clock reference symbol representation for this section is based on the symbols RGT to represent RGMII and RTBI timing. For example, the subscript of t_{RGT} represents the TBI (T) receive (RX) clock. Note also that the notation for rise (R) and fall (F) times follows the clock symbol that is being represented. For symbols representing skews, the subscript is skew (SK) followed by the clock that is being skewed (RGT).
- 2. This implies that PC board design will require clocks to be routed such that an additional trace delay of greater than 1.5 ns will be added to the associated clock signal. Many PHY vendors already incorporate the necessary delay inside their chip. If so, additional PCB delay is probably not needed.
- 3. For 10 and 100 Mbps, t_{RGT} scales to 400 ns \pm 40 ns and 40 ns \pm 4 ns, respectively.
- 4. Duty cycle may be stretched/shrunk during speed changes or while transitioning to a received packet's clock domains as long as the minimum duty cycle is not violated and stretching occurs for no more than three t_{RGT} of the lowest speed transitioned between.
- 5) The frequency of RX_CLK should not exceed the frequency of GTX_CLK125 by more than 300 ppm.



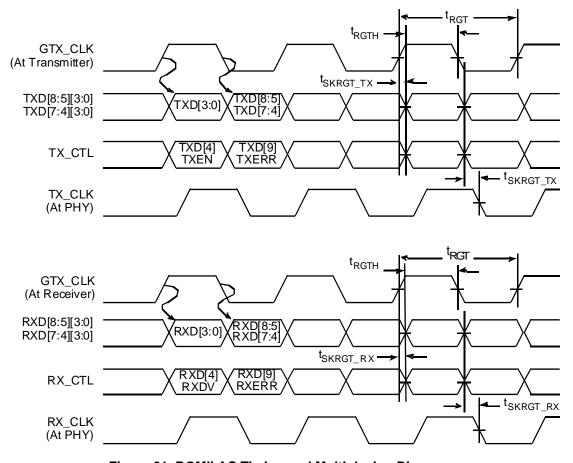


Figure 21. RGMII AC Timing and Multiplexing Diagrams

2.11.4 SGMII Interface Electrical Characteristics

Each SGMII port features a 4-wire AC-Coupled serial link from the dedicated SerDes interface of P1021 as shown in Figure 23, where C_{TX} is the external (on board) AC-Coupled capacitor. Each output pin of the SerDes transmitter differential pair features 50- Ω output impedance. Each input of the SerDes receiver differential pair features 50- Ω on-die termination to SGND_SRDS. The reference circuit of the SerDes transmitter and receiver is shown in Figure 49.

2.11.4.1 SGMII DC Electrical Characteristics

This section discusses the electrical characteristics for the SGMII interface.

2.11.4.1.1 DC Requirements for SGMII SD_REF_CLK and SD_REF_CLK

The characteristics and DC requirements of the separate SerDes reference clock are described in Section 2.18.2.2, "DC Level Requirement for SerDes Reference Clocks."

2.11.4.1.2 SGMII Transmit DC Timing Specifications

Table 39 describe the SGMII SerDes transmitter AC-Coupled DC electrical characteristics. Transmitter DC characteristics are measured at the transmitter outputs $(SDn_TX[n])$ and $\overline{SDn_TX[n]}$ as shown in Figure 23.

Table 39. SGMII DC Transmitter Electrical Characteristics

For recommended operating conditions, see Table 3.

| Parameter | Symbol | Min | Тур | Max | Unit | Notes |
|---|-----------------|---|-----|---|------|-----------------------------|
| Output high voltage | V _{OH} | _ | _ | XV _{DD_SRDS2-Typ} /2+ V _{OD} _{-max} /2 | mV | 1 |
| Output low voltage | V _{OL} | XV _{DD_SRDS2-Typ} /2- V _{OD} _{-max} /2 | _ | _ | mV | 1 |
| | | 304 | 475 | 689 | | Equalization setting: 1.0x |
| | | 279 | 436 | 632 | | Equalization setting: 1.09x |
| | | 254 | 396 | 574 | | Equalization setting: 1.2x |
| | | 229 | 357 | 518 | | Equalization setting: 1.33x |
| Output differential | | 202 | 316 | 459 | | Equalization setting: 1.5x |
| voltage ^{2, 3, 4} (XV _{DD-Typ} at 1.0V) | V _{OD} | 178 | 277 | 402 | mV | Equalization setting: 1.71x |
| (XV _{DD-Typ} at 1.0V) | | 152 | 237 | 344 | | Equalization setting: 2.0x |
| Output impedance (single-ended) | R _O | 40 | 50 | 60 | Ω | _ |

- 1. This will not align to DC-coupled SGMII.
- 2. $|V_{OD}| = |V_{SD2_TXn} V_{\overline{SD2_TXn}}|$. $|V_{OD}|$ is also referred as output differential peak voltage. $V_{TX-DIFFp-p} = 2*|V_{OD}|$.
- 3. The |V_{OD}| value shown in the table assumes the following transmit equalization setting in the XMITEQAB (for SerDes lanes A & B) or XMITEQEF (for SerDes lanes E & E) bit field of the SerDes 2 control register:
 - The MSbit (bit 0) of the above bit field is set to zero (selecting the full V_{DD-DIFF-p-p} amplitude power up default);
 - The LSbits (bit [1:3]) of the above bit field is set based on the equalization setting shown in table.
- 4. The $|V_{OD}|$ value shown in the Typ column is based on the condition of $XV_{DD_SRDS2-Typ}$ =1.0 V, <u>no common mode offset variation</u>, SerDes transmitter is terminated with 100- Ω differential load between SD_TX[n] and SD_TX[n].

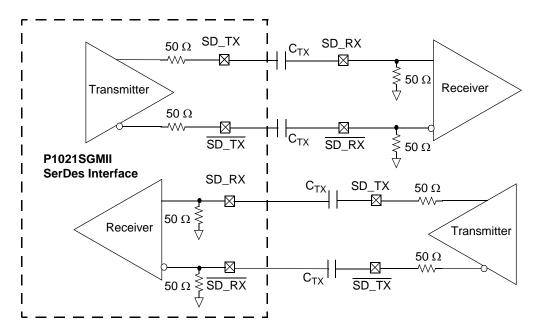


Figure 22. 4-Wire AC-Coupled SGMII Serial Link Connection Example

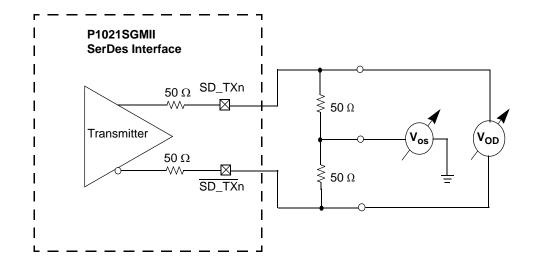


Figure 23. SGMII Transmitter DC Measurement Circuit

2.11.4.1.3 SGMII DC Receiver Timing Specification

Table 40 lists the SGMII DC receiver electrical characteristics. Source synchronous clocking is not supported. Clock is recovered from the data.

Table 40. SGMII DC Receiver Electrical Characteristics⁵

For recommended operating conditions, see Table 3.

| Parameter | | Symbol | Min | Тур | Max | Unit | Notes |
|---------------------------------------|----------|-------------------------|-----|-----|------|------|-------|
| DC Input voltage range | | _ | | N/A | 1 | _ | 1 |
| Input differential voltage | LSTS = 0 | V _{RX_DIFFp-p} | 100 | _ | 1200 | mV | 2, 4 |
| | LSTS = 1 | | 175 | _ | | | |
| Loss of signal threshold | LSTS = 0 | VLOS | 30 | _ | 100 | mV | 3, 4 |
| | LSTS = 1 | | 65 | _ | 175 | | |
| Receiver differential input impedance | | Z _{RX_DIFF} | 80 | _ | 120 | Ω | _ |

Note:

- 1. Input must be externally AC-coupled.
- 2. V_{RX DIFFp-p} is also referred to as peak-to-peak input differential voltage.
- 3. The concept of this parameter is equivalent to the Electrical Idle Detect Threshold parameter in PCI Express. Refer to the PCI Express Differential Receiver (RX) Input Specifications section for further explanation.
- 4. The LSTS shown in the table refers to the LSTSAB or LSTSEF bit field of the SerDes control register.

2.11.4.2 SGMII AC Timing Specifications

This section describes the AC timing specifications for the SGMII interface.

2.11.4.2.1 AC Requirements for SGMII SD_REF_CLK and SD_REF_CLK

Note that the SGMII clock requirements for SD_REF_CLK and SD_REF_CLK are intended to be used within the clocking guidelines specified by Section 2.18.2.3, "AC Requirements for SerDes Reference Clocks."

2.11.4.2.2 SGMII Transmit AC Timing Specifications

Table 41 provides the SGMII transmit AC timing specifications. A source synchronous clock is not supported. The AC timing specifications do not include RefClk jitter.

Table 41. SGMII Transmit AC Timing Specifications

At recommended operating conditions with XV_{DD} SRDS = 1.0 V ± 50 mV

| Parameter | Symbol | Min | Тур | Max | Unit | Notes |
|-----------------------|-----------------|--------|-----|--------|--------|-------|
| Deterministic Jitter | JD | _ | _ | 0.17 | UI p-p | _ |
| Total Jitter | JT | _ | _ | 0.35 | UI p-p | _ |
| Unit Interval | UI | 799.92 | 800 | 800.08 | ps | _ |
| AC coupling capacitor | C _{TX} | 5 | 100 | 200 | nF | 3 |

- 1. Each UI is 800 ps ± 100 ppm.
- 2. See Figure 25 for single frequency sinusoidal jitter limits.
- 3. The external AC coupling capacitor is required. It is recommended that it be placed near the device transmitter outputs.

2.11.4.2.3 SGMII AC Measurement details

Transmitter and receiver AC characteristics are measured at the transmitter outputs (SD_TX[n] and $\overline{SD_TX}[n]$) or at the receiver inputs (SD_RX[n] and $\overline{SD_RX}[n]$) as depicted in Figure 24, respectively.

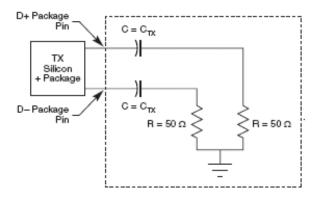


Figure 24. SGMII AC Test/Measurement Load

2.11.4.2.4 SGMII Receiver AC Timing Specifications

Table 42 provides the SGMII receive AC timing specifications. The AC timing specifications do not include RefClk jitter. Source synchronous clocking is not supported. Clock is recovered from the data.

Table 42. SGMII Receive AC Timing Specifications

At recommended operating conditions with $XV_{DD\ SRDS2} = 1.0V \pm 50mV$

| Parameter | Symbol | Min | Тур | Max | Unit | Notes |
|--|--------|--------|-----|-------------------|--------|-------|
| Deterministic Jitter Tolerance | JD | 0.37 | _ | _ | UI p-p | 1, 2 |
| Combined Deterministic and Random Jitter Tolerance | JDR | 0.55 | _ | _ | UI p-p | 1, 2 |
| Total Jitter Tolerance | JT | 0.65 | _ | _ | UI p-p | 1, 2 |
| Bit Error Ratio | BER | _ | _ | 10 ⁻¹² | | _ |
| Unit Interval | UI | 799.92 | 800 | 800.08 | ps | 3 |

- 1. Measured at receiver
- 2. Refer to RapidIOTM 1×/4× LP Serial Physical Layer Specification for interpretation of jitter specifications.
- 3. Each UI is 800 ps ± 100 ppm.

The sinusoidal jitter in the total jitter tolerance may have any amplitude and frequency in the unshaded region of Figure 25.

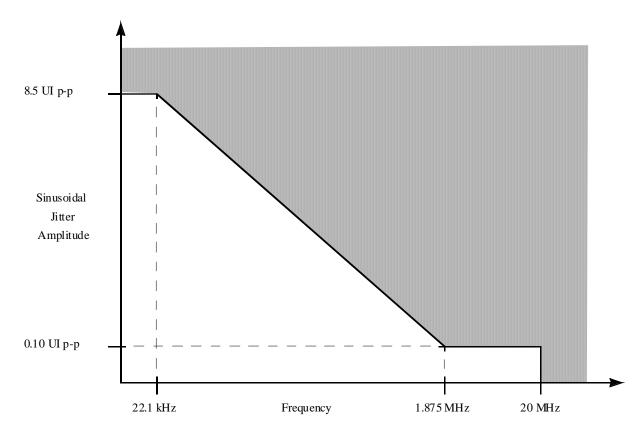


Figure 25. Single Frequency Sinusoidal Jitter Limits

2.11.5 MII Management

2.11.5.1 MII Management DC Electrical Characteristics

The MDC and MDIO are defined to operate at a supply voltage of 3.3 V and 2.5 V. The DC electrical characteristics for MDIO and MDC are provided in Table 43 and Table 44.

Table 43. MII Management DC Electrical Characteristics

At recommended operating conditions with $LV_{DD} = 3.3 \text{ V}$

| Parameter | Symbol | Min | Max | Unit | Notes |
|---|-----------------|------|------------------------|------|-------|
| Input high voltage | V _{IH} | 2.0 | _ | V | _ |
| Input low voltage | V _{IL} | _ | 0.90 | V | _ |
| Input high current (LV _{DD} = Max, V _{IN} = 2.1 V) | I _{IH} | _ | 40 | μА | 1 |
| Input low current (LV _{DD} = Max, V _{IN} = 0.5 V) | I _{IL} | -600 | _ | μА | 1 |
| Output high voltage (LV _{DD} = Min, I _{OH} = -1.0 mA) | V _{OH} | 2.4 | LV _{DD} + 0.3 | V | _ |

Table 43. MII Management DC Electrical Characteristics (continued)

At recommended operating conditions with LV_{DD} = 3.3 V

| Parameter | Symbol | Min | Max | Unit | Notes |
|---|-----------------|-----|-----|------|-------|
| Output low voltage (LV _{DD} = Min, I _{OL} = 1.0 mA) | V _{OL} | GND | 0.4 | V | _ |

Note:

1. Note that the symbol V_{IN} , in this case, represents the LV $_{\text{IN}}$ symbol referenced in Table 2 and Table 3.

Table 44. MII Management DC Electrical Characteristics

At recommended operating conditions with $LV_{DD} = 2.5 \text{ V}$

| Parameter | Symbol | Min | Max | Unit | Notes |
|--|-----------------|-----------|------------------------|------|-------|
| Input high voltage | V _{IH} | 1.70 | LV _{DD} + 0.3 | V | _ |
| Input low voltage | V _{IL} | -0.3 | 0.70 | V | _ |
| Input high current (V _{IN} = LV _{DD} ,) | I _{IH} | _ | 10 | μΑ | 1, 2 |
| Input low current (V _{IN} = GND) | I _{IL} | -15 | _ | μА | _ |
| Output high voltage (LV _{DD} = Min, IOH = -1.0 mA) | V _{OH} | 2.00 | LV _{DD} + 0.3 | V | _ |
| Output low voltage (LV _{DD} = Min, I _{OL} = 1.0 mA) | V _{OL} | GND - 0.3 | 0.40 | V | _ |

Notes:

- 1. EC1_MDC and EC1_MDIO operate on LV_{DD}.
- 2. Note that the symbol V_{IN} , in this case, represents the LV_{IN} and TV_{IN} symbols referenced in Table 3.

2.11.5.1.1 MII Management AC Electrical Specifications

Table 45 provides the MII management AC timing specifications.

Table 45. MII Management AC Timing Specifications

| Parameter | Symbol | Min | Тур | Max | Unit | Notes |
|----------------------------|---------------------|--------------------------------|-----|-------------------------|------|-------|
| MDC frequency | f _{MDC} | _ | 2.5 | _ | MHz | 2 |
| MDC period | t _{MDC} | _ | 400 | _ | ns | _ |
| MDC clock pulse width high | t _{MDCH} | 32 | _ | _ | ns | _ |
| MDC to MDIO delay | t _{MDKHDX} | (16*t _{plb_clk}) - 3 | _ | $(16*t_{plb_clk}) + 3$ | ns | 3, 4 |
| MDIO to MDC setup time | t _{MDDVKH} | 5 | _ | _ | ns | _ |

Table 45. MII Management AC Timing Specifications (continued)

| Parameter | Symbol | Min | Тур | Max | Unit | Notes |
|-----------------------|---------------------|-----|-----|-----|------|-------|
| MDIO to MDC hold time | t _{MDDXKH} | 0 | 1 | 1 | ns | _ |

Notes:

- 1. The symbols used for timing specifications follow the pattern of t_{(first two letters of functional block)(signal)(state)(reference)(state)} for inputs and t_(first two letters of functional block)(reference)(state)(signal)(state)</sub> for outputs. For example, t_{MDKHDX} symbolizes management data timing (MD) for the time t_{MDC} from clock reference (K) high (H) until data outputs (D) are invalid (X) or data hold time. Also, t_{MDDVKH} symbolizes management data timing (MD) with respect to the time data input signals (D) reach the valid state (V) relative to the t_{MDC} clock reference (K) going to the high (H) state or setup time. For rise and fall times, the latter convention is used with the appropriate letter: R (rise) or F (fall).
- This parameter is dependent on the platform clock frequency (MIIMCFG [MgmtClk] field determines the clock frequency of the MgmtClk Clock EC_MDC).
- 3. This parameter is dependent on the platform clock frequency. The delay is equal to 16 platform clock periods ± 3 ns. For example, with a platform clock of 333 MHz, the min/max delay is 48 ns ± 3 ns. Similarly, if the platform clock is 400 MHz, the min/max delay is 40 ns ± 3 ns.
- 4. t_{plb clk} is the platform (CCB) clock.

Figure 26 shows the MII management interface timing diagram.

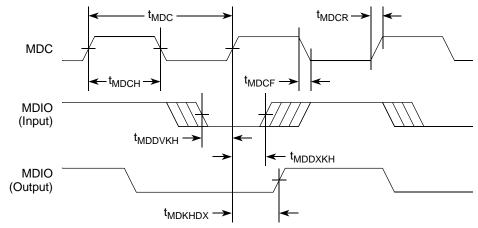


Figure 26. MII Management Interface Timing Diagram

2.11.6 eTSEC IEEE 1588 AC Specifications

Table 46 provides the IEEE 1588 AC timing specifications.

Table 46. eTSEC IEEE 1588 AC Timing Specifications

For recommended operating conditions, see Table 3.

| Parameter | Symbol | Min | Тур | Max | Unit | Note |
|------------------------------------|--|-----|-----|-------------------------|------|------|
| TSEC_1588_CLK clock period | t _{T1588CLK} | 3.8 | _ | T _{RX_CLK} × 7 | ns | 1, 3 |
| TSEC_1588_CLK duty cycle | t _{T1588CLKH} /t _{T1588CLK} | 40 | 50 | 60 | % | _ |
| TSEC_1588_CLK peak-to-peak jitter | t _{T1588CLKINJ} | _ | _ | 250 | ps | _ |
| Rise time eTSEC_1588_CLK (20%-80%) | t _{T1588} CLKINR | 1.0 | _ | 2.0 | ns | _ |

Table 46. eTSEC IEEE 1588 AC Timing Specifications (continued)

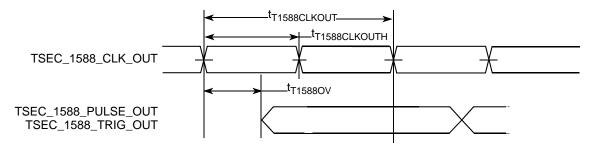
For recommended operating conditions, see Table 3.

| Parameter | Symbol | Min | Тур | Max | Unit | Note |
|------------------------------------|---|-------------------------------|-----|-----|------|------|
| Fall time eTSEC_1588_CLK (80%–20%) | t _{T1588} CLKINF | 1.0 | _ | 2.0 | ns | _ |
| TSEC_1588_CLK_OUT clock period | t _{T1588CLKOUT} | 2 × t _{T1588CLK} | _ | _ | ns | _ |
| TSEC_1588_CLK_OUT duty cycle | t _{T1588} CLKOTH /t _{T1588} CLKOUT | 30 | 50 | 70 | % | _ |
| TSEC_1588_PULSE_OUT | t _{T1588OV} | 0.5 | _ | 3.0 | ns | _ |
| TSEC_1588_TRIG_IN pulse width | t _{T1588} TRIGH | 2 × t _{T1588CLK_MAX} | _ | _ | ns | 2 |

Note:

- 1.T_{RX_CLK} is the max clock period of eTSEC receiving clock selected by TMR_CTRL[CKSEL]. See the *QorIQ P1021 Integrated Processor Reference Manual* for a description of TMR_CTRL registers.
- 2. It needs to be at least two times the clock period of the clock selected by TMR_CTRL[CKSEL]. See the *QorlQ P1021 Integrated Processor Reference Manual* for a description of TMR_CTRL registers.
- 3. The maximum value of t_{T1588CLK} is not only defined by the value of T_{RX_CLK}, but also defined by the recovered clock. For example, for 10/100/1000 Mbps modes, the maximum value of t_{T1588CLK} will be 2800, 280, and 56 ns respectively.

Figure 27 shows the data and command output AC timing diagram..



Note: The output delay is counted starting at the rising edge if t_{T1588CLKOUT} is noninverting. Otherwise, it is counted starting at the falling edge.

Figure 27. eTSEC IEEE 1588 Output AC Timing

Figure 28 shows the data and command input AC timing diagram.

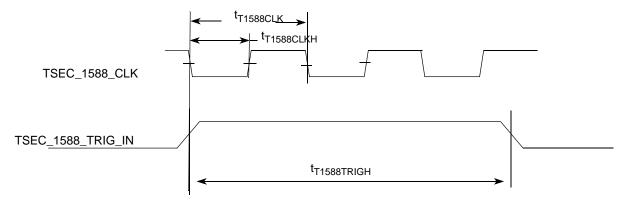


Figure 28. eTSEC IEEE 1588 Input AC Timing

2.12 USB

This section provides the AC and DC electrical specifications for the USB interface of the P1021.

2.12.1 USB DC Electrical Characteristics

Table 47, Table 48, and Table 49 provides the DC electrical characteristics for the USB interface.

Table 47. USB DC Electrical Characteristics (CV_{DD} = 3.3 V)

For recommended operating conditions, see Table 3.

| Parameter | Symbol | Min | Мах | Unit | Notes |
|---|-----------------|-----|-----|------|-------|
| Input high voltage | V _{IH} | 2 | _ | V | 1 |
| Input low voltage | V_{IL} | _ | 0.8 | V | 1 |
| Input current (CV _{IN} = 0V or CV _{IN} = CV _{DD}) | I _{IN} | _ | ±40 | μΑ | 2 |
| Output High voltage ($CV_{DD} = min$, $I_{OH} = -2 mA$) | V _{OH} | 2.8 | _ | V | _ |
| Output Low voltage (CV _{DD} = min, I _{OL} = 2 mA) | V _{OL} | _ | 0.3 | V | _ |

Note:

- 1. Note that the min V_{IL} and max V_{IH} values are based on the respective min and max CV_{IN} values found in Table 3.
- Note that the symbol CV_{IN} represents the input voltage of the supply. It is referenced in Table 3.

Table 48. USB DC Electrical Characteristics ($CV_{DD} = 2.5 \text{ V}$)

| Parameter | Symbol | Min | Max | Unit | Notes |
|--|-----------------|-----|-----|------|-------|
| High-level input voltage ¹ | V _{IH} | 1.7 | _ | V | 1 |
| Low-level input voltage | V _{IL} | _ | 0.7 | V | 1 |
| Input current (V _{IN} = 0 V or V _{IN} = CV _{DD}) | I _{IN} | _ | ±40 | μΑ | 2 |
| High-level output voltage (CV _{DD} = min, I _{OH} = -1 mA) | V _{OH} | 2.0 | _ | V | 3 |
| Low-level output voltage (CV _{DD} = min, I _{OL} = 1mA) | V _{OL} | _ | 0.4 | V | _ |

- 1. The min V_{IL} and max V_{IH} values are based on the respective min and max CV_{IN} values found in Table 3.
- 2. The symbol V_{IN} , in this case, represents the CV_{IN} symbol referenced in Section 2.1.2, "Recommended Operating Conditions."
- 3. Not applicable for open drain signals.

Table 49. USB DC Electrical Characteristics ($CV_{DD} = 1.8V$)

| Parameter | Symbol | Min | Max | Unit | Notes |
|--|-----------------|------|-----|------|-------|
| High-level input voltage ¹ | V _{IH} | 1.25 | _ | V | 1 |
| Low-level input voltage | V_{IL} | _ | 0.6 | V | 1 |
| Input current (V _{IN} = 0 V or V _{IN} = CV _{DD}) | I _{IN} | _ | ±40 | μΑ | 2 |
| High-level output voltage ($CV_{DD} = min, I_{OH} = -0.5 mA$) | V _{OH} | 1.35 | _ | V | 3 |
| Low-level output voltage (CV _{DD} = min, I _{OL} = 0.5 mA) | V _{OL} | _ | 0.4 | ٧ | _ |

Notes:

- 1. The min V_{IL}and max V_{IH} values are based on the respective min and max CV_{IN} values found in Table 3.
- The symbol V_{IN}, in this case, represents the CV_{IN} symbol referenced in Section 2.1.2, "Recommended Operating Conditions."
- 3. Not applicable for open drain signals.

2.12.2 USB AC Electrical Specifications

Table 50 describes the general timing parameters of the USB interface.

Table 50. USB General Timing Parameters

For recommended operating conditions, see Table 3

| Parameter | Symbol | Min | Max | Unit | Notes |
|--|---------------------|-----|-----|------|------------|
| USB clock cycle time | tusck | 15 | _ | ns | 2, 3, 4, 5 |
| Input setup to USB clock—all inputs | t _{USIVKH} | 4 | _ | ns | 2, 3, 4, 5 |
| input hold to USB clock—all inputs | t _{USIXKH} | 1 | _ | ns | 2, 3, 4, 5 |
| USB clock to output valid— all outputs | tuskhov | _ | 7 | ns | 2, 3, 4, 5 |
| Output hold from USB clock—all outputs | tuskhox | 2 | _ | ns | 2, 3, 4, 5 |

- 1. The symbols for timing specifications follow the pattern of t_(First two letters of functional block)(signal)(state) (reference)(state) for inputs and t_(First two letters of functional block)(reference)(state)(signal)(state) for outputs. For example, t_{USIXKH} symbolizes USB timing (US) for the input (I) to go invalid (X) with respect to the time the USB clock reference (K) goes high (H). Also, t_{USKHOX} symbolizes USB timing (US) for the USB clock reference (K) to go high (H) with respect to the output (O) going invalid (X) or output hold time.
- 2. All timings are in reference to USB clock.
- 3. All signals are measured from $CV_{DD}/2$ of the rising edge of the USB clock to $0.4 \times CV_{DD}$ of the signal in question for 3.3 V signaling levels.
- 4. Input timings are measured at the pin.
- 5. For active/float timing measurements, the high impedance or off state is defined to be when the total current delivered through the component pin is less than or equal to that of the leakage current specification.
- 6. When switching the data pins from outputs to inputs using the USBn_DIR pin, the output timings will be violated on that cycle because the output buffers are tristated asynchronously. This should not be a problem, because the PHY should not be functionally looking at these signals on that cycle as per ULPI specifications.

Figure 29 and Figure 30 provide the AC test load and signals for the USB, respectively.

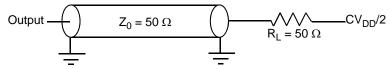


Figure 29. USB AC Test Load

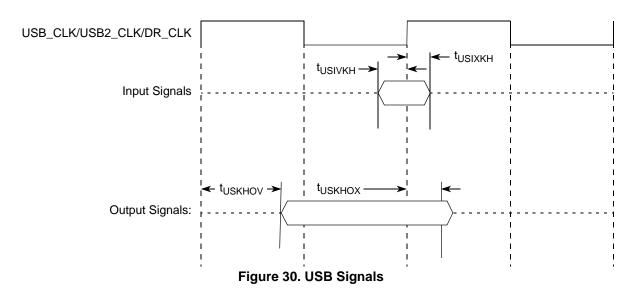


Table 51 provides the USB clock input (USB_CLK_IN) AC timing specifications.

Table 51. USB_CLK_IN AC Timing Specifications

| Parameter | Conditions | Symbol | Min | Тур | Max | Unit |
|--|---|-------------------------|-------|-----|-------|------|
| Frequency range | Steady state | f _{USB_CLK_IN} | 59.97 | 60 | 60.03 | MHz |
| Clock frequency tolerance | _ | t _{CLK_TOL} | -0.05 | 0 | 0.05 | % |
| Reference clock duty cycle | Measured at 1.6 V | t _{CLK_DUTY} | 40 | 50 | 60 | % |
| Total input jitter/time interval error | Peak-to-peak value measured with a second order high-pass filter of 500 kHz bandwidth | t _{CLK_PJ} | _ | _ | 200 | ps |

2.13 Enhanced Local Bus

This section describes the DC and AC electrical specifications for the enhanced local bus interface.

2.13.1 Enhanced Local Bus DC Electrical Characteristics

Table 52 provides the DC electrical characteristics for the enhanced local bus interface operating at $BV_{DD} = 3.3 \text{ V DC}$.

Table 52. Enhanced Local Bus DC Electrical Characteristics (3.3 V DC)

For recommended operating conditions, see Table 3.

| Parameter | Symbol | Min | Max | Unit |
|--|-----------------|-----|-----|------|
| Input high voltage | V _{IH} | 2 | _ | V |
| Input low voltage | V _{IL} | _ | 0.8 | V |
| Input current (V _{IN} = 0 V or V _{IN} = BV _{DD}) | I _{IN} | _ | ±40 | μΑ |
| Output high voltage (BV _{DD} = min, I _{OH} = -2 mA) | V _{OH} | 2.4 | _ | V |
| Output low voltage (BV _{DD} = min, I _{OL} = 2 mA) | V _{OL} | _ | 0.4 | V |

Note:

- 1. The min V_{IL} and max V_{IH} values are based on the respective min and max BV_{IN} values found in Table 3.
- 2. The symbol V_{IN}, in this case, represents the BV_{IN} symbol referenced in Section 2.1.2, "Recommended Operating Conditions."

Table 53 provides the DC electrical characteristics for the enhanced local bus interface when operating at $BV_{DD} = 2.5 \text{ V DC}$.

Table 53. Enhanced Local Bus DC Electrical Characteristics (2.5 V DC)

For recommended operating conditions, see Table 3

| Parameter | Symbol | Min | Max | Unit |
|--|-----------------|-----|-----|------|
| Input high voltage | V _{IH} | 1.7 | _ | V |
| Input low voltage | V _{IL} | _ | 0.7 | V |
| Input current (V _{IN} = 0 V or V _{IN} = BV _{DD}) | I _{IN} | _ | ±40 | μΑ |
| Output high voltage (BV _{DD} = min, I _{OH} = -1 mA) | V _{OH} | 2.0 | _ | V |
| Output low voltage (BV _{DD} = min, I _{OL} = 1 mA) | V _{OL} | _ | 0.4 | V |

Note

- 1. The min V_{IL}and max V_{IH} values are based on the respective min and max BV_{IN} values found in Table 3.
- 2. The symbol V_{IN} , in this case, represents the BV_{IN} symbol referenced in Section 2.1.2, "Recommended Operating Conditions."

Table 54 provides the DC electrical characteristics for the enhanced local bus interface when operating at $BV_{DD} = 1.8 \text{ V DC}$.

Table 54. Enhanced Local Bus DC Electrical Characteristics (1.8 V DC)

For recommended operating conditions, see Table 3.

| Parameter | Symbol | Min | Max | Unit |
|--|-----------------|------|-----|------|
| Input high voltage | V _{IH} | 1.25 | _ | V |
| Input low voltage | V _{IL} | _ | 0.6 | V |
| Input current (V _{IN} = 0 V or V _{IN} = BV _{DD}) | I _{IN} | _ | ±40 | μΑ |
| Output high voltage (BVDD = min, IOH = -0.5 mA) | V _{OH} | 1.35 | _ | V |
| Output low voltage (BVDD = min, IOL = 0.5 mA) | V _{OL} | _ | 0.4 | V |

Note:

- 1. The min V_{IL}and max V_{IH} values are based on the respective min and max BV_{IN} values found in Table 3.
- 2. The symbol VIN, in this case, represents the BVIN symbol referenced in Section 2.1.2, "Recommended Operating Conditions."

2.13.2 Enhanced Local Bus AC Electrical Specifications

2.13.2.1 Test Condition

Figure 31 provides the AC test load for the enhanced local bus.

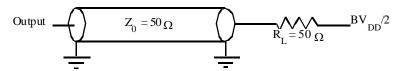


Figure 31. Enhanced Local Bus AC Test Load

2.13.2.2 Local Bus AC Timing Specifications for PLL Bypass Mode

All output signal timings are relative to the falling edge of any LCLKs for PLL bypass mode. The external circuit must use the rising edge of the LCLKs to latch the data.

All input timings except LGTA/LUPWAIT/LFRB are relative to the rising edge of LCLKs. LGTA/LUPWAIT/LFRB are relative to the falling edge of LCLKs.

Table 55 describes the timing specifications of the local bus interface for PLL bypass mode.

Table 55. Enhanced Local Bus Timing Specifications (BV_{DD} = 3.3 V)—PLL Bypass Mode

For recommended operating conditions, see Table 3.

| Parameter | Symbol ¹ | Min | Max | Unit | Notes |
|---|-------------------------------------|--|-----|--------------------------------|-------|
| Local bus cycle time | t _{LBK} | 12 | | ns | _ |
| Local bus duty cycle | t _{LBKH} /t _{LBK} | 45 | 55 | % | _ |
| LCLK[n] skew to LCLK[m] or LSYNC_OUT | t _{LBKSKEW} | _ | 150 | ps | 2 |
| Input setup (except LGTA/LUPWAIT/LFRB) | t _{LBIVKH} | 6 | _ | ns | _ |
| Input hold (except LGTA/LUPWAIT/LFRB) | t _{LBIXKH} | 1 | _ | ns | _ |
| Input setup (for LGTA/LUPWAIT/LFRB) | t _{LBIVKL} | 6 | _ | ns | _ |
| Input hold (for LGTA/LUPWAIT/LFRB) | t _{LBIXKL} | 1 | _ | ns | _ |
| Output delay (Except LALE) | t _{LBKLOV} | _ | 1.5 | ns | _ |
| Output hold (Except LALE) | t _{LBKLOX} | -3.5 | _ | ns | 5 |
| Local bus clock to output high impedance for LAD/LDP | t _{LBKLOZ} | _ | 2 | ns | 3 |
| LALE output negation to LAD/LDP output transition (LATCH hold time) | t _{LBONOT} | 1/2 (LBCR[AHD]=1) 1 (LBCR[AHD]=0) | _ | eLBC controller clock cycle | 4 |

Note:

- 1. All signals are measured from BV_{DD}/2 of rising/falling edge of LCLK to BV_{DD}/2 of the signal in question.
- 2. Skew measured between different LCLK signals at BV_{DD}/2.
- 3. For purposes of active/float timing measurements, the high impedance or off state is defined to be when the total current delivered through the component pin is less than or equal to the leakage current specification.
- 4. t_{LBONOT} is a measurement of the minimum time between the negation of LALE and any change in LAD. t_{LBONOT} is determined by LBCR[AHD]. The unit is the eLBC controller clock cycle, which is the internal clock that runs the local bus controller, not the external LCLK. LCLK cycle = eLBC controller clock cycle × LCRR[CLKDIV]. After power on reset, LBCR[AHD] defaults to 0 and eLBC runs at maximum hold time.
- 5. Output hold is negative. This means that output transition happens earlier than the falling edge of LCLK.

Figure 32 shows the AC timing diagram for PLL bypass mode.

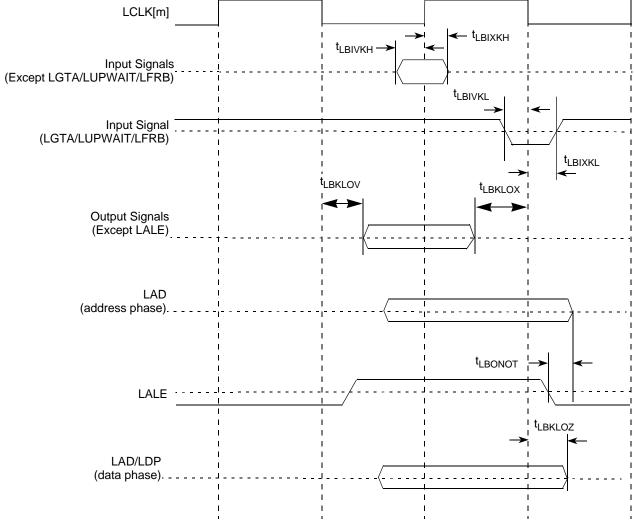


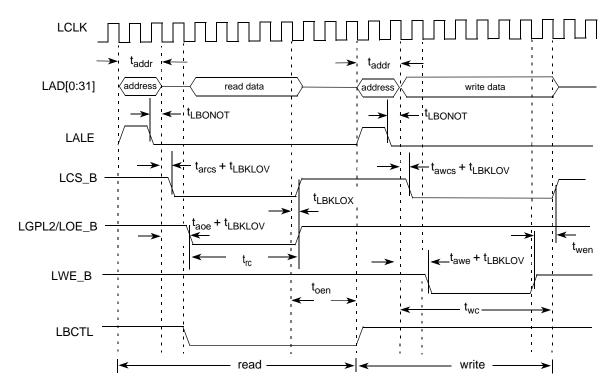
Figure 32. Enhanced Local Bus Signals (PLL Bypass Mode)

Figure 32 applies to all three controllers that eLBC supports: GPCM, UPM, and FCM.

For input signals, the AC timing data is used directly for all three controllers.

For output signals, each type of controller provides its own unique method to control the signal timing. The final signal delay value for output signals is the programmed delay plus the AC timing delay. For example, for GPCM, LCS can be programmed to delay by t_{acs} (0, ½, ½, 1, 1 + ½, 1 + ½, 2, 3 cycles), so the final delay is t_{acs} + t_{LBKLOV} .

Figure 33 shows how the AC timing diagram applies to GPCM in PLL bypass mode. The same principle applies to UPM and FCM.



 $^{^{1}}$ t_{addr} is programmable and determined by LCRR[EADC] and ORx[EAD].

Figure 33. GPCM Output Timing Diagram (PLL Bypass Mode)

2.14 Enhanced Secure Digital Host Controller (eSDHC)

This section describes the DC and AC electrical specifications for the eSDHC interface.

2.14.1 eSDHC DC Electrical Characteristics

Table 56 provides the DC electrical characteristics for the eSDHC interface.

Table 56. eSDHC Interface DC Electrical Characteristics

At recommended operating conditions with $CV_{DD} = 3.3 \text{ V}$

| Parameter | Symbol | Condition | Min | Max | Unit | Notes |
|---------------------|-----------------|---|--------------------------------------|--------------------------------------|------|-------|
| Input high voltage | V _{IH} | _ | $0.625 \times \text{CV}_{\text{DD}}$ | _ | V | 1 |
| Input low voltage | V _{IL} | _ | _ | $0.25 \times \text{CV}_{\text{DD}}$ | V | 1 |
| Output high voltage | V _{OH} | I _{OH} = -100 uA at CV _{DD} min | $0.75 \times \text{CV}_{\text{DD}}$ | _ | V | _ |
| Output low voltage | V _{OL} | I _{OL} = 100uA at CV _{DD} min | _ | $0.125 \times \text{CV}_{\text{DD}}$ | V | _ |
| Output high voltage | V _{OH} | I _{OH} = -100 uA | CV _{DD} – 2 | _ | V | 2 |
| Output low voltage | V _{OL} | I _{OL} = 2 mA | _ | 0.3 | V | 2 |

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 $^{^{2}}$ t_{arcs} , t_{awcs} , t_{aoe} , t_{rc} , t_{oen} , t_{awe} , t_{wc} , t_{wen} are determined by ORx. See the P1021 reference manual.

Table 56. eSDHC Interface DC Electrical Characteristics (continued)

At recommended operating conditions with $CV_{DD} = 3.3 \text{ V}$

| Parameter | Symbol | Condition | Min | Max | Unit | Notes |
|------------------------------|----------------------------------|-----------|-----|-----|------|-------|
| Input/output leakage current | I _{IN} /I _{OZ} | _ | -10 | 10 | uA | _ |

Note:

- 1. Note that the min V_{IL} and max V_{IH} values are based on the respective min and max CV_{IN} values found in Figure 3.
- 2. Open drain mode for MMC cards only.

2.14.2 eSDHC AC Timing Specifications

Table 57 provides the eSDHC AC timing specifications as defined in Figure 35.

Table 57. eSDHC AC Timing Specifications

At recommended operating conditions with CV_{DD} = 3.3 V

| Parameter | Symbol | Min | Max | Unit | Notes |
|---|---|------|----------------|------|-------|
| SD_CLK clock frequency: SD/SDIO Full-speed/High-speed mode MMC Full-speed/High-speed mode | f _{SFSCK} | 0 | 25/50 20/52 | MHz | 2, 4 |
| SD_CLK clock low time—Full-speed/High-speed mode | t _{SFSCKL} | 10/7 | _ | ns | 4 |
| SD_CLK clock high time—Full-speed/High-speed mode | t _{SFSCKH} | 10/7 | _ | ns | 4 |
| SD_CLK clock rise and fall times | t _{SFSCKR/} t _{SFSCKF} | _ | 3 | ns | 4 |
| Input setup times: SD_CMD, SD_DATx, SD_CD to SD_CLK | t _{SFSIVKH} | 5.0 | _ | ns | 4 |
| Input hold times: SD_CMD, SD_DATx, SD_CD to SD_CLK | t _{SFSIXKH} | 2.5 | _ | ns | 3, 4 |
| Output delay time: SD_CLK to SD_CMD, SD_DATx valid | t _{SHSKHOV} | -3 | 3 | ns | 4 |

Note:

- 1. The symbols used for timing specifications herein follow the pattern of t_{(first three letters of functional block)(signal)(state)} (reference)(state) for inputs and t_(first three letters of functional block)(reference)(state)(signal)(state) for outputs. For example, t_{FHSKHOV} symbolizes eSDHC high speed mode device timing (SHS) clock reference (K) going to the high (H) state, with respect to the output (O) reaching the invalid state (X) or output hold time. Note that, in general, the clock reference symbol representation is based on five letters representing the clock of a particular functional. For rise and fall times, the latter convention is used with the appropriate letter: R (rise) or F (fall).
- 2. In full speed mode, clock frequency value can be 0–25 MHz for a SD/SDIO card and 0–20 MHz for a MMC card. In high speed mode, clock frequency value can be 0–50 MHz for a SD/SDIO card and 0–52 MHz for a MMC card.
- 3. To satisfy hold timing, the delay difference between clock input and cmd/data input must not exceed 2 ns.
- 4. $C_{CARD} \le$ 10 pF, (1 card), and $C_{L} = C_{BUS} + C_{HOST} + C_{CARD} \le$ 40 pF

Figure 34 provides the eSDHC clock input timing diagram.

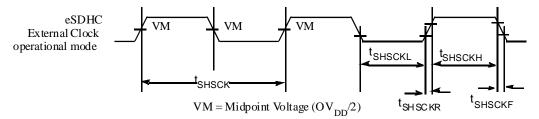


Figure 34. eSDHC Clock Input Timing Diagram

Figure 35 provides the data and command input/output timing diagram.

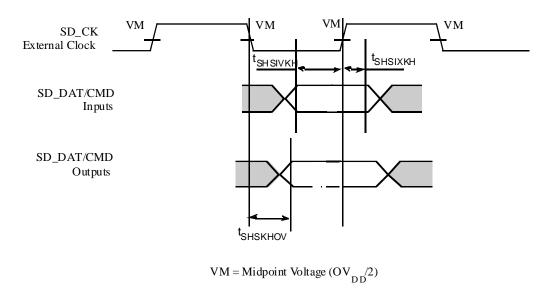


Figure 35. eSDHC Data and Command Input/Output Timing Diagram Referenced to Clock

2.15 Programmable Interrupt Controller (PIC) Specifications

This section describes the DC and AC electrical specifications for PIC.

2.15.1 PIC DC Electrical Characteristics

Table 58 provides the DC electrical characteristics for the PIC interface.

Table 58. PIC DC Electrical Characteristics

For recommended operating conditions, see Table 3.

| Parameter | Symbol | Min | Max | Unit | Notes |
|---|-----------------|-----|-----|------|-------|
| Input high voltage | V _{IH} | 2 | _ | V | 1 |
| Input low voltage | V _{IL} | _ | 0.8 | V | 1 |
| Input current (OV _{IN} = 0V or OV _{IN} = OV _{DD}) | I _{IN} | _ | ±40 | μΑ | 2 |
| Output high voltage (OV _{DD} = min, I _{OH} = -2 mA) | V _{OH} | 2.4 | _ | V | _ |

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Table 58. PIC DC Electrical Characteristics (continued)

For recommended operating conditions, see Table 3.

| Parameter | Symbol | Min | Max | Unit | Notes |
|--|-----------------|-----|-----|------|-------|
| Output low voltage (OV _{DD} = min, I_{OL} = 2 mA) | V _{OL} | - | 0.4 | V | _ |

Note:

- 1. Note that the min V_{IL}and max V_{IH} values are based on the respective min and max OV_{IN} values found in Table 3.
- 2. Note that the symbol OV_{IN} represents the input voltage of the supply. It is referenced in Table 3.

2.15.2 PIC AC Timing Specifications

Table 59 provides the PIC input and output AC timing specifications.

Table 59. PIC Input AC Timing Specifications

For recommended operating conditions, see Table 3

| Parameter | Symbol | Min | Max | Unit | Notes |
|--------------------------------|--------------------|-----|-----|--------|-------|
| PIC inputs—minimum pulse width | t _{PIWID} | 3 | _ | SYSCLK | 1 |

Note:

 PIC inputs and outputs are asynchronous to any visible clock. PIC outputs should be synchronized before use by any external synchronous logic. PIC inputs are required to be valid for at least t_{PIWID} ns to ensure proper operation when working in edge-triggered mode.

2.16 JTAG

This section describes the AC electrical specifications for the IEEE 1149.1 (JTAG) interface of the P1021.

2.16.1 JTAG DC Electrical Characteristics

Table 60 provides the JTAG DC electrical characteristics.

Table 60. JTAG DC Electrical Characteristics

For recommended operating conditions, see Table 3.

| Parameter | Symbol | Min | Max | Unit | Notes |
|---|-----------------|-----|-----|------|-------|
| Input high voltage | V _{IH} | 2 | _ | V | 1 |
| Input low voltage | V _{IL} | _ | 0.8 | V | 1 |
| Input current (OV _{IN} = 0V or OV _{IN} = OV _{DD}) | I _{IN} | _ | ±40 | μΑ | 2 |
| Output high voltage (OV _{DD} = min, I _{OH} = -2 mA) | V _{OH} | 2.4 | _ | V | _ |
| Output low voltage (OV _{DD} = min, I _{OL} = 2 mA) | V _{OL} | _ | 0.4 | V | _ |

Note:

- 1. Note that the min V_{IL} and max V_{IH} values are based on the respective min and max OV_{IN} values found in Table 3.
- 2. Note that the symbol OV_{IN} represents the input voltage of the supply. It is referenced in Table 3.

2.16.2 JTAG AC Timing Specifications

Table 61 provides the JTAG AC timing specifications as defined in Figure 36 through Figure 39.

Table 61. JTAG AC Timing Specifications

For recommended operating conditions see Table 3.

| Parameter | Symbol | Min | Max | Unit | Notes |
|---|---|-----|------|------|-------|
| JTAG external clock frequency of operation | f _{JTG} | 0 | 33.3 | MHz | _ |
| JTAG external clock cycle time | t _{JTG} | 30 | _ | ns | _ |
| JTAG external clock pulse width measured at 1.4 V | t _{JTKHKL} | 15 | _ | ns | _ |
| JTAG external clock rise and fall times | t _{JTGR} and t _{JTGF} | 0 | 2 | ns | _ |
| TRST assert time | t _{TRST} | 25 | _ | ns | 2 |
| Input setup times | t _{JTDVKH} | 4 | _ | ns | _ |
| Input hold times | t _{JTDXKH} | 10 | _ | ns | _ |
| Output valid times | t _{JTKLDV} | 4 | 10 | ns | 3 |
| Output hold times | t _{JTKLDX} | 30 | _ | ns | 3 |

Notes:

- 1. The symbols used for timing specifications follow the pattern t_{(first two letters of functional block)(signal)(state)} (reference)(state) for inputs and t_(first two letters of functional block) (reference)(state)(signal)(state)</sub> for outputs. For example, t_{JTDVKH} symbolizes JTAG device timing (JT) with respect to the time data input signals (D) reaching the valid state (V) relative to the t_{JTG} clock reference (K) going to the high (H) state or setup time. Also, t_{JTDXKH} symbolizes JTAG timing (JT) with respect to the time data input signals (D) reaching the invalid state (X) relative to the t_{JTG} clock reference (K) going to the high (H) state. Note that in general, the clock reference symbol representation is based on three letters representing the clock of aSerDes Transmitter particular functional. For rise and fall times, the latter convention is used with the appropriate letter: R (rise) or F (fall).
- 2. TRST is an asynchronous level sensitive signal. The setup time is for test purposes only.
- 3. All outputs are measured from the midpoint voltage of the falling/rising edge of t_{TCLK} to the midpoint of the signal in question. The output timings are measured at the pins. All output timings assume a purely resistive 50-Ω load. Time-of-flight delays must be added for trace lengths, vias, and connectors in the system.

Figure 36 provides the AC test load for TDO and the boundary-scan outputs.

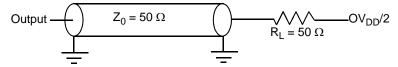
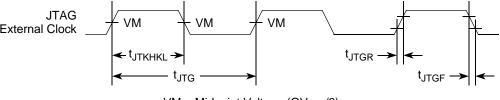


Figure 36. AC Test Load for the JTAG Interface

Figure 37 provides the JTAG clock input timing diagram.



VM = Midpoint Voltage (OV_{DD}/2)

Figure 37. JTAG Clock Input Timing Diagram

Figure 38 provides the TRST timing diagram.

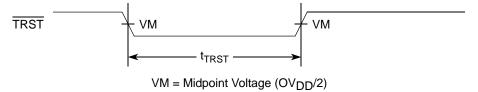


Figure 38. TRST Timing Diagram

Figure 39 provides the boundary-scan timing diagram.

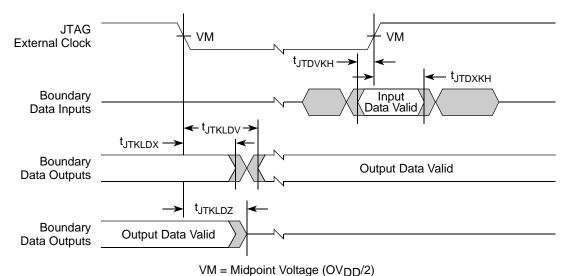


Figure 39. Boundary-Scan Timing Diagram

2.17 I²C

This section describes the DC and AC electrical characteristics for the I²C interfaces.

2.17.1 I²C DC Electrical Characteristics

Table 62 provides the DC electrical characteristics for the I²C interfaces.

Table 62. I²C DC Electrical Characteristics

For recommended operating conditions, see Table 3.

| Parameter | Symbol | Min | Max | Unit | Notes |
|---|---------------------|-----|-----|------|-------|
| Input high voltage | V _{IH} | 2 | _ | V | 1 |
| Input low voltage | V _{IL} | _ | 0.8 | V | 1 |
| Output low voltage | V _{OL} | 0 | 0.4 | V | 2 |
| Pulse width of spikes which must be suppressed by the input filter | t _{I2KHKL} | 0 | 50 | ns | 3 |
| Input current each I/O pin (input voltage is between 0.1 \times OV $_{DD}$ and 0.9 \times OV $_{DD}(max)$ | l _l | -10 | 10 | μА | 4 |

Table 62. I²C DC Electrical Characteristics (continued)

For recommended operating conditions, see Table 3.

| Parameter | Symbol | Min | Max | Unit | Notes |
|------------------------------|----------------|-----|-----|------|-------|
| Capacitance for each I/O pin | C _I | _ | 10 | рF | _ |

Notes:

- 1. Note that the min V_{IL}and max V_{IH} values are based on the respective min and max OV_{IN} values found in Table 3.
- 2. Output voltage (open drain or open collector) condition = 3 mA sink current.
- 3. Refer to the QorIQ P1021 Integrated Processor Reference Manual for information on the digital filter used.
- 4. I/O pins will obstruct the SDA and SCL lines if OV_{DD} is switched off.

2.17.2 I²C AC Electrical Specifications

Table 63 provides the AC timing parameters for the I²C interfaces.

Table 63. I²C AC Electrical Specifications

For recommended operariong conditions see Table 3. All values refer to VIH (min) and VIL (max) levels (see Table 62).

| Parameter | Symbol | Min | Max | Unit | Notes |
|--|---------------------|------------------------------------|-----|------|-------|
| SCL clock frequency | f _{I2C} | 0 | 400 | kHz | 2 |
| Low period of the SCL clock | t _{I2CL} | 1.3 | _ | μS | _ |
| High period of the SCL clock | t _{I2CH} | 0.6 | _ | μS | _ |
| Setup time for a repeated START condition | t _{I2SVKH} | 0.6 | _ | μS | _ |
| Hold time (repeated) START condition (after this period, the first clock pulse is generated) | t _{I2SXKL} | 0.6 | _ | μS | _ |
| Data setup time | t _{I2DVKH} | 100 | _ | ns | _ |
| Data hold time: CBUS compatible masters I ² C bus devices | ^t i2DXKL | 0 | | μS | 3 |
| Data output delay time | t _{I2OVKL} | _ | 0.9 | μS | 4 |
| Set-up time for STOP condition | t _{I2PVKH} | 0.6 | _ | μS | _ |
| Bus free time between a STOP and START condition | t _{I2KHDX} | 1.3 | _ | μS | _ |
| Noise margin at the LOW level for each connected device (including hysteresis) | V _{NL} | $0.1 \times \text{OV}_{\text{DD}}$ | _ | V | _ |
| Noise margin at the HIGH level for each connected device (including hysteresis) | V _{NH} | $0.2 \times \text{OV}_{\text{DD}}$ | _ | V | _ |

Table 63. I²C AC Electrical Specifications (continued)

For recommended operariong conditions see Table 3. All values refer to VIH (min) and VIL (max) levels (see Table 62).

| Parameter | Symbol | Min | Max | Unit | Notes |
|-----------------------------------|--------|-----|-----|------|-------|
| Capacitive load for each bus line | Cb | 1 | 400 | pF | |

Note:

- 1. The symbols used for timing specifications herein follow the pattern t_(first two letters of functional block)(signal)(state)(reference)(state) for inputs and t_(first two letters of functional block)(reference)(state) for outputs. For example, t_{I2DVKH} symbolizes I²C timing (I2) with respect to the time data input signals (D) reaching the valid state (V) relative to the t_{I2C} clock reference (K) going to the high (H) state or setup time. Also, t_{I2SXKL} symbolizes I²C timing (I2) for the time that the data with respect to the START condition (S) went invalid (X) relative to the t_{I2C} clock reference (K) going to the low (L) state or hold time. Also, t_{I2PVKH} symbolizes I²C timing (I2) for the time that the data with respect to the STOP condition (P) reaches the valid state (V) relative to the t_{I2C} clock reference (K) going to the high (H) state or setup time.
- The requirements for I²C frequency calculation must be followed. Refer to Freescale application note AN2919, "Determining the I²C Frequency Divider Ratio for SCL."
- 3. As a transmitter, the processor provides a delay time of at least 300 ns for the SDA signal (referred to as the V_{IHmin} of the SCL signal) to bridge the undefined region of the falling edge of SCL to avoid unintended generation of a START or STOP condition. When the processor acts as the I²C bus master while transmitting, it drives both SCL and SDA. As long as the load on SCL and SDA are balanced, the device does not generate an unintended START or STOP condition. Therefore, the 300 ns SDA output delay time is not a concern. If under some rare condition, the 300 ns SDA output delay time is required for the processor as transmitter, refer to AN2919, "Determining the I²C Frequency Divider Ratio for SCL."
- 4. The maximum t_{I2OVKI} only must be met if the device does not stretch the LOW period (t_{I2CI}) of the SCL signal.

Figure 40 provides the AC test load for the I²C.

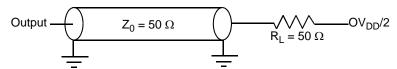


Figure 40. I²C AC Test Load

Figure 41 shows the AC timing diagram for the I^2C bus.

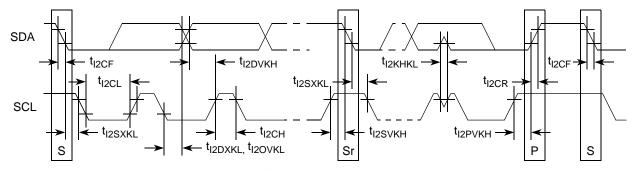


Figure 41. I²C Bus AC Timing Diagram

2.18 High-Speed Serial Interfaces (HSSI)

The P1021 features one Serializer/Deserializer (SerDes) interfaces to be used for high-speed serial interconnect applications. The SerDes interface can be used for PCI Express data transfers and for SGMII application.

This section describes the common portion of SerDes DC electrical specifications, which is the DC requirement for SerDes reference clocks. The SerDes data lane's transmitter and receiver reference circuits are also shown.

2.18.1 Signal Terms Definition

The SerDes utilizes differential signaling to transfer data across the serial link. This section defines terms used in the description and specification of differential signals.

Figure 42 shows how the signals are defined. For illustration purpose, only one SerDes lane is used for description. The figure shows a waveform for either a transmitter output (SDn_TX and $\overline{SDn_TX}$) or a receiver input (SDn_RX and $\overline{SDn_RX}$). Each signal swings between A volts and B volts where A > B.

Using this waveform, the definitions are as follows. To simplify illustration, the following definitions assume that the SerDes transmitter and receiver operate in a fully symmetrical differential signaling environment.

Single-Ended Swing

The transmitter output signals and the receiver input signals SDn_TX , $\overline{SDn_TX}$, SDn_RX and $\overline{SDn_RX}$ each have a peak-to-peak swing of A – B volts. This is also referred as each signal wire's Single-Ended Swing.

• Differential Output Voltage, V_{OD} (or Differential Output Swing):

The Differential Output Voltage (or Swing) of the transmitter, V_{OD} , is defined as the difference of the two complimentary output voltages: $V_{SDn_TX} - V_{\overline{SDn_TX}}$. The V_{OD} value can be either positive or negative.

• Differential Input Voltage, V_{ID} (or Differential Input Swing):

The Differential Input Voltage (or Swing) of the receiver, V_{ID} , is defined as the difference of the two complimentary input voltages: $V_{SDn_RX} - V_{\overline{SDn_RX}}$. The V_{ID} value can be either positive or negative.

• Differential Peak Voltage, V_{DIFFp}

The peak value of the differential transmitter output signal or the differential receiver input signal is defined as Differential Peak Voltage, $V_{DIFFD} = |A - B|$ Volts.

• Differential Peak-to-Peak, VDIFFp-p

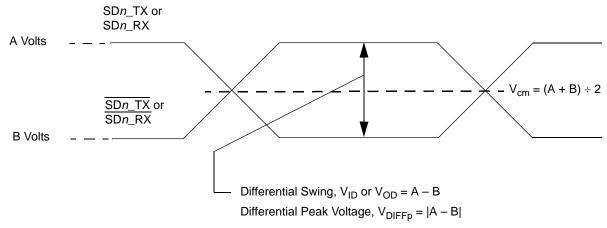
Since the differential output signal of the transmitter and the differential input signal of the receiver each range from A-B to -(A-B) Volts, the peak-to-peak value of the differential transmitter output signal or the differential receiver input signal is defined as Differential Peak-to-Peak Voltage, $V_{DIFFp-p} = 2 \times V_{DIFFp} = 2 \times |(A-B)|$ Volts, which is twice of differential swing in amplitude, or twice of the differential peak. For example, the output differential peak-peak voltage can also be calculated as $V_{TX-DIFFp-p} = 2 \times |V_{OD}|$.

• Differential Waveform

The differential waveform is constructed by subtracting the inverting signal (SDn_TX, for example) from the non-inverting signal (SDn_TX, for example) within a differential pair. There is only one signal trace curve in a differential waveform. The voltage represented in the differential waveform is not referenced to ground. Refer to Figure 42 as an example for differential waveform.

Common Mode Voltage, V_{cm}

The Common Mode Voltage is equal to one half of the sum of the voltages between each conductor of a balanced interchange circuit and ground. In this example, for SerDes output, $V_{cm_out} = (VSDn_TX + VSDn_TX)/2 = (A + B) / 2$, which is the arithmetic mean of the two complimentary output voltages within a differential pair. In a system, the common mode voltage may often differ from one component's output to the other's input. Sometimes, it may even be different between the receiver input and driver output circuits within the same component. It is also referred to as the DC offset occasionally.



Differential Peak-Peak Voltage, $V_{DIFFpp} = 2 \times V_{DIFFp}$ (not shown)

Figure 42. Differential Voltage Definitions for Transmitter or Receiver

To illustrate these definitions using real values, consider the case of a CML (Current Mode Logic) transmitter that has a common mode voltage of 2.25 V and each of its outputs, TD and $\overline{\text{TD}}$, has a swing that goes between 2.5 V and 2.0 V. Using these values, the peak-to-peak voltage swing of each signal (TD or $\overline{\text{TD}}$) is 500 mV p-p, which is referred as the single-ended swing for each signal. In this example, since the differential signaling environment is fully symmetrical, the transmitter output's differential swing (V_{OD}) has the same amplitude as each signal's single-ended swing. The differential output signal ranges between 500 mV and –500 mV, in other words, V_{OD} is 500 mV in one phase and –500 mV in the other phase. The peak differential voltage (V_{DIFFp}) is 500 mV. The peak-to-peak differential voltage (V_{DIFFp}) is 1000 mV p-p.

2.18.2 SerDes Reference Clocks

The SerDes reference clock inputs are applied to an internal PLL whose <u>output creates</u> the clock used by the corresponding SerDes lanes. The SerDes reference clock inputs are SD_REF_CLK and SD_REF_CLK for PCI Express and SGMII interface.

The following sections describe the SerDes reference clock requirements and some application information.

2.18.2.1 SerDes Reference Clock Receiver Characteristics

Figure 43 shows a receiver reference diagram of the SerDes reference clocks.

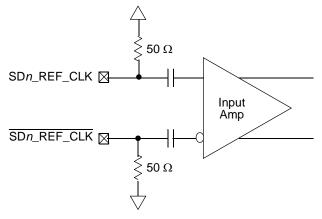


Figure 43. Receiver of SerDes Reference Clocks

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The characteristics of the clock signals are as follows:

- The supply voltage requirements for XV_{DD SRDS2} are specified in Table 2 and Table 3.
- SerDes reference clock receiver reference circuit structure
 - The SD_REF_CLK and SD_REF_CLK are internally AC-coupled differential inputs as shown in Figure 43. Each differential clock input (SD_REF_CLK or SD_REF_CLK) has a 50-Ω termination to SGND_SRDS followed by on-chip AC-coupling.
 - The external reference clock driver must be able to drive this termination.
 - The SerDes reference clock input can be either differential or single-ended. Refer to the differential mode and single-ended mode descriptions in Section 2.18.2.2, "DC Level Requirement for SerDes Reference Clocks," for requirements.
- The maximum average current requirement that also determines the common mode voltage range.
 - When the SerDes reference clock differential inputs are DC coupled externally with the clock driver chip, the maximum average current allowed for each input pin is 8 mA. In this case, the exact common mode input voltage is not critical as long as it is within the range allowed by the maximum average current of 8 mA (refer to the following bullet for more detail), since the input is AC-coupled on-chip.
 - This current limitation sets the maximum common mode input voltage to be less than $0.4~V~(0.4~V \div 50 = 8~mA)$ while the minimum common mode input level is $0.1~V~above~SGND_SRDS$. For example, a clock with a 50/50~duty~cycle can be produced by a clock driver with output driven by its current source from 0~mA to 16~mA~(0-0.8~V), such that each phase of the differential input has a single-ended swing from 0~V~to~800~mV with the common mode voltage at 400~mV.
 - If the device driving the SD_REF_CLK and $\overline{\text{SD}_{REF}_{CLK}}$ inputs cannot drive 50 Ω to SGND_SRDS DC, or it exceeds the maximum input current limitations, then it must be AC-coupled off-chip.

2.18.2.2 DC Level Requirement for SerDes Reference Clocks

The DC level requirement for the SerDes reference clock inputs is different depending on the signaling mode used to connect the clock driver chip and SerDes reference clock inputs as described below.

• Differential Mode

- The input amplitude of the differential clock must be between 400 mV and 1600 mV differential peak-peak (or between 200 mV and 800 mV differential peak). In other words, each signal wire of the differential pair must have a single-ended swing less than 800 mV and greater than 200 mV. This requirement is the same for both external DC-coupled or AC-coupled connection.
- For external DC-coupled connection, as described in Section 2.18.2.1, "SerDes Reference Clock Receiver Characteristics," the maximum average current requirements sets the requirement for average voltage (common mode voltage) to be between 100 mV and 400 mV. Figure 44 shows the SerDes reference clock input requirement for DC-coupled connection scheme.
- For external AC-coupled connection, there is no common mode voltage requirement for the clock driver. Since the external AC-coupling capacitor blocks the DC level, the clock driver and the SerDes reference clock receiver operate in different command mode voltages. The SerDes reference clock receiver in this connection scheme has its common mode voltage set to SGND_SRDS. Each signal wire of the differential inputs is allowed to swing below and above the command mode voltage (SGND_SRDS). Figure 45 shows the SerDes reference clock input requirement for AC-coupled connection scheme.

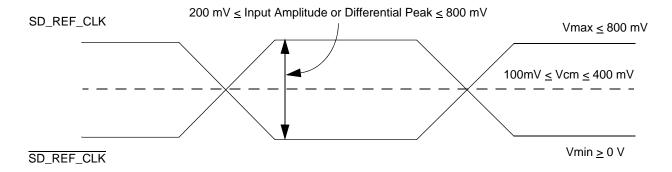


Figure 44. Differential Reference Clock Input DC Requirements (External DC-Coupled)

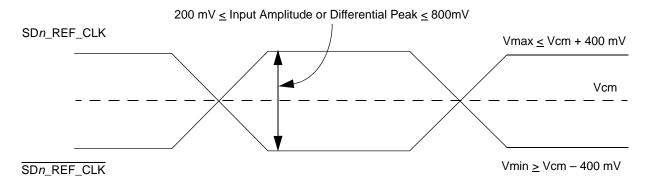


Figure 45. Differential Reference Clock Input DC Requirements (External AC-Coupled)

Single-ended Mode

- The reference clock can also be single ended. The SD_REF_CLK input amplitude (single-ended swing) must be between 400 mV and 800 mV peak-peak (from V_{MIN} to V_{MAX}) with SD_REF_CLK either left unconnected or tied to ground.
- The SD_REF_CLK input average voltage must be between 200 and 400 mV. Figure 46 shows the SerDes reference clock input requirement for single-ended signaling mode.
- To meet the input amplitude requirement, the reference clock inputs might need to be DC or AC coupled externally. For the best noise performance, the reference of the clock could be DC or AC coupled into the unused phase (SD_REF_CLK) through the same source impedance as the clock input (SD_REF_CLK) in use.

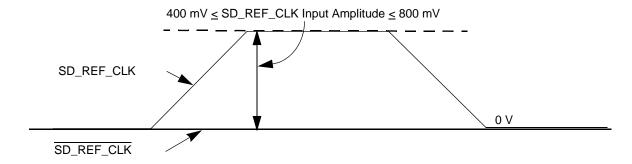


Figure 46. Single-Ended Reference Clock Input DC Requirements

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2.18.2.3 AC Requirements for SerDes Reference Clocks

Table 64 lists AC requirements for the PCI Express and SGMII SerDes reference clocks to be guaranteed by the customer's application design.

Table 64. SD_REF_CLK and SD_REF_CLK Input Clock Requirements

| Parameter | Symbol | Min | Typical | Max | Unit | Notes |
|---|--|------|---------|------|------|-------|
| SD_REF_CLK/ SD_REF_CLK frequency range | t _{CLK_REF} | _ | 100/125 | _ | MHz | 1 |
| SD_REF_CLK/ SD_REF_CLK clock frequency tolerance | ^t CLK_TOL | -350 | _ | +350 | ppm | _ |
| SD_REF_CLK/ SD_REF_CLK reference clock duty cycle (Measured at 1.6 V) | ^t CLK_DUTY | 40 | 50 | 60 | % | _ |
| SD_REF_CLK/ SD_REF_CLK max deterministic peak-peak Jitter at 10 ⁻⁶ BER | t _{CLK_DJ} | _ | _ | 42 | ps | _ |
| SD_REF_CLK/ SD_REF_CLK total reference clock jitter at 10 ⁻⁶ BER (Peak-to-peak jitter at refClk input) | ^t CLK_TJ | _ | _ | 86 | ps | 2 |
| SD_REF_CLK/ SD_REF_CLK rising/falling edge rate | ^t CLKRR ^{/t} CLKFR | 1 | _ | 4 | V/ns | 3 |

Notes:

- 1. Only 100/125 have been tested, other in between values will not work correctly with the rest of the system.
- 2. Limits from PCI Express CEM Rev 2.0
- 3. Measured from –200 mV to +200 mV on the differential waveform (derived from SDn_REF_CLK minus SDn_REF_CLK). The signal must be monotonic through the measurement region for rise and fall time. The 400 mV measurement window is centered on the differential zero crossing. See Figure 47.
- 4. Measurement taken from differential waveform
- 5. Measurement taken from single-ended waveform
- 6. Matching applies to rising edge for SD*n*_REF_CLK and falling edge rate for SD*n*_REF_CLK. It is measured using a 200 mV window centered on the median cross point where SD*n*_REF_CLK rising meets SD*n*_REF_CLK falling. The median cross point is used to calculate the voltage thresholds that the oscilloscope uses for the edge rate calculations. The rise edge rate of SD*n*_REF_CLK should be compared to the fall edge rate of SD*n*_REF_CLK, the maximum allowed difference should not exceed 20% of the slowest edge rate. See Figure 48.

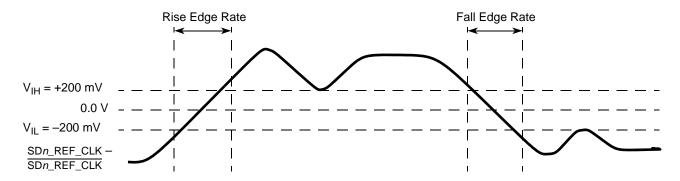


Figure 47. Differential Measurement Points for Rise and Fall Time

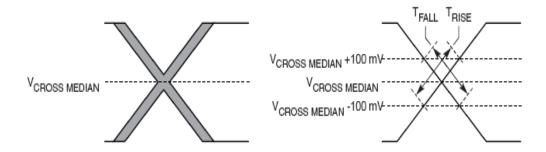


Figure 48. Single-Ended Measurement Points for Rise and Fall Time Matching

2.18.2.4 SerDes Transmitter and Receiver Reference Circuits

Figure 49 shows the reference circuits for SerDes data lane's transmitter and receiver.

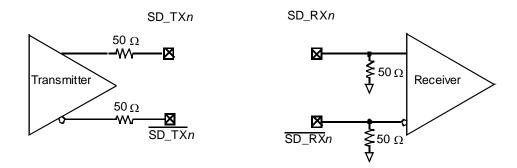


Figure 49. SerDes Transmitter and Receiver Reference Circuits

The DC and AC specification of SerDes data lanes are defined in each interface protocol section below (PCI Express, Serial Rapid IO or SGMII) in this document based on the application usage:

- Section 2.11.4, "SGMII Interface Electrical Characteristics"
- Section 2.19, "PCI Express"

Note that an external AC-coupling capacitor is required for the above three serial transmission protocols per the protocol's standard requirements.

2.19 PCI Express

This section describes the DC and AC electrical specifications for the PCI Express bus.

2.19.1 PCI Express DC Requirements for PCI Express SD_REF_CLK and SD_REF_CLK

For more information, see Section 2.18.2.2, "DC Level Requirement for SerDes Reference Clocks."

2.19.2 PCI Express DC Physical Layer Specifications

This section contains the DC specifications for the physical layer of PCI Express on this device.

2.19.2.1 PCI Express DC Physical Layer Transmitter Specifications

This section discusses PCI Express DC physical layer transmitter specifications for 2.5 Gb/s.

Table 65 defines the PCI Express (2.5 Gb/s) DC specifications for the differential output at all transmitters (TXs). The parameters are specified at the component pins.

Table 65. PCI Express (2.5Gb/s) Differential Transmitter (TX) Output DC Specifications

| Symbol | Parameter | Min | Typical | Max | Units | Comments |
|--------------------------|--|-----|---------|------|-------|--|
| V _{TX-DIFFp-p} | Differential Peak-to-Peak Output Voltage | 800 | 1000 | 1200 | mV | $V_{TX-DIFFp-p} = 2 \times V_{TX-D+} - V_{TX-D-} $ See Note 1. |
| V _{TX-DE-RATIO} | De-emphasized Differential Output Voltage (Ratio) | 3.0 | 3.5 | 4.0 | dB | Ratio of the $V_{TX-DIFFp-p}$ of the second and following bits after a transition divided by the $V_{TX-DIFFp-p}$ of the first bit after a transition. See Note 1. |
| Z _{TX-DIFF-DC} | DC Differential TX Impedance | 80 | 100 | 120 | Ω | TX DC Differential mode low Impedance |
| Z _{TX-DC} | Transmitter DC Impedance | 40 | 50 | 60 | Ω | Required TX D+ as well as D– DC impedance during all states |

Note:

^{1.} Specified at the measurement point into a timing and voltage compliance test load as shown in Figure 50 and measured over any 250 consecutive TX UIs.

2.19.2.2 PCI Express DC Physical Layer Receiver Specifications

This section discusses PCI Express DC physical layer receiverspecifications for 2.5 Gb/s.

Table 66 defines the PCI Express (2.5 Gb/s) DC specifications for the differential output at all receivers (RXs). The parameters are specified at the component pins.

Table 66. PCI Express (2.5 Gb/s) Differential Receiver (RX) Input DC Specifications

| Symbol | Parameter | Min | Typical | Max | Units | Comments |
|----------------------------------|---|------|---------|------|-------|---|
| V _{RX-DIFFp-p} | Differential Input Peak-to-Peak Voltage | 175 | _ | 1200 | mV | $V_{RX-DIFFp-p} = 2 \times V_{RX-D+} - V_{RX-D-} $ See Note 1. |
| Z _{RX-DIFF-DC} | DC Differential Input Impedance | 80 | 100 | 120 | Ω | RX DC differential mode impedance. See Note 2 |
| Z _{RX-DC} | DC Input Impedance | 40 | 50 | 60 | Ω | Required RX D+ as well as D- DC impedance (50 ± 20% tolerance). See Notes 1 and 2. |
| Z _{RX-HIGH-IMP-DC} | Powered Down DC Input Impedance | 50 k | _ | | Ω | Required RX D+ as well as D– DC impedance when the receiver terminations do not have power. See Note 3. |
| V _{RX-IDLE-DET-DIFFp-p} | Electrical Idle Detect Threshold | 65 | _ | 175 | mV | V _{RX-IDLE-DET-DIFFp-p} = 2 x V _{RX-D+} -V _{RX-D-} Measured at the package pins of the receiver |

Notes:

- 1. Specified at the measurement point and measured over any 250 consecutive UIs. The test load in Figure 50 should be used as the RX device when taking measurements. If the clocks to the RX and TX are not derived from the same reference clock, the TX UI recovered from 3500 consecutive UI must be used as a reference for the eye diagram.
- 2. Impedance during all LTSSM states. When transitioning from a fundamental reset to detect (the initial state of the LTSSM) there is a 5 ms transition time before receiver termination values must be met on all unconfigured lanes of a port.
- 3. The RX DC common mode Impedance that exists when no power is present or fundamental reset is asserted. This helps ensure that the Receiver Detect circuit will not falsely assume a receiver is powered on when it is not. This term must be measured at 300 mV above the RX ground.

2.19.3 PCI Express AC Physical Layer Specifications

This section contains the DC specifications for the physical layer of PCI Express on this device.

2.19.3.1 PCI Express AC Physical Layer Transmitter Specifications

This section discusses the PCI Express AC physical layer transmitter specifications for 2.5Gb/s.

Table 67 defines the PCI Express (2.5Gb/s) AC specifications for the differential output at all transmitters (TXs). The parameters are specified at the component pins. The AC timing specifications do not include RefClk jitter.

Table 67. PCI Express (2.5Gb/s) Differential Transmitter (TX) Output AC Specifications

| Symbol | Parameter | Min | Typical | Max | Units | Comments |
|--|---|--------|---------|--------|-------|---|
| UI | Unit Interval | 399.88 | 400.00 | 400.12 | ps | Each UI is 400 ps ± 300 ppm. UI does not account for spread-spectrum-clock-dictated variations. See Note 1. |
| T _{TX-EYE} | Minimum TX Eye Width | 0.70 | _ | _ | UI | The maximum transmitter jitter can be derived as $T_{TX-MAX-JITTER} = 1 - T_{TX-EYE} = 0.3 UI$. See Notes 2 and 3. |
| T _{TX-EYE-MEDIAN-to} - MAX-JITTER | Maximum time between the jitter median and maximum deviation from the median. | _ | _ | 0.15 | UI | Jitter is defined as the measurement variation of the crossing points (V _{TX-DIFFp-p} = 0 V) in relation to a recovered TX UI. A recovered TX UI is calculated over 3500 consecutive unit intervals of sample data. Jitter is measured using all edges of the 250 consecutive UI in the center of the 3500 UI used for calculating the TX UI. See Notes 2 and 3. |
| C _{TX} | AC Coupling Capacitor | 75 | _ | 200 | nF | All transmitters shall be AC coupled. The AC coupling is required either within the media or within the transmitting component itself. See Note 4. |

Notes:

- 1. No test load is necessarily associated with this value.
- 2. Specified at the measurement point into a timing and voltage compliance test load as shown in Figure 50 and measured over any 250 consecutive TX UIs.
- 3. A $T_{TX-EYE} = 0.70$ UI provides for a total sum of deterministic and random jitter budget of $T_{TX-JITTER-MAX} = 0.30$ UI for the Transmitter collected over any 250 consecutive TX UIs. The $T_{TX-EYE-MEDIAN-to-MAX-JITTER}$ median is less than half of the total TX jitter budget collected over any 250 consecutive TX UIs. It should be noted that the median is not the same as the mean. The jitter median describes the point in time where the number of jitter points on either side is approximately equal as opposed to the averaged time value.
- 4. SerDes transmitter does not have CTX built-in. An external AC-coupling capacitor is required.

2.19.3.2 PCI Express AC Physical Layer Receiver Specifications

This section discusses the PCI Express AC physical layer receiver specifications for 2.5 Gb/s.

Table 68 defines the AC specifications for the PCI Express (2.5 Gb/s) differential input at all receivers (RXs). The parameters are specified at the component pins. The AC timing specifications do not include RefClk jitter.

Table 68. PCI Express (2.5 Gb/s) Differential Receiver (RX) Input AC Specifications

| Symbol | Parameter | Min | Typical | Max | Units | Comments |
|---------------------|----------------------------------|--------|---------|--------|-------|---|
| UI | Unit Interval | 399.88 | 400.00 | 400.12 | ps | Each UI is 400 ps ± 300 ppm. UI does not account for Spread Spectrum Clock dictated variations. See Note 1. |
| T _{RX-EYE} | Minimum Receiver Eye Width | 0.4 | _ | _ | UI | The maximum interconnect media and Transmitter jitter that can be tolerated by the Receiver can be derived as $T_{RX-MAX-JITTER} = 1 - T_{RX-EYE} = 0.6$ UI. See Notes 2 and 3. |

Table 68. PCI Express (2.5 Gb/s) Differential Receiver (RX) Input AC Specifications (continued)

| Symbol | Parameter | Min | Typical | Max | Units | Comments |
|---|--|-----|---------|-----|-------|--|
| T _{RX-EYE-MEDIAN-to-} MAX-JITTER | Maximum time between the jitter median and maximum devia- tion from the median. | | 1 | 0.3 | UI | Jitter is defined as the measurement variation of the crossing points ($V_{RX-DIFFp-p}=0$ V) in relation to a recovered TX UI. A recovered TX UI is calculated over 3500 consecutive unit intervals of sample data. Jitter is measured using all edges of the 250 consecutive UI in the center of the 3500 UI used for calculating the TX UI. See Notes 2, 3 and 4. |

Notes:

- 1. No test load is necessarily associated with this value.
- 2. Specified at the measurement point and measured over any 250 consecutive UIs. The test load in Figure 50 should be used as the RX device when taking measurements. If the clocks to the RX and TX are not derived from the same reference clock, the TX UI recovered from 3500 consecutive UI must be used as a reference for the eye diagram.
- 3. A T_{RX-EYE} = 0.40 UI provides for a total sum of 0.60 UI deterministic and random jitter budget for the Transmitter and interconnect collected any 250 consecutive UIs. The TRX-EYE-MEDIAN-to-MAX-JITTER specification ensures a jitter distribution in which the median and the maximum deviation from the median is less than half of the total. UI jitter budget collected over any 250 consecutive TX UIs. It should be noted that the median is not the same as the mean. The jitter median describes the point in time where the number of jitter points on either side is approximately equal as opposed to the averaged time value. If the clocks to the RX and TX are not derived from the same reference clock, the TX UI recovered from 3500 consecutive UI must be used as the reference for the eye diagram.
- 4. It is recommended that the recovered TX UI is calculated using all edges in the 3500 consecutive UI interval with a fit algorithm using a minimization merit function. Least squares and median deviation fits have worked well with experimental and simulated data.

2.19.3.3 Compliance Test and Measurement Load

The AC timing and voltage parameters must be verified at the measurement point, as specified within 0.2 inches of the package pins, into a test/measurement load shown in Figure 50.

NOTE

The allowance of the measurement point to be within 0.2 inches of the package pins is meant to acknowledge that package/board routing may benefit from D+ and D- not being exactly matched in length at the package pin boundary. If the vendor does not explicitly state where the measurement point is located, the measurement point is assumed to be the D+ and D- package pins.

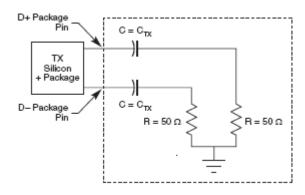


Figure 50. Compliance Test/Measurement Load

3 QUICC Engine Block Specifications

3.1 Ethernet Interface

This section provides the AC and DC electrical characteristics for the Ethernet interfaces inside the QUICC Engine block.

3.1.1 MII and RMII DC Electrical Characteristics

Table 69 shows the MII and RMII DC electrical characteristics

Table 69. MII and RMII DC Electrical Characteristics

| Parameter | Symbol | Min | Max | Unit | Notes |
|---|-----------------|------|------------------------|------|-------|
| Input high voltage | V _{IH} | 2.0 | _ | V | 1 |
| Input low voltage | V _{IL} | _ | 0.8 | V | _ |
| Input high current (V _{IN} = BV _{DD}) | I _{IH} | _ | 40 | μΑ | 2 |
| Input low current (V _{IN} = GND) | I _{IL} | -600 | _ | μΑ | 2 |
| Output high voltage (BV _{DD} = Min, I _{OH} = -4.0 mA) | V _{OH} | 2.4 | BV _{DD} + 0.3 | V | _ |
| Output low voltage (BV _{DD} = Min, I _{OL} = 4.0 mA) | V _{OL} | GND | 0.4 | V | _ |

Note:

- 1. Note that the min V_{IL} and max V_{IH} values are based on the respective min and max LV_{IN} values found in Table 3.
- 2. The symbol V_{IN} , in this case, represents the LV_{IN} symbols referenced in Table 2 and Table 3.

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3.1.2 MII AC Timing Specifications

This section describes the MII transmit and receive AC timing specifications.

Table 70 provides the MII transmit AC timing specifications.

Table 70. MII Transmit AC Timing Specifications

For recommended operating conditions, see Table 3

| Parameter/Condition | Symbol | Min | Тур | Max | Unit |
|---|-------------------------------------|--------|-----|--------|------|
| TX_CLK clock period 10 Mbps | t _{MTX} | 399.96 | 400 | 400.04 | ns |
| TX_CLK clock period 100 Mbps | t _{MTX} | 39.996 | 40 | 40.004 | ns |
| TX_CLK duty cycle | t _{MTXH} /t _{MTX} | 35 | _ | 65 | % |
| TX_CLK to MII data TXD[3:0], TX_ER, TX_EN delay | t _{MTKHDX} | 1 | _ | 15 | ns |
| TX_CLK data clock rise (20%–80%) | t _{MTXR} | 1.0 | _ | 4.0 | ns |
| TX_CLK data clock fall (80%–20%) | t _{MTXF} | 1.0 | _ | 4.0 | ns |

Figure 51 shows the MII transmit AC timing diagram.

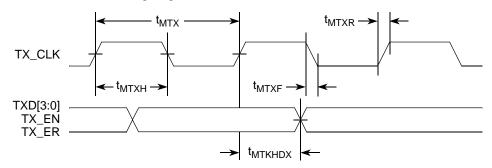


Figure 51. MII Transmit AC Timing Diagram

Table 71 provides the MII receive AC timing specifications.

Table 71. MII Receive AC Timing Specifications

For recommended operating conditions, see Table 3.

| Parameter/Condition | Symbol | Min | Тур | Max | Unit |
|---|-------------------------------------|--------|-----|--------|------|
| RX_CLK clock period 10 Mbps | t _{MRX} | 399.96 | 400 | 400.04 | ns |
| RX_CLK clock period 100 Mbps | t _{MRX} | 39.996 | 40 | 40.004 | ns |
| RX_CLK duty cycle | t _{MRXH} /t _{MRX} | 35 | _ | 65 | % |
| RXD[3:0], RX_DV, RX_ER setup time to RX_CLK | t _{MRDVKH} | 10.0 | _ | _ | ns |
| RXD[3:0], RX_DV, RX_ER hold time to RX_CLK | t _{MRDXKH} | 10.0 | _ | _ | ns |
| RX_CLK clock rise (20%–80%) | t _{MRXR} | 1.0 | _ | 4.0 | ns |
| RX_CLK clock fall time (80%–20%) | t _{MRXF} | 1.0 | _ | 4.0 | ns |

Note: The frequency of RX_CLK should not exceed the frequency of TX_CLK by more than 300 ppm.

Figure 52 shows the MII receive AC timing diagram.

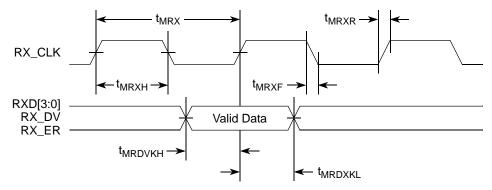


Figure 52. MII Receive AC Timing Diagram

Figure 53 provides the MII AC test load.

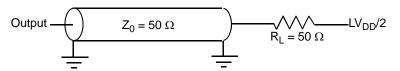


Figure 53. MII AC Test Load

3.1.3 RMII AC Timing Specifications

This section describes the RMII transmit and receive AC timing specifications.

The RMII transmit AC timing specifications are in Table 72.

Table 72. RMII Transmit AC Timing Specifications

For recommended operating conditions, see Table 3

| Parameter | Symbol | Min | Тур | Max | Unit |
|--|--------------------|-----|------|------|------|
| REF_CLK clock period | t _{RMT} | _ | 20.0 | _ | ns |
| REF_CLK duty cycle | t _{RMTH} | 35 | _ | 65 | % |
| REF_CLK peak-to-peak jitter | t _{RMTJ} | _ | _ | 250 | ps |
| Rise time REF_CLK (20%–80%) | t _{RMTR} | 1.0 | _ | 5.0 | ns |
| Fall time REF_CLK (80%–20%) | t _{RMTF} | 1.0 | _ | 5.0 | ns |
| REF_CLK to RMII data TXD[1:0], TX_EN delay | t _{RMTDX} | 2.0 | _ | 10.0 | ns |

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Figure 54 shows the RMII transmit AC timing diagram.

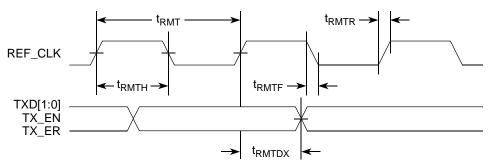


Figure 54. RMII Transmit AC Timing Diagram

Table 73 provides the MII receive AC timing specifications.

Table 73. RMII Receive AC Timing Specifications

For recommended operating conditions, see Table 3

| Parameter | Symbol | Min | Тур | Max | Unit |
|---|----------------------|-----|------|-----|------|
| REF_CLK clock period | t _{RMR} | _ | 20.0 | _ | ns |
| REF_CLK duty cycle | t _{RMRH} | 35 | _ | 65 | % |
| REF_CLK peak-to-peak jitter | t _{RMRJ} | _ | _ | 250 | ps |
| Rise time REF_CLK (20%-80%) | t _{RMRR} | 1.0 | _ | 5.0 | ns |
| Fall time REF_CLK (80% –20%) | t _{RMRF} | 1.0 | _ | 5.0 | ns |
| RXD[1:0], CRS_DV, RX_ER setup time to REF_CLK rising edge | t _{RMRDVKH} | 4.0 | _ | _ | ns |
| RXD[1:0], CRS_DV, RX_ER hold time to REF_CLK rising edge | t _{RMRKHDX} | 2.0 | _ | _ | ns |

Figure 55 shows the RMII receive AC timing diagram.

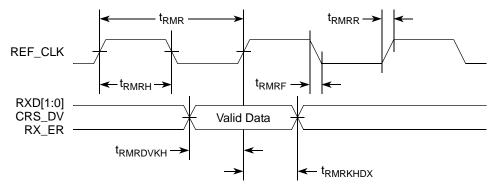


Figure 55. RMII Receive AC Timing Diagram

Figure 56 provides the AC test load.

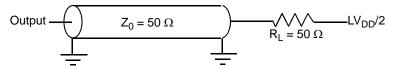


Figure 56. AC Test Load

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3.2 HDLC, BISYNC, Transparent, and Synchronous UART Interfaces

This section describes the DC and AC electrical specifications for the high level data link control (HDLC), BISYNC, transparent and synchronous UART.

3.2.1 HDLC, BISYNC, Transparent and Synchronous UART DC Electrical Characteristics

Table 74 provides the DC electrical characteristics for the HDLC, BISYNC, Transparent and Synchronous UART protocols.

Table 74. HDLC, BiSync, Transparent and Synchronous UART DC Electrical Characteristics

For recommended operating conditions, see Table 3.

| Parameter | Symbol | Min | Max | Unit | Notes |
|--|-----------------|-----|-----|------|-------|
| Input high voltage | V _{IH} | 2.0 | _ | V | 1 |
| Input low voltage | V _{IL} | _ | 0.8 | V | 1 |
| Input current (BV _{IN} = 0 V or BV _{IN} = BV _{DD}) | I _{IN} | _ | ±40 | μΑ | 2 |
| Output high voltage (BV _{DD} = min, I _{OH} = -2 mA) | V _{OH} | 2.4 | _ | V | _ |
| Output low voltage (BV _{DD} = min, I _{OH} = 2 mA) | V _{OL} | _ | 0.4 | V | _ |

Note:

- 1. Note that the min V_{IL} and max V_{IH} values are based on the respective min and max BV_{IN} values found in Table 3.
- 2. Note that the symbol BV_{IN} represents the input voltage of the supply. It is referenced in Table 3.

3.2.2 HDLC, BISYNC, Transparent and Synchronous UART AC Timing Specifications

Table 75 provides the input and output AC timing specifications for HDLC, BiSync, and Transparent and Synchronous UART protocols.

Table 75. HDLC, BiSync, Transparent AC Timing Specifications

For recommended operating conditions, see Table 3.

| Parameter | Symbol ¹ | Min | Max | Unit | Notes |
|--|---------------------|-----|-----|------|-------|
| Outputs—Internal clock delay | t _{HIKHOV} | 0 | 5.5 | ns | 2 |
| Outputs—External clock delay | t _{HEKHOV} | 1 | 8 | ns | 2 |
| Outputs—Internal clock High Impedance | t _{HIKHOX} | 0 | 5.5 | ns | 2 |
| Outputs—External clock High Impedance | t _{HEKHOX} | 1 | 8 | ns | 2 |
| Inputs—Internal clock input setup time | t _{HIIVKH} | 6 | _ | ns | _ |
| Inputs—External clock input setup time | t _{HEIVKH} | 4 | _ | ns | _ |
| Inputs—Internal clock input Hold time | t _{HIIXKH} | 0 | _ | ns | _ |

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Table 75. HDLC, BiSync, Transparent AC Timing Specifications (continued)

For recommended operating conditions, see Table 3.

| Parameter | Symbol ¹ | Min | Max | Unit | Notes |
|---------------------------------------|---------------------|-----|-----|------|-------|
| Inputs—External clock input hold time | t _{HEIXKH} | 1 | _ | ns | _ |

Notes:

- 1. The symbols used for timing specifications follow the pattern t_{(first two letters of functional block)(signal)(state)} for inputs and t_(first two letters of functional block)(reference)(state)(signal)(state) for outputs. For example, t_{HIKHOX} symbolizes the outputs internal timing (HI) for the time t_{serial} memory clock reference (K) goes from the high state (H) until outputs (O) are invalid (X).
- 2. Output specifications are measured from the 50% level of the rising edge of CLKIN to the 50% level of the signal. Timings are measured at the pin.

Table 76 provides the input and output AC timing specifications for the synchronous UART protocols.

Table 76. Synchronous UART AC Timing Specifications

For recommended operating conditions, see Table 3

| Parameter | Symbol ¹ | Min | Max | Unit | Notes |
|--|---------------------|-----|-----|------|-------|
| Outputs—Internal clock delay | t _{HIKHOV} | 0 | 11 | ns | 2 |
| Outputs—External clock delay | t _{HEKHOV} | 1 | 14 | ns | 2 |
| Outputs—Internal clock High Impedance | t _{HIKHOX} | 0 | 11 | ns | 2 |
| Outputs—External clock High Impedance | t _{HEKHOX} | 1 | 14 | ns | 2 |
| Inputs—Internal clock input setup time | t _{HIIVKH} | 10 | _ | ns | _ |
| Inputs—External clock input setup time | t _{HEIVKH} | 8 | _ | ns | _ |
| Inputs—Internal clock input Hold time | t _{HIIXKH} | 0 | _ | ns | _ |
| Inputs—External clock input hold time | t _{HEIXKH} | 1 | _ | ns | _ |

Notes:

- 1. Output specifications are measured from the 50% level of the rising edge of CLKIN to the 50% level of the signal. Timings are measured at the pin.
- 2. The symbols used for timing specifications follow the pattern of $t_{(first\ two\ letters\ of\ functional\ block)(signal)(state)}$ for inputs and $t_{(first\ two\ letters\ of\ functional\ block)(reference)(state)(signal)(state)}$ for outputs. For example, t_{HIKHOX} symbolizes the outputs internal timing (HI) for the time t_{serial} memory clock reference (K) goes from the high state (H) until outputs (O) are invalid (X).

Figure 57 provides the AC test load.

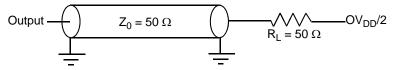
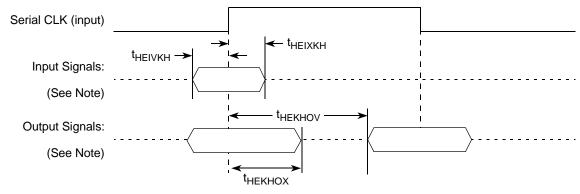


Figure 57. AC Test Load

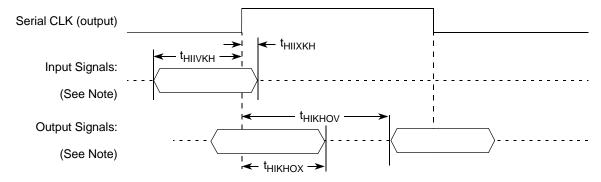
Figure 58 and Figure 59 represent the AC timing from Table 75 and Table 76. Note that although the specifications generally reference the rising edge of the clock, these AC timing diagrams also apply when the falling edge is the active edge. Figure 58 shows the timing with external clock.



Note: The clock edge is selectable

Figure 58. AC Timing (External Clock) Diagram

Figure 59 shows the timing with internal clock.



Note: The clock edge is selectable

Figure 59. AC Timing (Internal Clock) Diagram

3.3 TDM/SI

This section describes the DC and AC electrical specifications for the time-division-multiplexed and serial interface (TDM/SI).

3.3.1 TDM/SI DC Electrical Characteristics

Table 77 provides the TDM/SI DC electrical characteristics.

Table 77. TDM/SI DC Electrical Characteristics

For recommended operating conditions, see Table 3.

| Parameter | Symbol | Min | Max | Unit | Notes |
|--|-----------------|-----|-----|------|-------|
| Input high voltage | V _{IH} | 2.0 | _ | V | 1 |
| Input low voltage | V _{IL} | _ | 0.8 | V | 1 |
| Input current (BV _{IN} = 0 V or BV _{IN} = BV _{DD}) | I _{IN} | _ | ±40 | μΑ | 2 |

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Table 77. TDM/SI DC Electrical Characteristics (continued)

For recommended operating conditions, see Table 3.

| Parameter | Symbol | Min | Max | Unit | Notes |
|---|-----------------|-----|-----|------|-------|
| Output high voltage (BV _{DD} = min, $I_{OH} = -2 \text{ mA}$) | V _{OH} | 2.4 | | V | _ |
| Output low voltage (BV _{DD} = min, I _{OH} = 2 mA) | V _{OL} | _ | 0.4 | V | _ |

Note:

- 1. Note that the min V_{IL}and max V_{IH} values are based on the respective min and max BV_{IN} values found in Table 3.
- 2. Note that the symbol BV_{IN} represents the input voltage of the supply. It is referenced in Table 3.

3.3.2 TDM/SI AC Timing Specifications

Table 78 provides the TDM/SI input and output AC timing specifications.

Table 78. TDM/SI AC Timing Specifications ¹

| Parameter | Symbol ² | Min | Max | Unit |
|---|---------------------|-----|-----|------|
| TDM/SI outputs—External clock delay | t _{SEKHOV} | 2 | 11 | ns |
| TDM/SI outputs—External clock High Impedance | t _{SEKHOX} | 2 | 10 | ns |
| TDM/SI inputs—External clock input setup time | t _{SEIVKH} | 5 | _ | ns |
| TDM/SI inputs—External clock input hold time | t _{SEIXKH} | 2 | _ | ns |

Notes:

- 1. Output specifications are measured from the 50% level of the rising edge of CLKIN to the 50% level of the signal. Timings are measured at the pin.
- 2. The symbols used for timing specifications follow the pattern of $t_{(first\ two\ letters\ of\ functional\ block)(signal)(state)}$ (reference)(state) for inputs and $t_{(first\ two\ letters\ of\ functional\ block)}$ (reference)(state) for outputs. For example, t_{SEKHOX} symbolizes the TDM/SI outputs external timing (SE) for the time $t_{TDM/SI}$ memory clock reference (K) goes from the high state (H) until outputs (O) are invalid (X).

Figure 60 provides the AC test load for the TDM/SI.

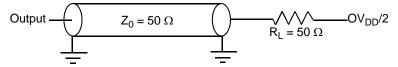
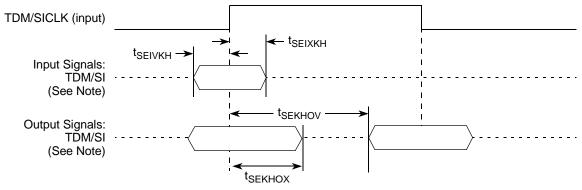


Figure 60. TDM/SI AC Test Load

Figure 61 represents the AC timing from Table 78. Note that although the specifications generally reference the rising edge of the clock, these AC timing diagrams also apply when the falling edge is the active edge. Figure 61 shows the TDM/SI timing with external clock.



Note: The clock edge is selectable on TDM/SI

Figure 61. TDM/SI AC Timing (External Clock) Diagram

3.4 UTOPIA Interface

This section describes the DC and AC electrical specifications for the UTOPIA.

3.4.1 UTOPIA DC Electrical Characteristics

Table 79 provides the DC electrical characteristics for the UTOPIA.

Table 79. UTOPIA DC Electrical Characteristics

For recommended operating conditions, see Table 3.

| Parameter | Symbol | Min | Max | Unit | Notes |
|--|-----------------|-----|-----|------|-------|
| Input high voltage | V _{IH} | 2.0 | _ | V | 1 |
| Input low voltage | V _{IL} | _ | 0.8 | V | 1 |
| Input current (BV _{IN} = 0 V or BV _{IN} = BV _{DD}) | I _{IN} | _ | ±40 | μΑ | 2 |
| Output high voltage (BV _{DD} = min, I _{OH} = -2 mA) | V _{OH} | 2.4 | _ | V | _ |
| Output low voltage (BV _{DD} = min, I _{OH} = 2 mA) | V _{OL} | _ | 0.4 | V | _ |

Note:

- 1. Note that the min V_{IL} and max V_{IH} values are based on the respective min and max BV_{IN} values found in Table 3.
- 2. Note that the symbol BV_{IN} represents the input voltage of the supply. It is referenced in Table 3.

3.4.2 UTOPIA AC Timing Specifications

Table 80 provides the UTOPIA input and output AC timing specifications.

Table 80. UTOPIA AC Timing Specifications¹

| Parameter | Symbol ² | Min | Max | Unit |
|---|---------------------|-----|-----|------|
| UTOPIA/POS outputs—Internal clock delay | t _{UIKHOV} | 0 | 8 | ns |
| UTOPIA/POS outputs—External clock delay | t _{UEKHOV} | 1 | 10 | ns |
| UTOPIA/POS outputs—Internal clock High Impedance | t _{UIKHOX} | 0 | 8 | ns |
| UTOPIA/POS outputs—External clock High Impedance | t _{UEKHOX} | 1 | 10 | ns |
| UTOPIA/POS inputs—Internal clock input setup time | t _{UIIVKH} | 6 | _ | ns |
| UTOPIA/POS inputs—External clock input setup time | t _{UEIVKH} | 4 | _ | ns |
| UTOPIA/POS inputs—Internal clock input Hold time | t _{UIIXKH} | 0 | _ | ns |
| UTOPIA/POS inputs—External clock input hold time | t _{UEIXKH} | 1 | _ | ns |

Notes:

- 1. Output specifications are measured from the 50% level of the rising edge of CLKIN to the 50% level of the signal. Timings are measured at the pin.
- 2. The symbols used for timing specifications follow the pattern of t_{(first two letters of functional block)(signal)(state)} (reference)(state) for inputs and t_(first two letters of functional block)(reference)(state)(signal)(state) for outputs. For example, t_{UIKHOX} symbolizes the UTOPIA/POS outputs internal timing (UI) for the time t_{Utopia} memory clock reference (K) goes from the high state (H) until outputs (O) are invalid (X).

Figure 62 provides the AC test load for the UTOPIA.

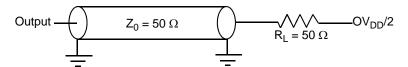


Figure 62. UTOPIA AC Test Load

Figure 63 through Figure 64 represent the AC timing from Table 80. Note that although the specifications generally reference the rising edge of the clock, these AC timing diagrams also apply when the falling edge is the active edge.

Figure 63 shows the UTOPIA timing with external clock.

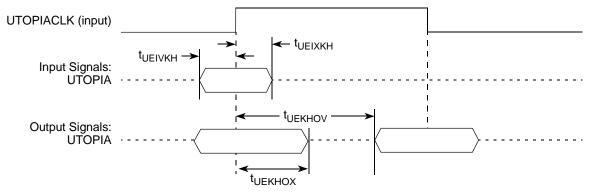


Figure 63. UTOPIA AC Timing (External Clock) Diagram

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Figure 64 shows the UTOPIA timing with internal clock.

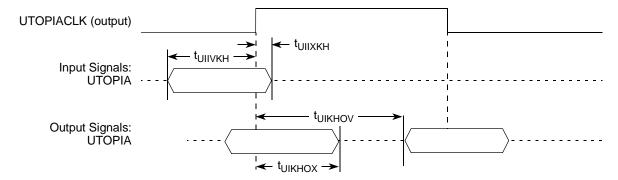


Figure 64. UTOPIA AC Timing (Internal Clock) Diagram

3.5 SPI Interface

This section describes the SPI DC and AC electrical specifications.

3.5.1 SPI DC Electrical Characteristics

Table 81 provides the SPI DC electrical characteristics.

Table 81. SPI DC Electrical Characteristics

For recommended operating conditions, see Table 3

| Parameter | Symbol | Min | Max | Unit | Notes |
|--|-----------------|-----|-----|------|-------|
| Input high voltage | V _{IH} | 2.0 | _ | V | 1 |
| Input low voltage | V _{IL} | _ | 0.8 | V | 1 |
| Input current (OV _{IN} = 0 V or OV _{IN} = OV _{DD}) | I _{IN} | _ | ±40 | μΑ | 2 |
| Output high voltage (OV _{DD} = min, I _{OH} = -2 mA) | V _{OH} | 2.4 | _ | V | _ |
| Output low voltage (OV _{DD} = min, I _{OH} = 2 mA) | V _{OL} | _ | 0.4 | V | _ |

Note:

- 1. The min V_{IL} and max V_{IH} values are based on the respective min and max OV_{IN} values found in Table 3.
- 2. The symbol OV_{IN} represents the input voltage of the supply. It is referenced in Table 3.

3.5.2 SPI AC Timing Specifications

Table 82 and provide the SPI input and output AC timing specifications.

Table 82. SPI AC Timing Specifications

For recommended operating conditions, see Table 3.

| Parameter | Symbol ¹ | Min | Max | Unit | Note |
|--|---------------------|-----|-----|------|------|
| SPI outputs valid—Master mode (internal clock) delay | t _{NIKHOV} | _ | 6 | ns | 2 |
| SPI outputs hold—Master mode (internal clock) delay | t _{NIKHOX} | 0.5 | _ | ns | 2 |
| SPI outputs valid—Slave mode (external clock) delay | t _{NEKHOV} | _ | 9 | ns | 2 |
| SPI outputs hold—Slave mode (external clock) delay | t _{NEKHOX} | 2 | _ | ns | 2 |

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Table 82. SPI AC Timing Specifications (continued)

For recommended operating conditions, see Table 3.

| Parameter | Symbol ¹ | Min | Max | Unit | Note |
|--|---------------------|-----|-----|------|------|
| SPI inputs—Master mode (internal clock) input setup time | t _{NIIVKH} | 4 | _ | ns | _ |
| SPI inputs—Master mode (internal clock) input hold time | t _{NIIXKH} | 0 | _ | ns | _ |
| SPI inputs—Slave mode (external clock) input setup time | t _{NEIVKH} | 4 | _ | ns | _ |
| SPI inputs—Slave mode (external clock) input hold time | t _{NEIXKH} | 2 | _ | ns | _ |

Note:

- The symbols used for timing specifications follow the pattern of t_{(first two letters of functional block)(signal)(state)} (reference)(state) for inputs and t_(first two letters of functional block)(reference)(state)(signal)(state) for outputs. For example, t_{NIKHOX} symbolizes the internal timing (NI) for the time SPICLK clock reference (K) goes to the high state (H) until outputs (O) are invalid (X).
- Output specifications are measured from the 50% level of the rising edge of CLKIN to the 50% level of the signal. Timings are measured at the pin.

Figure 65 provides the AC test load for the SPI.

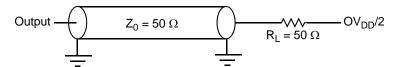
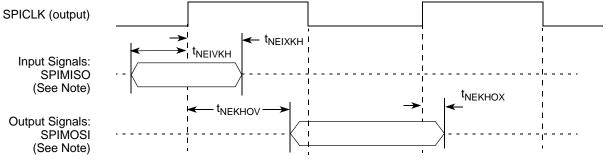


Figure 65. SPI AC Test Load

Figure 66 through Figure 67 represent the AC timing from Table 29. Note that although the specifications generally reference the rising edge of the clock, these AC timing diagrams also apply when the falling edge is the active edge.

Figure 66 shows the SPI timing in slave mode (external clock).



Note: The clock edge is selectable on SPI.

Figure 66. SPI AC Timing in Slave Mode (External Clock) Diagram

Figure 67 shows the SPI timing in master mode (internal clock).

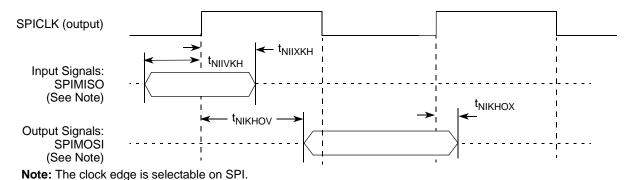


Figure 67. SPI AC Timing in Master Mode (Internal Clock) Diagram

3.6 **GPIO**

This section describes the DC and AC electrical characteristics for the GPIO interface.

3.6.1 GPIO DC Electrical Characteristics

Table 83 provides the DC electrical characteristics for the GPIO interface when operating from a 3.3 V supply.

Table 83. GPIO DC Electrical Characteristics (3.3 V)

For recommended operating conditions, see Table 3

| Parameter | Symbol | Min | Max | Unit | Notes |
|--|-----------------|-----|-----|------|-------|
| Input high voltage | V _{IH} | 2 | _ | V | 1 |
| Input low voltage | V _{IL} | _ | 0.8 | V | 1 |
| Input current (OV _{IN} = 0 V or OV _{IN} = OV _{DD}) | I _{IN} | _ | ±40 | μΑ | 2 |
| Output high voltage (OV _{DD} = min, $I_{OH} = -2 \text{ mA}$) | V _{OH} | 2.4 | _ | V | _ |
| Output low voltage (OV _{DD} = min, I _{OL} = 2 mA) | V _{OL} | _ | 0.4 | V | _ |

Note:

- 1. The min V_{IL} and max V_{IH} values are based on the min and max OV_{IN} respective values found in Table 3.
- 2. The symbol ${\rm OV}_{\rm IN}$ represents the input voltage of the supply. It is referenced in Table 3.

3.6.2 GPIO AC Timing Specifications

Table 84 provides the GPIO input and output AC timing specifications.

Table 84. GPIO Input AC Timing Specifications

For recommended operating conditions, see Table 3

| Parameter | Symbol | Min | Unit | Notes |
|---------------------------------|--------------------|-----|------|-------|
| GPIO inputs—minimum pulse width | t _{PIWID} | 20 | ns | 1 |

Notes:

1. GPIO inputs and outputs are asynchronous to any visible clock. GPIO outputs should be synchronized before use by any external synchronous logic. GPIO inputs are required to be valid for at least t_{PIWID} to ensure proper operation.

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Figure 68 provides the AC test load for the GPIO.

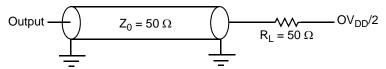


Figure 68. GPIO AC Test Load

4 Hardware Design Considerations

This section provides electrical and thermal design recommendations.

4.1 Clocking

This section describes the PLL configuration. Note that the platform clock is identical to the core complex bus (CCB) clock.

4.1.1 System Clocking

This device includes five PLLs:

- The platform PLL generates the platform clock from the externally supplied SYSCLK input. The frequency ratio
 between the platform and SYSCLK is selected using the platform PLL ratio configuration bits as described in
 Section 4.1.3, "CCB/SYSCLK PLL Ratio."
- The e500 core PLL generates the core clock as a slave to the platform clock. The frequency ratio between the e500 core clock and the platform clock is selected using the e500 PLL ratio configuration bits as described in Section 4.1.4, "e500 Core PLL Ratio."
- There is one PLL for the SerDes block.
- There is one PLL for DDR for asynchronous operation.

4.1.2 Clock Ranges

Table 85 provides the clocking specifications for the processor cores and Table 86 provides the clocking specifications for the memory bus.

Table 85. Processor Core Clocking Specifications

| Parameter | Processor (| Core Frequency | Unit | Notes | |
|-------------------------------|-------------|----------------|------|-------|--|
| T didinatei | Min | Мах | Onic | | |
| e500 core processor frequency | 333 | 800 | MHz | 1 | |

Notes:

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1. **Caution:** The CCB to SYSCLK ratio and e500 core to CCB ratio settings must be chosen such that the resulting SYSCLK frequency, e500 (core) frequency, and CCB frequency do not exceed their respective maximum or minimum operating frequencies. Refer to Section 4.1.3, "CCB/SYSCLK PLL Ratio," and Section 4.1.4, "e500 Core PLL Ratio," for ratio settings.

The DDR memory controller can run in either synchronous or asynchronous mode. When running in synchronous mode, the memory bus is clocked relative to the platform clock frequency. When running in asynchronous mode, the memory bus is clocked with its own dedicated PLL. Table 86 provides the clocking specifications for the memory bus.

Table 86. Memory Bus Clocking Specifications

| Characteristic | Min | Max | Unit | Notes |
|-----------------------------|-----|-----|------|-------|
| DDR2 Memory bus clock speed | 200 | 333 | MHz | 1, 2 |
| DDR3 Memory bus clock speed | 300 | 333 | MHz | 1, 2 |

Notes:

- 1. Caution: The CCB clock to SYSCLK ratio and e500 core to CCB clock ratio settings must be chosen such that the resulting SYSCLK frequency, e500 (core) frequency, and CCB clock frequency do not exceed their respective maximum or minimum operating frequencies. Refer to Section 4.1.3, "CCB/SYSCLK PLL Ratio," Section 4.1.4, "e500 Core PLL Ratio," and Section 4.1.5, "DDR/DDRCLK PLL Ratio," for ratio settings.
- 2. In synchronous mode, the memory bus clock speed is half the platform clock frequency. In asynchronous mode, the memory bus clock speed is dictated by its own PLL. Refer to Section 4.1.5, "DDR/DDRCLK PLL Ratio."

4.1.3 CCB/SYSCLK PLL Ratio

The CCB clock is the clock that drives the e500 core complex bus (CCB) and is also called the platform clock. The frequency of the CCB is set using the following reset signals, as shown in Table 87:

- SYSCLK input signal
- Binary value on LA[28:31] at power up

Note that there is no default for this PLL ratio; these signals must be pulled to the desired values.

Table 87. CCB Clock Ratio

| Binary Value of LA[29:31] Signals | CCB:SYSCLK Ratio |
|-----------------------------------|------------------|
| 000 | 4:1 |
| 001 | 5:1 |
| 010 | 6:1 |
| 011 | Reserved |
| 100 | Reserved |
| 101 | Reserved |
| 110 | Reserved |
| 111 | Reserved |

4.1.4 e500 Core PLL Ratio

Table 88 describes the clock ratio between the e500 core complex bus (CCB) and the e500 core clock. This ratio is determined by the binary value of LBCTL, LALE, and LGPL2 at power up for Core0 and LWE0,UART_SOUT1 and READY_P1 for Core1 as shown in Table 88.

Table 88, e500 Core 0 to CCB Clock Ratio

| Binary Value of LBCTL, LALE, LGPL2 Signals | e500 core: CCB Clock Ratio | Binary Value of LBCTL, LALE, LGPL2 Signals | e500 core: CCB Clock Ratio |
|--|----------------------------|--|----------------------------|
| 000 | Reserved | 100 | 2:1 |
| 001 | Reserved | 101 | 5:2 |
| 010 | 1:1 | 110 | 3:1 |
| 011 | 3:2 | 111 | Reserved |

e500 Core 1 PLL ratio is shown in Table 89

Table 89. e500 Core 1 to CCB Clock Ratio

| Binary Value of LWE0, UART_SOUT1, READY_P1 Signals | e500 core: CCB Clock Ratio | Binary Value of LWE0, UART_SOUT1, READY_P1 Signals | e500 core: CCB Clock Ratio |
|--|----------------------------|--|----------------------------|
| 000 | Reserved | 100 | 2:1 |
| 001 | Reserved | 101 | 5:2 |
| 010 | 1:1 | 110 | 3:1 |
| 011 | 3:2 | 111 | Reserved |

4.1.5 DDR/DDRCLK PLL Ratio

The DDR memory controller complex can be synchronous with, or asynchronous to, the CCB, depending on configuration.

Table 90 describes the clock ratio between the DDR memory controller complex and the DDR/DDRCLK PLL reference clock, DDRCLK, which is not the memory bus clock.

When synchronous mode is selected, the memory buses are clocked at half the CCB clock rate. The default mode of operation is for the DDR data rate for the DDR controller to be equal to the CCB clock rate in synchronous mode, or the resulting DDR PLL rate in asynchronous mode. The DDRCLKDR configuration register in the Global Utilities block allows the DDR controller to be run in a divided down mode where the DDR bus clock is half the speed of the default configuration. Changing these defaults must be completed prior to initialization of the DDR controller.

Table 90. DDR Clock Ratio

| Binary Value of TSEC_1588_CLK_Out, TSEC_1588_PULSE_OUT1, TSEC_1588_PULSE_OUT2 Signals | DDR:DDRCLK Ratio | |
|---|------------------|--|
| 000 | 3:1 | |
| 001 | 4:1 | |

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Table 90. DDR Clock Ratio (continued)

| Binary Value of TSEC_1588_CLK_Out, TSEC_1588_PULSE_OUT1, TSEC_1588_PULSE_OUT2 Signals | DDR:DDRCLK Ratio |
|---|------------------|
| 010 | 6:1 |
| 011 | 8:1 |
| 100 | 10:1 |
| 101 | Reserved |
| 110 | Reserved |
| 111 | Synchronous mode |

4.1.6 QUICC Engine Block to CCB Clock Ratio

The QUICC Engine block works on the same clock as CCB.

4.1.7 Frequency Options

4.1.7.1 SYSCLK to Platform Frequency Options

Table 91 shows the expected frequency values for the platform frequency when using a CCB clock to SYSCLK ratio in comparison to the memory bus clock speed.

Table 91. Frequency Options of SYSCLK with Respect to Memory Bus Speeds

| CCB to SYSCLK Ratio | SYSCLK (MHz) | |
|------------------------|----------------------------------|-----|
| | 66.66 | 100 |
| | Platform /CCB Frequency (MHz) | |
| 4 | 267 | 400 |
| 5 | 333 | |
| 6 | 400 | |

4.1.7.2 Core to CCB Frequency Options

Table 92 shows the expected frequency values for the core frequency when the e500 core clock PLL inputs that program the core PLLs and establish the ratio between the e500 core clocks and the e500 core complex bus (CCB) clock.

Table 92. Frequency Options for e500 Core Frequency

| Core to CCB Ratio | Platform /CCB Frequency (MHz) | | |
|----------------------|----------------------------------|----------|-------|
| | 266 | 333 | 400 |
| | Core I | requency | (MHz) |
| 1:1 | | 333 | 400 |
| 1.5:1 | 400 | 500 | 600 |
| 2:1 | 533 | 666 | 800 |
| 2.5:1 | 666 | | |
| 3:1 | 800 | | |

4.1.7.3 DDRCLK to DDR Controller Operating Frequency Options

Table 93 shows the expected frequency values for the DDR controller operating frequency when using external asynchronous clock.

Table 93. DDRCLK to DDR Controller Frequency

| DDRC to DDRCLK Ratio | DDRCLK (MHz) | | | |
|-------------------------|--------------|--------------|----------|--------|
| | 66.66 | 100 | 133.33 | 166.66 |
| | DDR | Controller F | requency | (MHz) |
| 3 | | | 400 | 500 |
| 4 | | 400 | 533 | 667 |
| 6 | 400 | 600 | | |
| 8 | 533 | | • | |
| 10 | 667 | | | |

4.1.8 Minimum Platform Frequency Requirements for High-speed Interfaces

The "I/O Port Selection" section of the *QorIQ P1021 Integrated Processor Reference Manual* describes various high-speed interface configuration options. Note that the CCB/platform clock frequency must be considered for proper operation of such interfaces as described below.

For proper PCI Express operation, the CCB/platform clock frequency must be greater than:

$$\frac{527 \text{ MHz} \times (\text{PCI Express link width})}{8}$$

See the "Link Width" section of the *QorIQ P1021 Integrated Processor Reference Manual* for PCI Express interface width details. Note that the "PCI Express link width" in the above equation refers to the negotiated link width as the result of PCI Express link training, which may or may not be the same as the link width POR selection.

See the "System PLL Ratio," section of the *QorIQ P1021 Integrated Processor Reference Manual* for details about selecting this ratio.

4.2 Supply Power Default Setting

The processor is capable of supporting multiple power supply levels on its I/O supply. Table 94, Table 95, and Table 96 show the encoding used to select the voltage level for each I/O supply.

Table 94. Default Voltage Level for LV_{DD}

| LV _{DD} VSEL | I/O Voltage Level |
|-----------------------|-------------------|
| 0 | 3.3 V |
| 1 | 2.5 V |

Table 95. Default Voltage Level for BV_{DD}

| BV _{DD} VSEL [0:1] | I/O Voltage Level |
|-----------------------------|-------------------|
| 00 | 3.3 V |
| 01 | 2.5 V |
| 10 | 1.8 V |
| 11 | 3.3 V |

Table 96. Default Voltage Level for CV_{DD}

| CV _{DD} VSEL [0:1] | I/O Voltage Level |
|-----------------------------|-------------------|
| 00 | 3.3 V |
| 01 | 2.5 V |
| 10 | 1.8 V |
| 11 | 3.3 V |

4.3 Power Supply Design and Sequencing

4.3.1 PLL Power Supply Filtering

Each of the PLLs listed above is provided with power through independent power supply pins (AV_{DD}_PLAT, AV_{DD}_CORE, AV_{DD}_DDR, and AV_{DD}_SRDS respectively). The AV_{DD} level should always be equivalent to V_{DD} , and these voltages must be derived directly from V_{DD} through a low frequency filter scheme.

The recommended solution for PLL filtering is to provide independent filter circuits per PLL power supply, as illustrated in Figure 69, one for each of the AV_{DD} pins. By providing independent filters to each PLL the opportunity to cause noise injection from one PLL to the other is reduced.

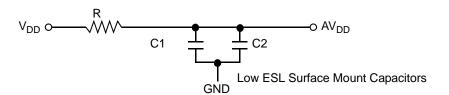
This circuit is intended to filter noise in the PLL's resonant frequency range from a 500-kHz to 10-MHz range. It should be built with surface mount capacitors with minimum effective series inductance (ESL). Consistent with the recommendations of Dr.

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Howard Johnson in *High Speed Digital Design: A Handbook of Black Magic* (Prentice Hall, 1993), multiple small capacitors of equal value are recommended over a single large value capacitor.

Each circuit should be placed as close as possible to the specific AV_{DD} pin being supplied to minimize noise coupled from nearby circuits. It should be possible to route directly from the capacitors to the AV_{DD} pin, which is on the periphery of 689 WB-TePBGA the footprint, without the inductance of vias.

Figure 69 shows the PLL power supply filter circuit.



Notes:

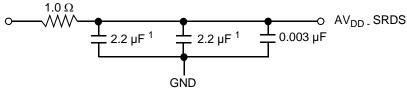
1. $R = 5\Omega \pm 5\%$

2. C1 =10 μ F ± 10%, 603, X5R with ESL <= 0.5nH

 $3.C2 = 1.0 \mu F \pm 10\%$, 402 X5R with ESL <=0.5 nH

Figure 69. P1021 PLL Power Supply Filter Circuit

The AV_{DD}_SRDS signals provides power for the analog portions of the SerDes PLL. To ensure stability of the internal clock, the power supplied to the PLL is filtered using a circuit similar to the one shown in following Figure 70. For maximum effectiveness, the filter circuit is placed as closely as possible to the AV_{DD}_SRDSn balls to ensure it filters out as much noise as possible. The ground connection should be near the AV_{DD}_SRDSn balls. The 0.003- μ F capacitor is closest to the balls, followed by two 2.2- μ F capacitor, and finally the 1 ohm resistor to the board supply plane. The capacitors are connected from AV_{DD}_SRDSn to the ground plane. Use ceramic chip capacitors with the highest possible self-resonant frequency. All traces should be kept short, wide and direct.



1. An 0805 sized capacitor is recommended for system initial bring-up

Figure 70. SerDes PLL Power Supply Filter Circuit

Note the following:

- AV_{DD} should be a filtered version of SV_{DD}.
- Signals on the SerDes interface are fed from the XV_{DD} power plane.
- AV_{DD}_SRDS consumes less than 40 mW; SV_{DD} + AV_{DD}_SRDS consumes less than 750 mW.

4.4 Decoupling Recommendations

Due to large address and data buses, and high operating frequencies, the device can generate transient power surges and high frequency noise in its power supply, especially while driving large capacitive loads. This noise must be prevented from reaching other components in the processor's system, and the device itself requires a clean, tightly regulated source of power. Therefore, it is recommended that the system designer place at least one decoupling capacitor at each V_{DD} , BV_{DD} , OV_{DD} , OV_{DD} , OV_{DD} , OV_{DD} , and OV_{DD} , OV_{DD} , and $OV_$

These capacitors should have a value of 0.01 or $0.1 \mu F$. Only ceramic SMT (surface mount technology) capacitors should be used to minimize lead inductance, preferably 0402 or 0603 sizes.

In addition, it is recommended that there be several bulk storage capacitors distributed around the PCB, feeding the V_{DD} , BV_{DD} , OV_{DD} , CV_{DD} , GV_{DD} , and LV_{DD} planes, to enable quick recharging of the smaller chip capacitors. These bulk capacitors should have a low ESR (equivalent series resistance) rating to ensure the quick response time necessary. They should also be connected to the power and ground planes through two vias to minimize inductance. Suggested bulk capacitors—100–330 μ F (AVX TPS tantalum or Sanyo OSCON).

4.5 SerDes Block Power Supply Decoupling Recommendations

The SerDes block requires a clean, tightly regulated source of power (SV_{DD} and XV_{DD}) to ensure low jitter on transmit and reliable recovery of data in the receiver. An appropriate decoupling scheme is outlined below.

Only surface mount technology (SMT) capacitors should be used to minimize inductance. Connections from all capacitors to power and ground should be done with multiple vias to further reduce inductance.

- First, the board should have at least 10 × 10-nF SMT ceramic chip capacitors as close as possible to the supply balls
 of the device. Where the board has blind vias, these capacitors should be placed directly below the chip supply and
 ground connections. Where the board does not have blind vias, these capacitors should be placed in a ring around the
 device as close to the supply and ground connections as possible.
- Second, there should be a 1-μF ceramic chip capacitor on each side of the device. This should be done for all SerDes supplies.
- Third, between the device and any SerDes voltage regulator there should be a 10-μF, low equivalent series resistance (ESR) SMT tantalum chip capacitor and a 100-μF, low ESR SMT tantalum chip capacitor. This should be done for all SerDes supplies.

4.6 Connection Recommendations

To ensure reliable operation, it is highly recommended that unused inputs be connected to an appropriate signal level. All unused active low inputs should be tied to V_{DD} , BV_{DD} , CV_{DD} , CV_{DD} , CV_{DD} , CV_{DD} , CV_{DD} , and CV_{DD} as required. All unused active high inputs should be connected to GND. All NC (no-connect) signals must remain unconnected. Power and ground connections must be made to all external CV_{DD} , CV_{DD} , CV_{DD} , CV_{DD} , CV_{DD} , CV_{DD} , and CV_{DD} and CV_{DD} pins of the device.

4.7 Pull-Up and Pull-Down Resistor Requirements

The device requires pull-up resistors on open drain type pins including I^2C pins (1 k Ω is recommended) and MPIC interrupt pins (2–10 k Ω is recommended).

Correct operation of the JTAG interface requires configuration of a group of system control pins as demonstrated in Figure 73. Care must be taken to ensure that these pins are maintained at a valid deasserted state under normal operating conditions as most have asynchronous behavior and spurious assertion will give unpredictable results.

The following pins must NOT be pulled down during power-on reset: HRESET_REQ, TRIG_OUT/READY/QUIESCE, MSRCID[1:3], ASLEEP. The DMA1_DACK_B00, TEST_SEL_B, SCAN_MODE_B and USB_STP pins must be set to a proper state during POR configuration. Please refer to the pinlist table. See Table 97 for more details.

NOTE

External pull-ups should connect to the appropriate supply rail voltage for each specific signal as per Table 1.

Table 97. Test Mode Select

| DMA1_DACK_B00 | USB_STP | TEST_SEL_B | SCAN_MODE_B |
|---------------|---------|------------|-------------|
| 1 | 0 | 1 | 1 |

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4.8 Output Buffer DC Impedance

The processor's drivers are characterized over process, voltage, and temperature. For all buses, the driver is a push-pull single-ended driver type (open drain for I²C).

To measure Z_0 for the single-ended drivers, an external resistor is connected from the chip pad to OV_{DD} (OV_{DD} in this section refers to IO power supply) or GND. Then, the value of each resistor is varied until the pad voltage is $OV_{DD}/2$ (see Figure 71). The output impedance is the average of two components, the resistances of the pull-up and pull-down devices. When data is held high, SW1 is closed (SW2 is open) and R_P is trimmed until the voltage at the pad equals $OV_{DD}/2$. R_P then becomes the resistance of the pull-up devices. R_P and R_N are designed to be close to each other in value. Then, $Z_0 = (R_P + R_N) \div 2$.

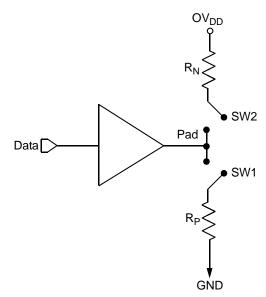


Figure 71. Driver Impedance Measurement

Table 98 summarizes the signal impedance targets. The driver impedances are targeted at minimum V_{DD}, nominal OV_{DD}, 90°C.

Enhanced Local Bus, Ethernet, DUART, Control, **Impedance** DDR DRAM **Symbol** Unit **Configuration, Power Management** Z_0 R_N 43 20 Ω R_P 43 20 Z_0 Ω

Table 98. Impedance Characteristics

Note: Nominal supply voltages. See Table 3

4.9 Configuration Pin Muxing

The processor provides the user with power-on configuration options that can be set through the use of external pull-up or pull-down resistors of $4.7~k\Omega$ on certain output pins (see customer visible configuration pins). These pins are generally used as output only pins in normal operation.

While \overline{HRESET} is asserted, however, these pins are treated as inputs. The value presented on these pins while \overline{HRESET} is asserted, is latched when \overline{HRESET} deasserts, at which time the input receiver is disabled and the I/O circuit takes on its normal function. Most of these sampled configuration pins are equipped with an on-chip gated resistor of approximately $20~k\Omega$. This value should permit the 4.7- $k\Omega$ resistor to pull the configuration pin to a valid logic low level. The pull-up resistor is enabled only during \overline{HRESET} (and for platform /system clocks after \overline{HRESET} deassertion to ensure capture of the reset value). When the input receiver is disabled the pull-up is also, thus allowing functional operation of the pin as an output with minimal signal quality or delay disruption. The default value for all configuration bits treated this way has been encoded such that a high voltage

level puts the device into the default state and external resistors are needed only when non-default settings are required by the user.

Careful board layout with stubless connections to these pull-down resistors coupled with the large value of the pull-down resistor should minimize the disruption of signal quality or speed for output pins thus configured.

The platform PLL ratio and e500 PLL ratio configuration pins are not equipped with these default pull-up devices.

4.10 JTAG Configuration Signals

Boundary-scan testing is enabled through the JTAG interface signals. The \overline{TRST} signal is optional in the IEEE 1149.1 specification, but is provided on all processors that implement the PowerPC architecture. The device requires \overline{TRST} to be asserted during reset conditions to ensure the JTAG boundary logic does not interfere with normal chip operation. While it is possible to force the TAP controller to the reset state using only the TCK and TMS signals, generally systems will assert \overline{TRST} during the power-on reset flow. Simply tying \overline{TRST} to \overline{HRESET} is not practical because the JTAG interface is also used for accessing the common on-chip processor (COP) function.

The COP function of these processors allow a remote computer system (typically, a PC with dedicated hardware and debugging software) to access and control the internal operations of the processor. The COP interface connects primarily through the JTAG port of the processor, with some additional status monitoring signals. The COP port requires the ability to independently assert HRESET or TRST in order to fully control the processor. If the target system has independent reset sources, such as voltage monitors, watchdog timers, power supply failures, or push-button switches, then the COP reset signals must be merged into these signals with logic.

The arrangement shown in Figure 73 allows the COP port to independently assert HRESET or TRST, while ensuring that the target can drive HRESET as well.

The COP interface has a standard header, shown in Figure 73 for connection to the target system, and is based on the 0.025" square-post, 0.100" centered header assembly (often called a Berg header). The connector typically has pin 14 removed as a connector key.

The COP header adds many benefits such as breakpoints, watchpoints, register and memory examination/modification, and other standard debugger features. An inexpensive option can be to leave the COP header unpopulated until needed.

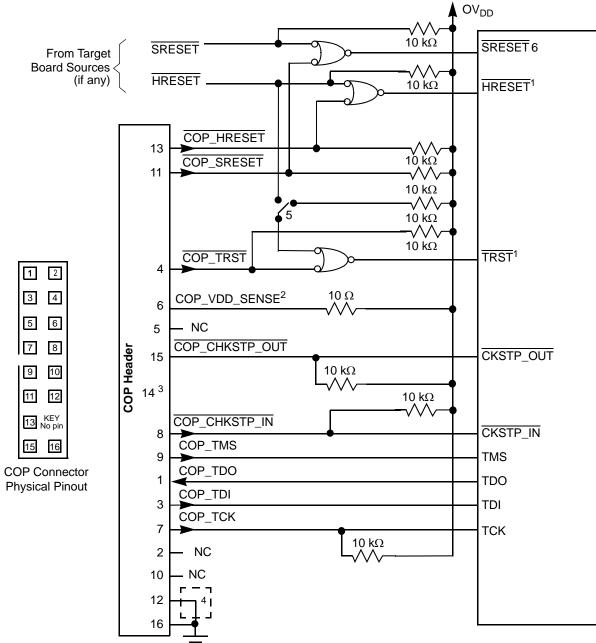
There is no standardized way to number the COP header; consequently, many different pin numbers have been observed from emulator vendors. Some are numbered top-to-bottom then left-to-right, while others use left-to-right then top-to-bottom, while still others number the pins counter clockwise from pin 1 (as with an IC). Regardless of the numbering, the signal placement recommended in Figure 73 is common to all known emulators.

4.10.1 Termination of Unused Signals

If the JTAG interface and COP header will not be used, Freescale recommends the following connections:

- \overline{TRST} should be tied to \overline{HRESET} through a 0 k Ω isolation resistor so that it is asserted when the system reset signal (\overline{HRESET}) is asserted, ensuring that the JTAG scan chain is initialized during the power-on reset flow. Freescale recommends that the COP header be designed into the system as shown in Figure 73. If this is not possible, the isolation resistor will allow future access to \overline{TRST} in case a JTAG interface may need to be wired onto the system in future debug situations.
- Tie TCK to OV_{DD} through a 10 k Ω resistor. This will prevent TCK from changing state and reading incorrect data into the device.
- No connection is required for TDI, TMS, or TDO.

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Notes:

- 1. The COP port and target board should be able to independently assert HRESET and TRST to the processor in order to fully control the processor as shown here.
- 2. Populate this with a 10 Ω resistor for short-circuit/current-limiting protection.
- 3. The KEY location (pin 14) is not physically present on the COP header.
- 4. Although pin 12 is defined as a No-Connect, some debug tools may use pin 12 as an additional GND pin for improved signal integrity.
- 5. This switch is included as a precaution for BSDL testing. The switch should be open during BSDL testing to avoid accidentally <u>asserting</u> the TRST line. If BSDL testing is not being performed, this switch should be closed or removed. 6. Asserting SRESET causes a machine check interrupt to the e500 core.

Figure 72. JTAG Interface Connection

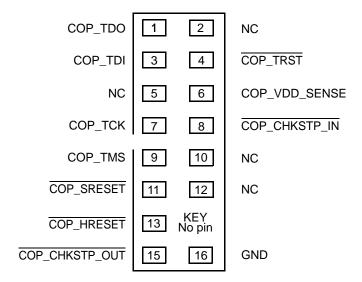


Figure 73. COP Connector Physical Pinout

4.11 Guidelines for High-Speed Interface Termination

If the high-speed SerDes interface is not used at all, the unused pin should be terminated as described in this section. However, the SerDes must always have power applied to its supply pins.

The following pins must be left unconnected (float):

- SD_TX[3:0]
- SD_TX[3:0]

The following pins must be connected to GND:

- SD_RX[3:0]
- SD_RX[3:0]
- SD_REF_CLK
- SD_REF_CLK

4.12 Thermal

This section describes the thermal specifications.

4.12.1 Thermal Characteristics

Table 99 provides the package thermal characteristics.

Table 99. Package Thermal Characteristics

| Parameter | JEDEC Board | Symbol | Value | Unit | Notes |
|--|-------------------------|-----------------|-------|------|-------|
| Junction-to-ambient Natural Convection | Single layer board (1s) | $R_{\theta JA}$ | 23 | °C/W | 1, 2 |
| Junction-to-ambient Natural Convection | Four layer board (2s2p) | $R_{\theta JA}$ | 17 | °C/W | 1, 2, |
| Junction-to-ambient (at 200 ft/min) | Single layer board (1s) | $R_{\theta JA}$ | 18 | °C/W | 1, 2 |
| Junction-to-ambient (at 200 ft/min) | Four layer board (2s2p) | $R_{\theta JA}$ | 14 | °C/W | 1, 2 |
| Junction-to-board thermal | _ | $R_{\theta JB}$ | 9 | °C/W | 3 |

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Table 99. Package Thermal Characteristics

| Parameter | JEDEC Board | Symbol | Value | Unit | Notes |
|--------------------------|-------------|-----------------|-------|------|-------|
| Junction-to-case thermal | _ | $R_{\theta JC}$ | 7 | °C/W | 4 |

Notes

- Junction temperature is a function of die size, on-chip power dissipation, package thermal resistance, mounting site (board) temperature, ambient temperature, air flow, power dissipation of other components on the board, and board thermal resistance.
- 2. Per JEDEC JESD51-2 and JESD51-6 with the board (JESD51-9) horizontal.
- 3. Thermal resistance between the die and the printed-circuit board per JEDEC JESD51-8. Board temperature is measured on the top surface of the board near the package.
- 4. Junction-to-case at the top of the package determined using MIL-STD 883 Method 1012.1. The cold plate temperature is used for the case temperature. Reported value includes the thermal resistance of the interface layer.

Table 100 provides the thermal resistance with heat sink in open flow.

Table 100. Thermal Resistance with Heat Sink in Open Flow

| Heat Sink with Thermal Grease | Air Flow | Thermal Resistance (°C/W) |
|-----------------------------------|--------------------|---------------------------|
| Wakefield 53 × 53 × 25 mm Pin Fin | Natural Convection | 10.3 |
| | 0.5 m/s | 9.0 |
| | 1 m/s | 8.2 |
| | 2 m/s | 7.7 |
| | 4 m/s | 7.4 |
| Aavid 35 x 31 x 23 mm Pin Fin | Natural Convection | 12.5 |
| | 0.5 m/s | 9.9 |
| | 1 m/s | 9.1 |
| | 2 m/s | 8.6 |
| | 4 m/s | 8.2 |
| Aavid 30 × 30 × 9.4 mm Pin Fin | Natural Convection | 14.1 |
| | 0.5 m/s | 12.0 |
| | 1 m/s | 10.7 |
| | 2 m/s | 9.6 |
| | 4 m/s | 8.9 |
| Aavid 43 × 41 × 16.5 mm Pin Fin | Natural Convection | 12.4 |
| | 0.5 m/s | 10.3 |
| | 1 m/s | 9.1 |
| | 2 m/s | 8.3 |
| | 4 m/s | 7.8 |

Simulations with heat sinks were done with the package mounted on the 2s2p thermal test board. A power value of 4.5 W was used for the heat sink simulations. The thermal interface material was a typical thermal grease such as Dow Corning 340 or Wakefield 120 grease.

Simulation Details:

The 1/8 symmetry model included the following package parameters:

Four layer Substrate

Substrate solder mask thickness: 0.030 mm

Substrate metal thicknesses: 0.030mm, 0.064mm, 0.064mm, 0.030 mm

Substrate core thickness: 0.115mm, 0.100mm, 0.115 mm Core via I.D: 0.118 mm, Core via plating 0.016 mm

Flag: trace style with ground balls under the die connected to the flag

Die Attach: 0.033 mm conductive die attach, k = 1.5 W/m K Mold Compound: generic mold compound, k = 0.9 W/m K

4.12.1.1 Estimation of Junction Temperature with Junction-to-Ambient Thermal Resistance

An estimation of the chip junction temperature, TJ, can be obtained from the equation:

$$T_{J} = T_{A} + (R_{\theta JA} \times P_{D})$$

where:

 T_I = junction temperature (°C)

 T_A = ambient temperature for the package (°C)

 R_{qJA} = junction to ambient thermal resistance (°C/W)

PD = power dissipation in the package (W) The junction to ambient thermal resistance is an industry standard value that provides a quick and easy estimation of thermal performance. As a general statement, the value obtained on a single layer board is appropriate for a tightly packed printed circuit board. The value obtained on the board with the internal planes is usually appropriate if the board has low power dissipation and the components are well separated. Test cases have demonstrated that errors of a factor of two (in the quantity TJ - TA) are possible.

4.12.1.2 Heat Sinks and Junction-to-Case Thermal Resistance

In application environments, a heat sink is frequently required to provide the necessary thermal management of the device. When a heat sink is used, the thermal resistance is frequently approximated as the sum of a junction to case thermal resistance and a case to ambient thermal resistance:

$$R_{\theta JA} = R_{\theta JC} + R_{\theta CA}$$

where:

 $R_{\theta JA}$ = junction to ambient thermal resistance (°C/W)

 $R_{\theta JC}$ = junction to case thermal resistance (°C/W)

 $R_{\theta CA}$ = case to ambient thermal resistance (°C/W)

For the processor in the WB-TEPBGA package, a substantial portion of the heat flow is to the board. Not all the heat flows to the heat sink. As a result, it is inappropriate to size a heat sink based on this equation. The heat sink choice is determined by the application environment (temperature, air flow, adjacent component power dissipation) and the physical space available. Because there is not a standard application environment, a standard heat sink is not required. To illustrate the thermal

Hardware Design Considerations

performance of the devices with heat sinks, the thermal performance has been simulated with a few commercially available heat sinks. Table 100 provides the thermal resistance with a heat sink in an open flow

Table 101. Thermal Resistance with Heat Sink in Open Flow

| Heat Sink with Thermal Grease | Air Flow | Thermal Resistance (°C/W) |
|---|--------------------|---------------------------|
| 23 × 23 × 10mm Extruded cross cut pin fin, Base is | Natural Convection | 16.9 |
| 1.5mm thick AAVID374024B60023G | 0.5 m/s | 13.8 |
| | 1 m/s | 12.1 |
| | 2 m/s | 10.6 |
| 38 × 38 × 16.5 mm Extruded cross cut pin fin, Base is 5 | Natural Convection | 13.8 |
| mm thick AAVID2330B | 0.5 m/s | 11.5 |
| | 1 m/s | 10.7 |
| | 2 m/s | 9.5 |
| 53 x 54 x 25 mm Extruded cross cut pin fin Base is 3.7 | Natural Convection | 13.0 |
| mm thick Wakefield 698100AB | 0.5 m/s | 10.4 |
| | 1 m/s | 9.3 |
| | 2 m/s | 8.8 |

The thermal resistances with heat sinks were simulated in an open flow environment per JEDEC JESD51-6 with the part on a 2s2p board as specified in JESD51-9. The thermal interface material was a typical thermal grease such as Dow Corning 340 or Wakefield 120 grease.

4.12.2 Recommended Thermal Model

Information about Flotherm models of the package or thermal data not available in this document can be obtained from your local Freescale sales office.

4.12.3 Thermal Management Information

This section provides thermal management information for the flip chip plastic ball grid array (WB-TePBGA) package for air-cooled applications. Proper thermal control design is primarily dependent on the system-level design—the heat sink, airflow, and thermal interface material. The processor implements several features designed to assist with thermal management, including the temperature diode. The temperature diode allows an external device to monitor the die temperature in order to detect excessive temperature conditions and alert the system.

The recommended attachment method to the heat sink is illustrated in Figure 74. The heat sink should be attached to the printed-circuit board with the spring force centered over the die. This spring force should not exceed 10 pounds force (45 Newton).

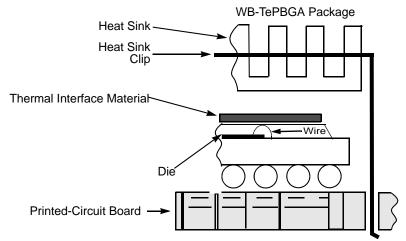


Figure 74. Package Exploded Cross-Sectional View with Several Heat Sink Options

The system board designer can choose between several types of heat sinks to place on the device. Ultimately, the final selection of an appropriate heat sink depends on factors such as thermal performance at a given air velocity, spatial volume, mass, attachment method, assembly, and cost.

The system board designer can choose between several types of thermal interface. There are several commercially-available thermal interfaces provided by the following vendors:

Aavid Thermalloy

Internet: www.aavidthermalloy.com

Alpha Novatech

Internet: www.alphanovatech.com

Wakefield Engineering

Internet: www.wakefield.com

Chomerics, Inc. 781-935-4850

77 Dragon Ct.

Woburn, MA 01801

Internet: www.chomerics.com

Dow-Corning Corporation 800-248-2481

Corporate Center P.O.Box 999

Midland, MI 48686-0997 Internet: www.dow.com

Shin-Etsu MicroSi, Inc. 888-642-7674

10028 S. 51st St. Phoenix, AZ 85044

Internet: www.microsi.com

The Bergquist Company 800-347-4572

18930 West 78th St. Chanhassen, MN 55317

Internet: www.bergquistcompany.com

Package Information

Thermagon Inc. 4707 Detroit Ave. Cleveland, OH 44102

Internet: www.thermagon.com

888-246-9050

4.12.3.1 Heat Sink Attachment

When attaching heat sinks to these devices, an interface material is required. The best method is to use thermal grease and a spring clip. The spring clip should connect to the printed circuit board, either to the board itself, to hooks soldered to the board, or to a plastic stiffener. Avoid attachment forces which would lift the edge of the package or peel the package from the board. Such peeling forces reduce the solder joint lifetime of the package. Recommended maximum force on the top of the package is 10 lb force (45 Newtons). If an adhesive attachment is planned, the adhesive should be intended for attachment to painted or plastic surfaces and its performance verified under the application requirements.

4.12.3.2 Experimental Determination of the Junction Temperature with a Heat Sink

When heat sink is used, the junction temperature is determined from a thermocouple inserted between the case of the package and the heat sink. A clearance slot or hole is normally required in the heat sink. Minimizing the size of the clearance is important to minimize the change in thermal performance caused by removing part of the thermal interface to the heat sink temperature and then back calculate the case temperature using a separate measurement of the thermal resistance of the interface. From this case temperature, the junction temperature is determined from the junction to case thermal resistance.

$$T_J = T_C + (R_{\Theta IC} \times P_D)$$

Where

 T_c is the case temperature of the package

 $R_{\theta IC}$ is the junction-to-case thermal resistance

P_D is the power dissipation

5 Package Information

This section provides the package parameters and ordering information.

5.1 Package Parameters for the P1021 WB-TePBGA

The package parameters are provided in the following list. The package type is $31 \text{ mm} \times 31 \text{ mm}$, 689 plastic ball grid array (WB-TePBGA).

Package outline $31 \text{ mm} \times 31 \text{ mm}$

Interconnects 689
Pitch 1.00 mm

Module height (typical) 2.0 mm to 2.46 mm (Maximum)

Solder Balls 3.5% Ag, 96.5% Sn

Ball diameter (typical) 0.60 mm

Figure 75 shows the P1021 package.

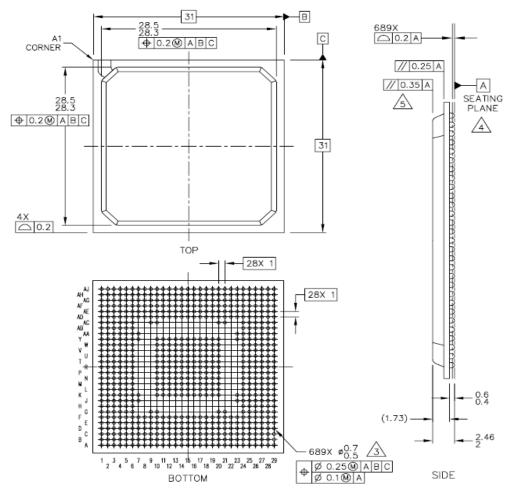


Figure 75. P1021 Package

NOTES for Figure 75:

- 1. All dimensions are in millimeters.
- 2. Dimensioning and tolerancing per ASME Y14. 5M-1994.
- 3. Maximum solder ball diameter measured parallel to Datum A.
- 4. Datum A, the seating plane, is determined by the spherical crowns of the solder balls.
- 5. Parallelism measurement shall exclude any effect of mark on top surface of package.

1

5.2 **Ordering Information**

02 or 01

Core

Table 102 provides the Freescale part numbering nomenclature. Each part number also contains a revision code which refers to the die mask revision number.

Table 102. Part Numbering Nomenclature

n

dd

| Generat ion | Platform | Number of Cores | Deriva tive | Qual Status | Temperature Range | Encryptio n | Package Type | CPU/CCB/DDR Frequency (MHz) | Die Revisio n |
|----------------|----------|--------------------|----------------|---------------|----------------------|----------------|-----------------|--------------------------------|---------------------|
| P = | 1 | 01 = Single | 0-9 | P = | S = Std Temp | E = SEC | 2 = | HF = 800/400/667 | A = 1.0 |
| 45 nm | | Core | | Prototype | X = Ext. Temp | Present | TePBGA | FF = 667/333/667 | B = 1.1 |
| | | 02 = Dual | | N = Qual'd to | | N = SEC | Pbfree | DF = 533/267/667 | |

Not

Present

Notes:

Ρ

1. See Section 5, "Package Information," for more information on available package types.

q

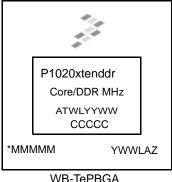
Industral Tier

S = Special

- 2. Processor core frequencies supported by parts addressed by this specification only. Not all parts described in this specification support all core frequencies. Additionally, parts addressed by part number specifications may support other maximum core
- 3) The QUICC Engine RISC clock speed is equal to the CCB/Platform speed.

1

Parts are marked as the example shown in Figure 76.



Notes:

P1020xtenddr is the orderable part number

*MMMMM is the mask number

YWWLAZ is the assembly traceability code.

CCCCC is the country code

ATWLYYWW is the standard assembly, test, year, and work week codes.

Figure 76. Part Marking for WB-TePBGA Device

Product Documentation 6

The following documents are required for a complete description of the device and are needed to design properly with the part:

- QorIQ P1021 Integrated Processor Reference Manual (document number P1021RM)
- e500 PowerPC Core Reference Manual (E500CORERM)

P1021 QorIQ Integrated Processor Hardware Specifications, Rev. N

7 Revision History

Table 103 provides a revision history.

Table 103. Document Revision History

| Rev. Number | Date | Substantive Change(s) |
|----------------|---------|---|
| N | 03/2011 | Changed SGMII IO power numbers from 0.96 to 0.096 in Table 9 Removed row of core frequency 533Mhz and CCB of 333Mhz in Table 8 In formula given in Section 4.1.8, "Minimum Platform Frequency Requirements for High-speed Interfaces", replaced 500 with 527 Removed note 5 from rows of LGLP0 and LGPL1 in Table 1 Added Section 3.6, "GPIO" Changed minimum core frequency to 333 in Table 85 Replaced "Thermal" with "Typical" in Table 8 Re-worded "CAUTION" in Section 2.7.2, "SYSCLK and Spread Spectrum Sources" to include DDR clock |

Revision History

| Rev. Number | Date | Substantive Change(s) |
|----------------|---------|--|
| M | 02/2011 | On page 1, modified "Four SerDes to 3.125 GHz multiplexed across controllers" to "Four SerDes upto 2.5 GHz/lane" in page 1 Updated SEC features in page 1. Added note 4 for IIC signals in Table 1. Removed notes 6, 7, 13, 14, 16, 22, 24, 30, and 35 from Table 1. Added note 36 in Table 1. Added note 2 from all QUICC Engine block pins. Added note 2 from all QUICC Engine block pins. Added note 2 from all QUICC Engine block pins. Added note 27 to LA[20:22] in Table 1. Removed note 9 from LA28 in Table 1. In figure note of Figure 7, updated MCLK with MCK. Moved reset initialization information to Section 2.4, "RESET Initialization." Added two rows for "Minimum assertion time of TRESET simultaneous to HRESET assertion" and "Maximum rise/fall time of HRESET" in Table 5. Added note 1, 2, and 3 in Table 5. Moved 1st column to 4th column in Table 8. Changed the name of Table 10 from "SYSCLK DC Electrical Characteristics (OVDD = 3.3 V ± 165 mV)" to "SYSCLK DC Electrical Characteristics (OVDD = 3.3 V ± 165 mV)" to "DDRCLK DC Electrical Characteristics" Updated min of VIH from 1.7 to 2 V, max value if VIL from 0.9 to 0.8 V, min value of VOH from 2.1 to 2.4, max value of VOL from 0.5 to 0.4 in Table 32, Table 43, and Table 69. Added notes in figure Figure 69. Updated Table 98. Changed min freq of core to 533 in page 1, Table 85 and Table 92. Added notes in figure Figure 69. Updated Section 2.7.3, "Real Time Clock Timing." Updated Section 2.7.3, "Real Time Clock Timing." Updated Section 2.7.3, "Real Time Clock Timing." Added 399.96 and 39.996 as minimum value of tMTX for 10Mbps and 100Mbps respectively in Table 33. Added 400.04 and 40.004 as maximum value of tMTX for 10Mbps and 100Mbps respectively in Table 33. Added 400.04 and 40.004 as maximum value of tMTX for 10Mbps and 100Mbps respectively in Table 33. Added 400.04 and 40.06 as maximum value of tMTX for 10Mbps and 100Mbps respectively in Table 33. Added 400.04 and 40.06 as maximum value of tMTX fo |

| Rev. Number | Date | Substantive Change(s) |
|----------------|---------|---|
| M, cont. | 02/2011 | Changed pintype of CFG_IO_PORTS3 and CFG_DRAM_TYPE as input in Table 1. Added note 4 for CKSTP_OUT and IRQ_OUT in Table 1. Removed notes 9 and 27 from TRIG_IN in Table 1. Updated note 27 in Table 1. Updated Table 1 so as to show all NC pins as type NC and remove notes from NC pin. Updated MSRCID[1:4] to MSRCID[1:3] in note 19 of Table 1. Removed note 27 from MSRCID00 in Table 1. Removed BVDD = 2.5 V and 1.8 V from Table 4, Table 55, and Section 2.13.1, "Enhanced Local Bus DC Electrical Characteristics." Removed GPIO from Table 2 and Table 4. Added note 6 to Table 50. Changed min of VIH, max value if VIL, min value of VOH, and max value of VOL in Table 69. Updated the list of PLLs in Section 4.1.1, "System Clocking." Updated range of \(\frac{1}{MTKHIDX} \) in Table 70. Added note "The frequency of RX_CLK should not exceed frequency of TX_CLK/GTX_CLK125 by more than 300ppm" in Table 71, Table 34 and Table 38. Added Section 3.5, "SPI Interface."Section 3.4, "UTOPIA Interface," and Section 3.1, "Ethernet Interface Updated Watts consumed in note #3 below Figure 70. Updated Table 5. Added Section 2.6.1, "I/O DC Power Supply Recommendation." Added Section 2.6.1, "I/O DC Power Supply Recommendation." Added "Steady state" in conditions column of "Frequency range" in Table 51. Updated VOH and VOL in Table 17. Removed 367/333/633 ("FD") part number option from Table 102. Modified "DF = 533/333/3667" to "DF = 533/267/667" in Table 102. Added the line "In RMII mode, the REF_CLK is fed to TSECn_TX_CLK" to Section 2.11.2, "RMII AC Timing Specifications." |
| | | Replaced all TSECn_RX_CLK with TSECn_TX_CLK in Section 2.11.2, "RMII AC Timing Specifications." Updated note 2 of Table 85. Added MII, RMII to feature list of eTSEC in Page 1. Added a note stating "External pull-ups should connect to the appropriate supply rail voltage for each specific signal as per Table 1 to Section 4.7, "Pull-Up and Pull-Down Resistor Requirements." |
| L | 10/2010 | Updated Package Numbering Nomenclature Table 102 Updated the Thermal Characteristic Section 4.12, "Thermal" Replaced DDR3 DC Electrical Spec with DDR2 DC Electrical Spec Table 17 |
| К | 9/2010 | Swapped AV _{DD} _CORE0 and AV _{DD} _CORE1 to F16 and F15 in Table 1as this pins are swapped in silicon. Minor edit on footnotes of Table 1 Updated DDR Spec Table 19 and Table 21 Updated Package Numbering Nomenclature Table 102 Removed DDR2 DC electrical spec Added DDR3 DC electrical spec |

Revision History

| Rev. Number | Date | Substantive Change(s) |
|----------------|---------|--|
| J | 6/2010 | Added Footnotes to pins Changed R&C values of Core PLL filter circuit Removed DDR3 DC Electrical spec Removed t _{NIKHOX} and t _{NIKHOV} spec from eSPI as it is not required with new feature Hold adjust Removed eLBC PLL enabled mode AC spec |
| Н | 5/2010 | Added TEST_SEL_B and SCAN_MODE_B pins in Table 97, "Test Mode Select" Updated eLBC spec to match standard C45 spec Added DC and AC Spec for MII and RMII Removed qq parameter from Table 95, "Part Numbering Nomenclature" |
| G | 3/2010 | Changed SYSCLK min to 64MHz from 66.7Mhz Changed all 0.95V Spec to 1.0V Added table for e500 core1 PLL ratio POR configuration bits Added USB DC Electrical Specification for 2.5V and 1.8V Added eSPI DC Electrical Specification for 2.5V and 1.8V Changed RGMII T _{SKRGT_RX} from 2.8ns to 2.6ns Added Part Ordering Information table |
| F | 10/2009 | Modified Table 5 HREST Min parameter Modified Table 71 Synchronous UART parameter t _{HIIVKH} Modified Table 57 eSDHC parameter t _{SFSIVKH} Remove eSPI AC Spec Note 3, As SPCOM[RxDelay] bit is removed. Added Table 15 max PLL Lock Time Changed the conditional texting of partnumber P1011202112 in order to generate separate document for single core products. |

| Rev. Number | Date | Substantive Change(s) |
|----------------|--------|--|
| E | 5/2009 | Added Section 4.1.7.2, "Core to CCB Frequency Options" and Section 4.1.7.3, "DDRCLK to DDR Controller Operating Frequency Options" Modified Table 91 to remove option of 33MHz In Table 90, marked options 110 as reserved. In Table 88, marked options 000, 001, & 111 as reserved. In Table 85, marked options 100 & 101 as reserved. Removed min & max values of t_{RMR} and typical value of t_{RMRH} in Table 72 and Table 73 Added min & max values of t_{MTX} in Table 70 and Table 71 Removed the row of t_{I2CR} and changed all the notes of Table 63 Modified all the notes in Table 61 Added Section 2.15.1, "PIC DC Electrical Characteristics", Section 2.15.2, "PIC AC Timing Specifications", and Section 2.16.1, "JTAG DC Electrical Characteristics" Changed all the values in Table 57 Removed min value of V_{IL}, max value for V_{IH} and changed value of V_{QH} & V_{QL} in Table 56, Table 62, Table 69, Table 74, Table 77 and Table 79 Modified Figure 34 and Figure 33 and removed figure titled as "Enhanced Local Bus Signals, GPCM/UPM Signals for LCRR[CLKDIV] = 4 (PLL Bypass Mode)" Removed min value of V_{IL}, max value for V_{IH} and changed value of V_{QH} & V_{QL} in Table 52 Changed notes of Table 50 Removed min value of V_{IL}, max value for V_{IH} and changed value of V_{QH} & V_{QL} in Table 41 Rewrote Section 2.9, "Ethernet: Enhanced Three-Speed Ethernet (eTSEC)," Section 2.18, "High-Speed Serial Interfaces (HSSI)," and Section 2.19, "PCI Express." Removed min value of V_{IL}, max value for V_{IH} and changed value of V_{QH} & V_{QL} in Table 30 Modified Table 14 Added two rows for t_{NIKHOX2} and t_{NIKHOV2} inTable 29 Added a row each for t_{NIKHOX2} and t_{NIKHOV2} inTable 29 Removed min value of VIL, max value for VIH and added two notes in Table 26 Remanued Table 10 |
| | | Added a row in Table 19 for DDR3 Added note 2 in Table 18 Changed all the values and notes in Table 19 Added note 4, 5, and 6 in Table 17 Added note 2 in Table 5 In Table 12, removed min valie of Frequency modulcation and added note 2. Replace old notes with new notes in Table 11 In Table 11, changed the min value for fSYSCLK from 33MHz to 66.7 MHz and hence max SYSCLK cycle time to 15ns. Added Table 6, Table 13, Section 2.7.5, "DDR Clock Timing", Figure 9, Section 2.8.2.3, "DDR2 and DDR3 SDRAM Differential Timing Specifications, Section 2.13.2.1, "Test Condition, Changed the range of all 1V signal from 0.95V to 1.05V in Figure 2 Shortenned feature list in intorductory section Replaced SENSEVDD and SENSEVSS with NC103 and NC104 in Table 1 Removed IRQ6 from Table 1 Changed frequency combination from 400–600Mhz to 267–533 MHz in Table 6 |

Revision History

| Rev. Number | Date | Substantive Change(s) |
|----------------|--------|--|
| D | 4/2009 | Changes done on Table 1 Renamed all XVDD_SRDS to XV _{DD} _SRDS Renamed all AVDD_CORE0 to AV _{DD} _CORE0, AVDD_CORE1 to AV _{DD} _CORE1, AVDD_DDR to AV _{DD} _DDR, AVDD_PLAT to AV _{DD} _PLAT, AVDD_SRDS to AV _{DD} _SRDS, SVDD_SRDS to SV _{DD} _SRDS Removed TDM signals Replaced AV _{DD} _LBIU with NC102 as eLBC PLL has been removed CE_PA29 muxed with LBCTL swapped with CE_PB20 muxed with CFG_DDR_DEBUG V _{DD} has been split into V _{DD} & V _{DDC} |
| | | Changes in Table 2 and Table 3 • Added a row for V _{DDC} • PLL AVDD expanded to AV _{DD} _CORE0, AV _{DD} _CORE1, AV _{DD} _DDR, AV _{DD} _PLAT, and AV _{DD} _SRDS • Changed SVDD to SV _{DD} _SRDS, XVDD to XV _{DD} _SRDS |

| Rev. Number | Date | Substantive Change(s) |
|----------------|--------|---|
| С | 2/2009 | Deleted MCC from Figure 1 Shifted Pinout List from Section 5.2 to Section 1.2, "Pinout Assignments" Following changes were done on Table 1: |
| | | Replaced NC54 with MECC05, NC55 with MECC06, NC56 with MECC07, CE_PA22 with CE_PA13, CE_PA23 with CE_PA25, CE_PA23 with CE_PA26, CE_PA24 with CE_PA26, CE_PA25 with CE_PA23, CE_PA26 with CE_PA23, CE_PA26 with CE_PA24, CE_PA28 with CE_PB44, CE_PA18 with CE_PB17, CE_PB15 with CE_PB16, CE_PB15 with CE_PB16, CE_PB16 with CE_PB15, CE_PB16 with CE_PB15, CE_PB9 with CE_PA15, DMA2_DACK_B00 with CFG_MEM_DEBUG, and DMA2_DDONE_B00 with CFG_DDR_DEBUG Added LB_MSRCID00 / PLL_PER_OUT00 to P28, LB_MSRCID03 / PLL_PER_OUT03 to P27, LB_MSRCID03 / PLL_PER_OUT03 to P26, LB_MSRCID04 / PLL_PER_OUT03 to P26, LB_MSRCID04 / PLL_PER_OUT01 M24 |
| | | Removed • DMA2_DREQ_B1, • DMA2_DACK_B1, • DMA2_DDONE_B[1], • DMA2_DREQ_B00, • IRQ07, • IRQ08, • IRQ09, • IRQ10, • IRQ11, • and USB_VBUSEN |

Revision History

| Rev. Number | Date | Substantive Change(s) |
|----------------|---------|--|
| В | 12/2008 | Removed adjective "weak" for pull up from first line of first paragraph of Section 4.7, "Pull-Up and Pull-Down Resistor Requirements" Removed Note 3 stating "memory bus clock should be less than CCB clock rate" in Table 86 Renamed t_{LBKHOV4} to t_{LBKLOV4} in Table 51 Added a note below Table 51 Changed the platform frequency from 400 to 333 Mhz in second row of Table 6 Removed E from P1012/21 Modified eTSEC features in introductory section. Added TSEC1_GTX_CLK125, TSEC3_RX_DV, TSEC3_RX_CLK, TSEC3_RXD[3:0], CFG_DRAM_TYPE, CFG_IO_PORTS3, SDHC_DAT[7:4], TDM_TFS, TDM_TX_CLK, TDM_RFS, TDM_RX_DATA in Table 1 Removed TSEC2_TXD05, TSEC2_TXD04, TSEC2_TXD01, TSEC2_TX_ER, TSEC2_CRS and TSEC2_COL from Table 1. Added suppport for x2 and x4 port in PCIe feature list Added Note 1 in Table 1 Removed all the references, figures and tables for PLL Enable. Added figures and tables for PLL Bypas mode in Section 2.13, "Enhanced Local Bus" Changed minimum time of t_{MCK} from 2.5ns to 3ns in Table 23 Changed P1021 to P1012/21 on all occurences. Modified Figure 1 to show P1012. Added Section 2.11.5, "MII Management" Table 1Added simlation details in Section 4.12.1, "Thermal Characteristics" Added data in Table 99 and Table 100. |
| Α | 10/2008 | Initial release. |

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Freescale Halbleiter Deutschland GmbH Technical Information Center Schatzbogen 7 81829 Muenchen, Germany +44 1296 380 456 (English) +46 8 52200080 (English) +49 89 92103 559 (German) +33 1 69 35 48 48 (French) www.freescale.com/support

Japan:

Freescale Semiconductor Japan Ltd. Headquarters ARCO Tower 15F 1-8-1, Shimo-Meguro, Meguro-ku, Tokyo 153-0064 Japan 0120 191014 or +81 3 5437 9125 support.japan@freescale.com

Asia/Pacific:

Freescale Semiconductor China Ltd. Exchange Building 23F No. 118 Jianguo Road Chaoyang District Beijing 100022 China +86 10 5879 8000 support.asia@freescale.com

For Literature Requests Only:

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